



10TH
EDITION

RF manual 10th edition

Application and design manual for RF products
September 2007

NXP
founded by Philips

Introduction

Welcome to this very special edition of the RF manual. This is our 10th issue – definitely an occasion for celebration! Over the years, the RF manual has become the leading RF application forum in the market and to celebrate our 10th edition we have launched an anniversary contest on our RF manual website: www.nxp.com/rfmanual.

New developments

This edition features some exciting new developments and products, which you can find in chapter 5 Focus applications and products. These include advances in SiGeC RF transistor and RF MMIC technologies such as the BFU725F, which meet today's demand for higher frequencies.

We have also introduced new CATV 1-GHz modules, enabling you to increase network capacity for high-end services.

In addition, we now offer WiMAX transceivers, covering frequencies from 2.3 GHz to 3.8 GHz. These allow you easily to create total WiMAX system solutions that meet TTA, FCC and ETSI requirements.

For satellite LNB, we have introduced the industry's first fully integrated silicon-based IC solution – a valuable contribution to lowering total cost of ownership of satellite solutions as a whole. This RF IC, manufactured in NXP's advanced SiGe BiCMOS process, QUBiC4G, paves the way for an exciting family of high frequency RF ICs, which will be available soon.

You will also find new BAW filters to improve reception in smart phone designs. And last but not least, we have released the first set of RF diodes in our latest UTLT package platform, enabling you to create smaller form factors.

Application driven

This manual is designed to be a dynamic source of RF information. In keeping with this, we have added some new applications that may be of interest: a satellite multi-switch box, wireless USB and RF front-ends for WiMAX applications.

Interactive

We know that many of you appreciate the RF manual's interactive features. Thus as always, this edition aims to be the interactive source for all information on our RF systems. Simply 'click' on a product type or application note and you will be taken directly to the corresponding product information page or application document on the NXP website.

Internet

You can access the manual via www.nxp.com/rfmanual or just 'google' RF manual.

RF manual web page

www.nxp.com/rfmanual

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What if you could reduce RF component count in your wireless devices?

Look at RF IC's – MMICs, chapter 2.4.1

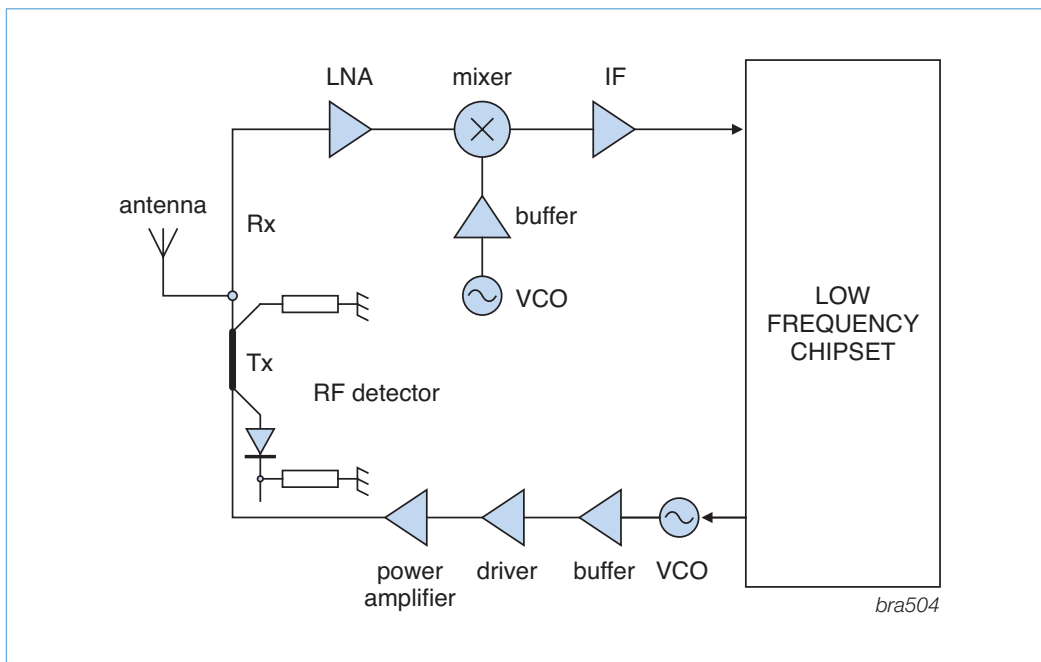
1. Applications, recommended products and application notes

NXP RF Applications
<http://www.nxp.com/rf>

NXP Application notes
http://www.nxp.com/all_appnotes/index.html

1.1 Low-cost cellular phone front-end for ODM/CEM designs

Application diagram



Recommended products

Function	Product	Package	Type	
RF detector	RF schottky diode	Low Cd schottky	SOT323	1PS70SB84
			SOD323	1PS76SB17
			SOD882	1PS10SB82
			SOT666	1PS66SB82

Function	Product	Package	Type	
Buffer	RF bipolar transistor	Wideband transistor	SOT343	BFG410W
			SOT343	BFG425W
			SOT343	BFG480W
			SOT23	BFR520T
			SOT416	BFR505T
			SOT323	BFS540

Function	Product	Package	Type	
Antenna switch	RF diode	PIN diode	various	BAP50
			various	BAP51
			various	BAP55
			various	BAP63
			various	BAP64
			various	BAP65
			various	BAP1321

Function	Product	Package	Type	
VCO	Varicap diodes	VCO varicap diodes	SOD523	BB145B
			SOD523	BB179

Function	Product	Package	Type	
VCxO	Varicap diodes	VCxO varicap diodes	SOD523	BB198
			SOD523	BB199

Function	Product	Package	Type	
LNA	MMIC	Low noise wideband amplifier	SOT343R	BGA2001
			SOT343R	BGA2003
			SOT363	BGA2011
			SOT363	BGA2012

* = 2 stage variable gain linear amplifier

Function	Product	Package	Type	
Driver	Bipolar transistor	Wideband transistor	SOT343	BFG21W
			SOT343	BFG425W
			SOT343	BFG480W
	MMIC	Amplifier*	SOT363	BGA2031/1
			SOT363	BGA2771
SOT363	Gen. purpose wideband ampl.	BGA2776		

Function	Product	Package	Type	
Mixer	RF bipolar transistor	Wideband transistor	SOT343	BFG410W
			SOT343	BFG425W
			SOT343	BFG480W
	MMIC	Linear mixer	SOT363	BGA2022

Function	Product	Package	Type	
IF	MMIC	Low noise amplifier	SOT343R	BGA2001
			SOT343R	BGA2003
			SOT363	BGA2771
	RF bipolar transistor	Gen. purpose amplifier	SOT363	BGA2776
			SOT363	PRF949
SOT363	Wideband transistor	BFS17W		

Function	Product	Package	Type	
Power amplifier	Bipolar transistor	Wideband transistor	SOT343	BFG21W
			SOT343	BFG480W
			SOT363	BGA2031/1
	MMIC	Amplifier*	SOT363	BGA2771
			SOT363	Gen. purpose wideband ampl.

Recommended application notes

1880MHz PA driver	BFG21W
1880MHz PA driver	BFG480W
2GHz LNA	BFG410W
2GHz LNA	BFG425W
800MHz PA driver	BFG21W
900MHz driver	BFG480W
900MHz LNA	BFG410W
900MHz LNA	BFG480W
CDMA cellular VCO	BFG425W, BFG410W
Demoboard 900MHz LNA	BGA2003
Demoboard for BGA2001	BGA2001
Demoboard for W-CDMA	BGA2003
High IP3 MMIC LNA at 1.8 - 2.4 GHz	BGA2012
High IP3 MMIC LNA at 900MHz	BGA2011
Power amplifier for 1.9GHz DECT and PHS	BFG425W, BFG21W
Rx mixer for 2450MHz	BGA2022
Ultra LNAs for 900&2000MHz with high IP3	BFG410W, BFG425W

Product highlight: BGA2771 MMIC General - purpose wideband amplifier

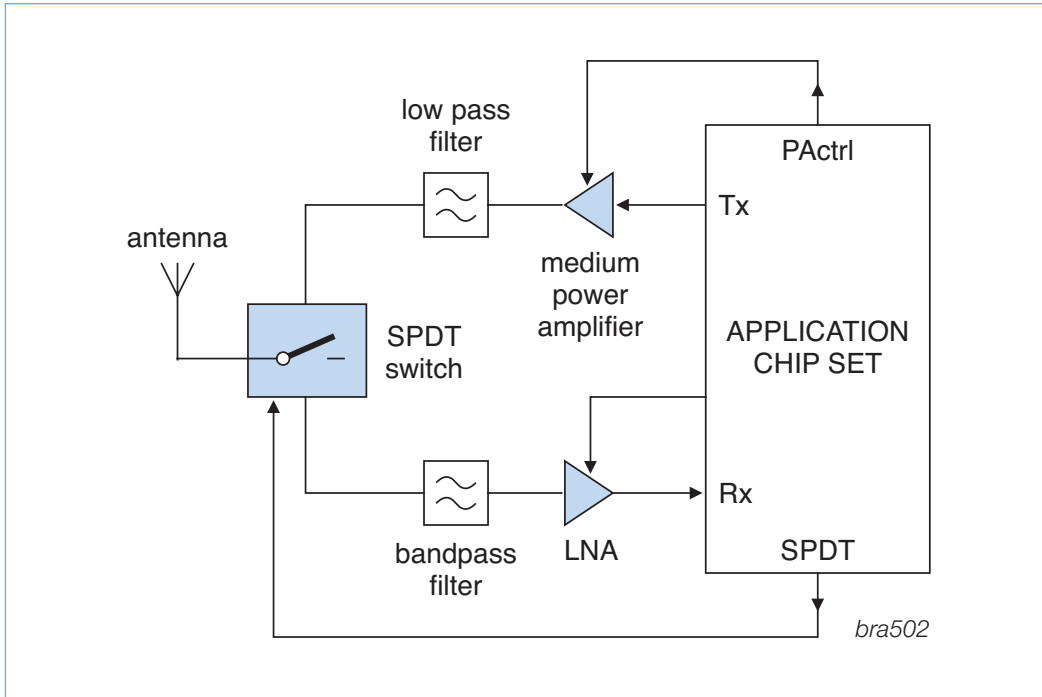
Silicon Monolithic Microwave Integrated Circuit (MMIC) wideband amplifier with internal matching circuit in a 6-pin SOT363 SMD plastic package. The BGA27xx series amplifier provides large bandwidth and high quality in wireless system applications.

Features

- ▶ Internally matched
- ▶ Wide frequency range
- ▶ Very flat gain
- ▶ High output power
- ▶ High linearity
- ▶ Unconditionally stable

1.2 A 2.4 GHz front-end for WLAN, Bluetooth™, DECT, ZigBee™, etc.

Application diagram



Recommended products

Function	Product		Package	Type
SPDT switch	RF diode	PIN diode	SOD523	BAP51-02
			SOD882T	BAP51LX
			SOD882T	BAP55LX

Function	Product		Package	Type
Medium power amplifier	MMIC	Gen. purpose med. power amplifier	SOT89	BGA6589

Function	Product		Package	Type
LNA	MMIC	Low noise wideband amplifier	SOT343R	BGA2003
			SOT343R	BGA2001

Recommended application notes

2.45 Ghz T/R, RF switch	BAP51-02
Low-impedance PIN diode	BAP50-05
Demoboard 900 MHz LNA	BGA2003
Demoboard for 900&1800 MHz	BGA2001
Demoboard for W-CDMA	BGA2003

Product highlight: BGA6289 MMIC medium power amplifier

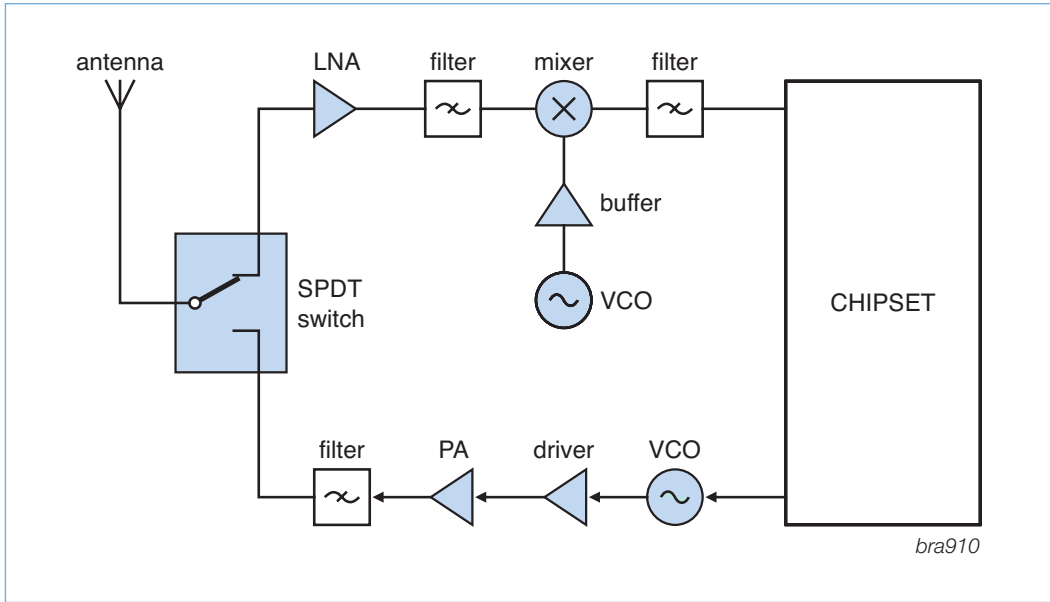
Silicon Monolithic Microwave Integrated Circuit (MMIC) wideband medium power amplifier with internal matching circuit in a 4-pin SOT89 plastic low thermal resistance SMD package. The BGA6x89 series of medium power gain blocks provides large bandwidth and high-quality performance in 2.4GHz wireless applications.

Features

- ▶ Broadband 50W gain block
- ▶ 17dBm output power
- ▶ Single supply voltage needed

1.3 Cordless Phone (Analog)

Application diagram



Recommended products

Function	Product	Package	Type	
RF Switch	RF diode	PIN Diode	various	BAP51
			various	BAP63
			various	BAP64

Function	Product	Package	Type	
LNA	RF bipolar transistor	Wideband transistor	SOT23	BFT25
			SOT23	PBR951
			SOT323	PRF957
			SOT343	BFG425W
			SOT343F	BFG424F

Function	Product	Package	Type	
Mixer	RF bipolar transistor	Wideband transistor	SOT323	PRF957
			SOT143	BFG540
			SOT343	BFG410W
			SOT343	BFG425W
			SOT343	BFG480W
	MMIC	Linear mixer	SOT363	BGA2022

Function	Product	Package	Type	
VCO	Varicap diodes	VCO varicap diodes	SOD323	BB131
			SOD523	BB145B
			SOD323	BB148
			SOD523	BB149

Function	Product	Package	Type	
Driver/Buffer	RF bipolar transistor	Wideband transistor	SOT23	PBR951
			SOT323	PRF957
			SOT343	BFG425W
			SOT343F	BFG424F

Recommended application notes

2.45 Ghz T/R, RF switch	BAP51-02
Low-impedance PIN diode	BAP50-05

Product highlight: BAP64xx PIN diode for RF switch

Operating up to 3GHz with high-voltage handling capabilities, NXP's PIN diodes are ideal for a wide range of wireless communication application. Together with outstanding RF performance, this component simplify design-in because of its extremely low forward resistance, diode capacitance and series inductance. Significant

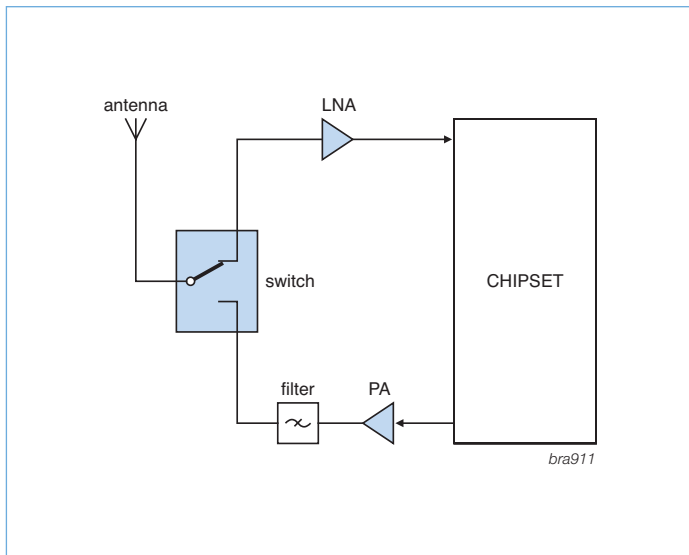
board space saving by supplying a range of high compact package options – including SOD523, SOD323 and leadless SOD882T.

Features

- ▶ Operate up to 3GHz
- ▶ High isolation, low distortion, low insertion loss
- ▶ Low forward resistance (Rd) and diode capacitance (Cd)
- ▶ Ultra-small package options

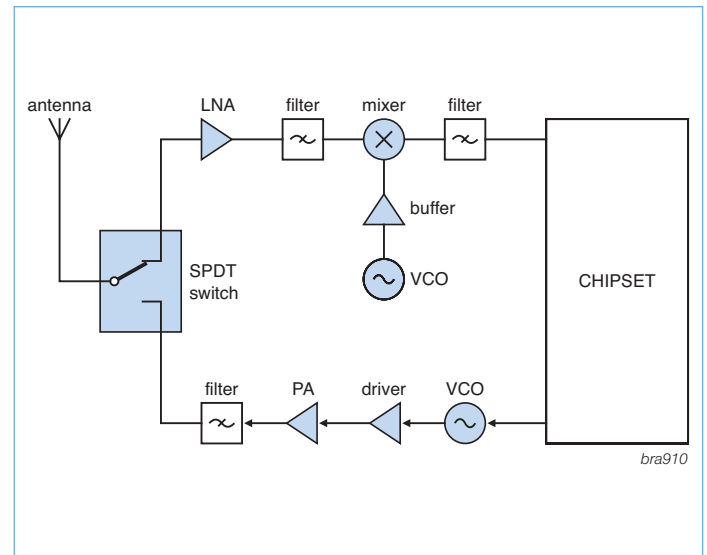
Cordless Phone (DECT front-end)

Application diagram



(DECT in-house basestation)

Application diagram



Recommended products

Function	Product	Package	Type	
RF Switch	RF diode	PIN Diode	various	BAP51
			SOD882T	BAP55LX
			SOD882T	BAP142LX
			various	BAP63
			various	BAP64
			various	BAP1321

Function	Product	Package	Type	
LNA	RF bipolar transistor	Wideband transistor	SOT343	BFG425W
		SOT343F	BFG424F	
	RF transistor	SiGeC transistor	SOT343F	BFU725F

Recommended products

Function	Product	Package	Type	
RF Switch	RF diode	PIN Diode	various	BAP51
			SOD882T	BAP55LX
			SOD882T	BAP142LX
			various	BAP63
			various	BAP64
			various	BAP1321

Function	Product	Package	Type	
LNA	RF bipolar transistor	Wideband transistor	SOT343	BFG425W
		SOT343F	BFG424F	
	RF transistor	SiGeC transistor	SOT343F	BFU725F

Function	Product	Package	Type	
Mixer	RF bipolar transistor	Wideband transistor	SOT343	BFG410W
		SOT343	BFG425W	
		SOT343	BFG480W	
	MMIC	Linear mixer	SOT363	BGA2022

Function	Product	Package	Type	
VCO	Varicap diodes	VCO varicap diodes	SOD523	BB145B

Function	Product	Package	Type	
Driver/Buffer	RF bipolar transistor	Wideband transistor	SOT343	BFG425W
		SOT343F	BFG424F	
		SOT343	BFG480W	
	RF transistor	SiGeC transistor	SOT343F	BFU725F

Product highlight: BFG425W NPN wideband transistor

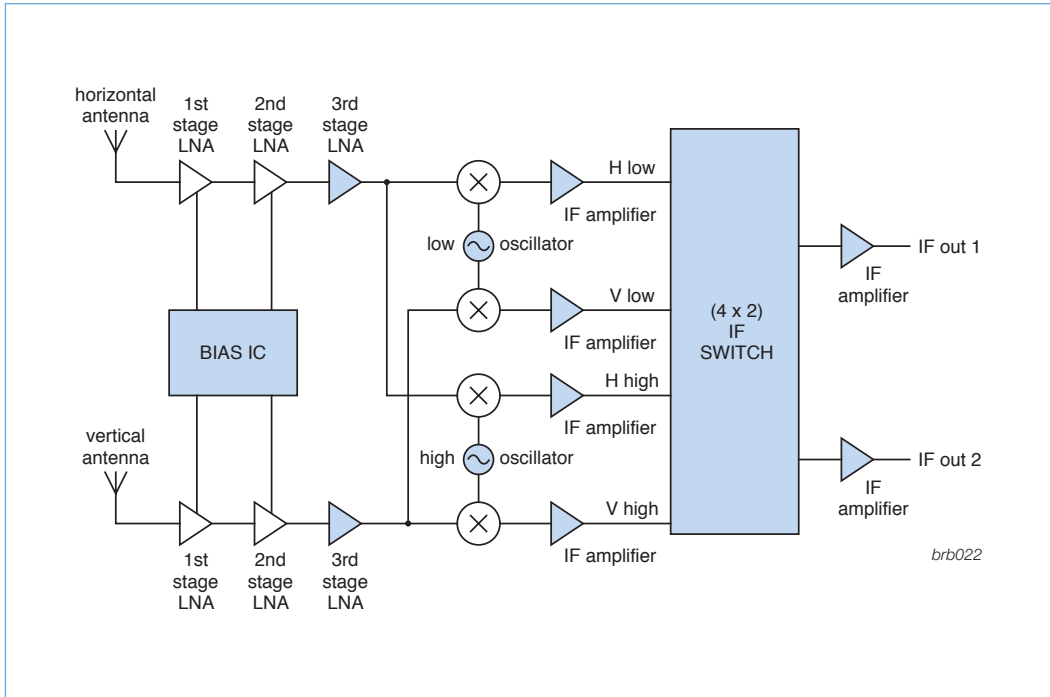
NXP NPN double polysilicon wideband transistor with buried layer is for low voltage and low noise applications in a plastic, 4-pin dual-emitter SOT343R package.

Features

- ▶ Very high maximum power gain (20dB for 2GHz)
- ▶ Low noise figure (1.2dB for 2GHz)
- ▶ High transition frequency (25GHz)
- ▶ Emitter is thermal lead
- ▶ Low feedback capacitance (95fF)

1.4 Satellite outdoor unit, low noise block (LNB) for multiple users.

Application diagram



Recommended products

Function	Product	Package	Type
Oscillator	RF bipolar transistor	Wideband transistor	SOT343
			SOT343F

Function	Product	Package	Type
1st stage IF amplifier	MMIC	General purpose amplifier	SOT363
			BGA2711
			SOT363
			BGA2712
	RF bipolar transistor	Wideband transistor	SOT363
			BGA2748
		SOT363	
		BGA2714	
		SOT363	
		BGA2717	
		SOT343	
		BFG424W	
		SOT343F	
		BFG424F	

Function	Product	Package	Type
IF switch	RF diode	PIN diode	various
			BAP64
			various
			BAP51
			various
		BAP1321	
		BAP50	
		BAP63	

Function	Product	Package	Type
Output stage IF amplifier	MMIC	General purpose amplifier	SOT363
			BGA2709
			SOT363
			BGA2776
	RF bipolar transistor	Wideband transistor	SOT363
			BGM1014
		SOT363	
		BGM1012	
		SOT363	
		BGA2716	
		SOT343	
		BFG325	

Function	Product	Package	Type
3rd stage LNA	RF transistor	SiGeC transistor	SOT343F
			BFU725F

Function	Product	Package	Type
BIAS IC	Bias IC	TSSOP16	UAF4000TS

Recommended application notes

2.45 Ghz T/R, RF switch	BAP51-02
Low-impedance PIN diode	BAP50-05

Product highlight: BFG424F bipolar oscillator

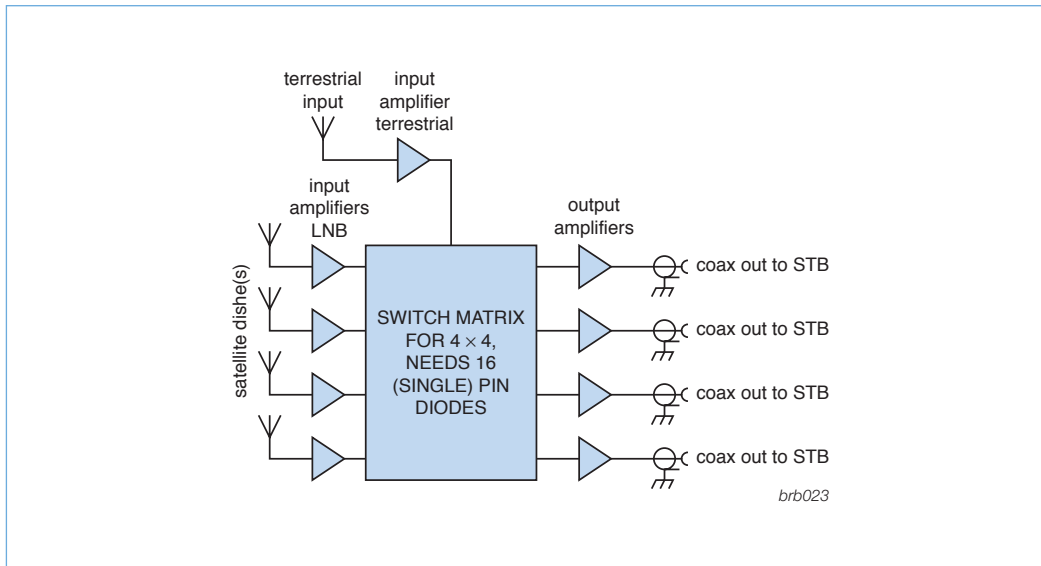
The BFG424F is an NPN double polysilicon wideband transistor with a buried layer for low-voltage applications. Housed in an easy-to-use SOT343F package, it features very high gain, stable phase noise & low feedback capacitance.

Features

- ▶ Stable phase noise over temperature performance
- ▶ Compact flat-lead SOT343F package simplifies assembly
- ▶ Free oscillations at all LO frequencies

1.5 Satellite Multi Switch Box - 4 x 4 (up to 16 x 16)

Application diagram



Recommended products

Function	Product		Package	Type
Input amplifier terrestrial	MMIC	General purpose medium power amplifier	SOT89	BGA6289
				BGA6489
				BGA6589

Function	Product		Package	Type
Input amplifier LNB	MMIC	General purpose amplifier	SOT363	BGA2771
			SOT363	BGA2776
			SOT363	BGA2709
			SOT363	BGM1012
			SOT343	BFG325
	RF bipolar transistor	Wideband transistor	SOT343	BFG425W
			SOT143	BFG520
			SOT143	BFG540
			SOT143	BFG540

Function	Product		Package	Type
Switch matrix	RF diode	PIN diode	Various	BAP50
				BAP51
				BAP63
				BAP64
				BAP70
				BAP1321

Function	Product		Package	Type			
Output amplifier	MMIC	General purpose medium power amplifier	SOT89	BGA6289			
				BGA6489			
				BGA6589			
				RF bipolar transistor	Wideband transistor	SOT363	BGM1011
						SOT363	BGM1013
	SOT363	BGM1014					
	SOT223	BFG135					
	RF bipolar transistor	Wideband transistor	SOT223	BFG591			
			SOT223	BFG198			
SOT143			BFG540				
SOT143			BFG540				

Product highlight: PIN diodes for switching matrix

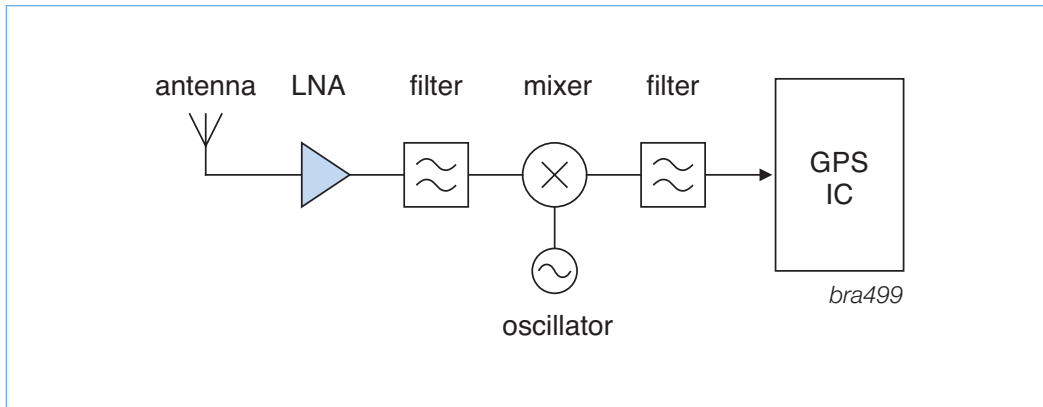
Together with outstanding RF performance, this component simplifies design-in because of its extremely low forward resistance, diode capacitance and series inductance. Significant board space saving by supplying a range of high compact package options – including SOD523, SOD323 and leadless SOD882T.

Features

- ▶ High isolation, low distortion, low insertion loss
- ▶ Low forward resistance (Rd) and diode capacitance (Cd)
- ▶ Ultra-small package options

1.6 Global Positioning System (GPS)

Application diagram



Recommended products

Function	Product		Package	Type	
LNA	RF bipolar transistor	Wideband transistor	SOT343	BFG425W	
			SOT343	BFG410W	
	MMIC	Low noise wideband amplifier		SOT343R	BGA2001
				SOT343R	BGA2003
		General purpose wideband amplifier		SOT363	BGM1013
				SOT363	BGM1011
				SOT363	BGA2715
			SOT363	BGA2748	
	RF transistor	SiGeC transistor	SOT343F	BFU725F	

Recommended application notes

Introduction into the GPS front-end*	BGAx, BGMx, BGuX
900 MHz LNA	BFG410W
2 GHz LNA	BFG410W
2 GHz high IP3 LNA	BGA2003

* No web link available, published in Appendix 6th edition, see RF Manual web page.

Product highlight: BFU725F SiGeC microwave NPN transistor

Meet the trend towards higher frequencies. The BFU725F provides high switching frequencies plus extreme high gain and low noise.

Features

- ▶ Very low noise (0.4 dB at 1.8 GHz / 0.67 dB at 5.8 GHz)
- ▶ High maximum stable gain (27.8 dB at 1.8 GHz / 10 dB at 18 GHz)

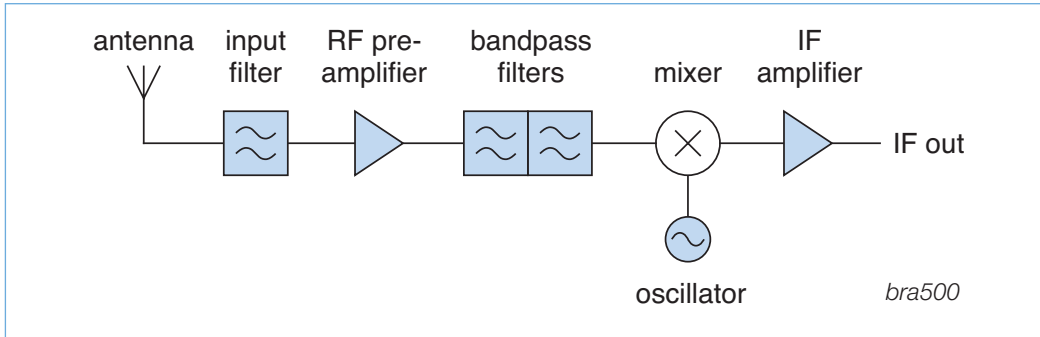
- ▶ High switching frequency (fT >100 GHz / fMAX >150 GHz)
- ▶ Plastic surface-mount SOT343F package

Benefits

- ▶ SiGeC process delivers high switching frequency from a silicon-based device
- ▶ Cost-effective alternative to GaAs devices
- ▶ RoHS compliant

1.7 TV / VCR / DVD tuning

Application diagram



Recommended products

Function	Product	Package	Type	
Input filter	Varicap diode	VHF low	SOD323	BB152
			SOD523	BB182
		VHF high	SOD323	BB153
			SOD523	BB178
		UHF	SOD523	BB187
			SOD323	BB149A
SOD523	BB179			

Function	Product	Package	Type	
Bandpass filter	Varicap diode	VHF low	SOD323	BB152
			SOD523	BB182
		VHF high	SOD323	BB153
			SOD523	BB178
		UHF	SOD523	BB187
			SOD323	BB149A
SOD523	BB179			

Function	Product	Package	Type	
RF pre-amplifier	MOSFET	5 V	SOT143	BF904
			SOT143	BF909
			SOT143	BF1201
			SOT143	BF1202
			SOT143	BF1105
			SOT143	BF1211
		9 V	SOT143	BF1212
			SOT143	BF1100
		2-in-1 @ 5 V	SOT143	BF1109
			SOT363	BF1102R
			SOT363	BF1203
			SOT363	BF1204
			SOT363	BF1205
			SOT363	BF1205C
			SOT363	BF1206
			SOT363	BF1207
			SOT666	BF1208
			SOT666	BF1208D
2-in-1 @ 3 V	SOT363	BF1210		
	SOT363	BF1214		
SOT666	BF1206F			

Function	Product	Package	Type	
Oscillator	Varicap diode	VHF low	SOD323	BB152
			SOD523	BB182
		VHF high	SOD323	BB153
			SOD523	BB178
		UHF	SOD523	BB187
			SOD323	BB149A
SOD523	BB179			

Function	Product	Package	Type	
IF amplifier	MMIC	Wideband amplifier	SOT363	BGA2717

Recommended application notes

Application note for MOSFETs: BF9x, BF110x, BF120x*	BF9x, BF110x, BF120x
--	----------------------

* No web link available, published in Appendix 3rd edition, see RF Manual web page.

Product highlight: BF1206F dual gate mosfet double amplifier specified for low power applications.

The device consists of two dual gate mosfet amplifiers in a small SOT666 flatlead package. The BF1206F is a true low power device specified for low voltage and low currents, intended for use in mobile applications where power consumption is critical. Performance is suitable for application at supply voltages of 3Volts and draincurrents of 4mA.

Features

- ▶ Low power specified
- ▶ Two amplifiers in one small SOT666 package
- ▶ Shared gate 2 and Source leads
- ▶ Each amplifier is biased by an external bias resistor
- ▶ Excellent noise and crossmodulation performance

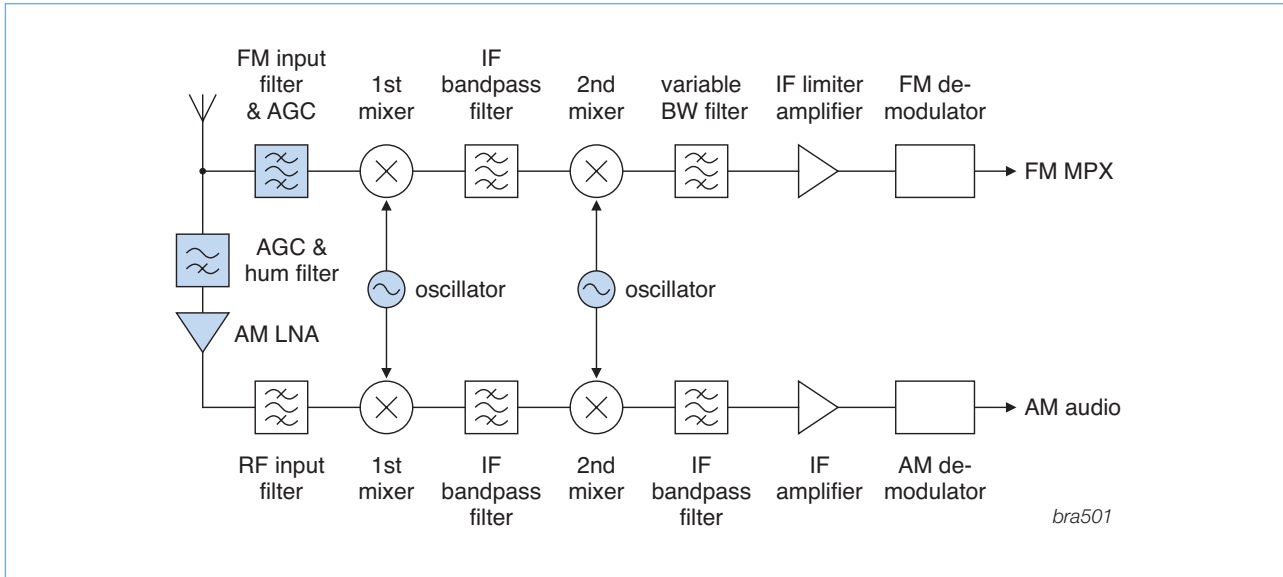


What if you could create a smaller form factor?

Look at UTLP packages, chapter 6

1.8 Car radio receiver (CREST ICs: TEF6860HL, TEF6862HL)

Application diagram



Recommended products

Function	Product	Package	Type
AM LNA	RF transistor	JFET	SOT23
FM input filter & AGC	RF diode	Varicap diode	SOT23
			SOT23
			SOD523
			SOD323

* = OIRT

Note 1:

All these recommended discrete products are applicable for NICEPACS, CCC and DDICE: NICE:TEA6840H,TEA6845H,TEA6846H, NICEPACS:TEA6848H,TEA6849H; CCC:TEF6901H,TEF6903H; DDICE: TEA6721HL. All these recommended discrete products are applicable excluding AM LNA in: DICE2:TEF6730HWCE.

Function	Product	Package	Type
AGC & hum filter	RF diode	PIN diode	SOT363
Oscillator	RF diode	Varicap diode	SOD323
			SOD523

Note 2:

Phone and portable radio (IC:TEA5767/68) use varicap BB202 as FM oscillator.

Recommended application notes

Low-voltage FM stereo radio (TEA5767/68)*	BB202
A NICE radio (TEA6848H) - Draft**	JFETS,Varicaps and PIN diodes
Integrated Car Radio CCC (TEF69xxx) - Draft**	JFETS,Varicaps and PIN diodes

* No web link available, published in Appendix 3rd edition, see RF Manual web page.

** No web link available, ask your NXP sales representative.

Product highlight: BF862 Junction Field Effect Transistor

Our Tuning component portfolio contains excellent products for car radio reception applications, playing a vital role for in-vehicle media platforms. The NXP devices for this application ensure excellent reception quality and ease of design in. Performance is demonstrated in reference designs.

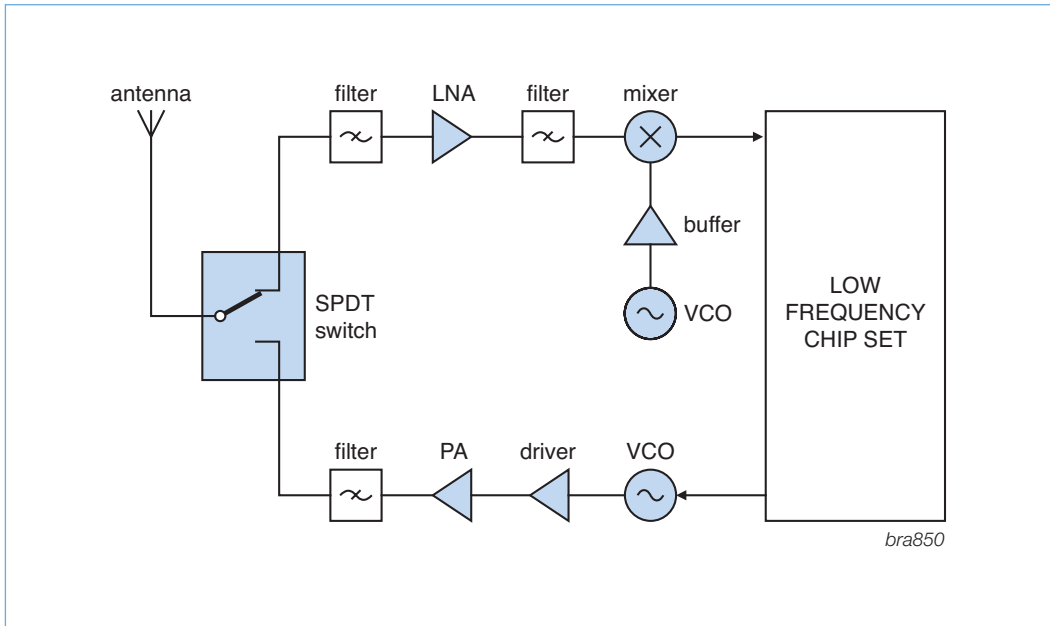
High performance Junction Fet BF862, specially designed for car radio AM amplifiers.

Features

- ▶ High transition frequency and optimized input capacitance for excellent sensitivity
- ▶ High transfer admittance resulting in high gain
- ▶ Encapsulated in the versatile and easy to use SOT23 package

1.9 RF generic front-end for applications with a single antenna: for e.g. walkie-talkie & remote metering

Application diagram



Recommended products

Function	Product	Package	Type
SPDT Switch	RF diode	Bandswitch diode	SOD523 BA277
			SOD323 BA591
		PIN diode	various BAP51
			various BAP1321

Function	Product	Package	Type
LNA	RF bipolar transistor	Wideband transistor	SOT23 PBR951
			SOT323 PRF957
			SOT323 PRF947
	MMIC	Low noise wideband ampl.	SOT343R BGA2001
		SOT343R BGA2003	

Function	Product	Package	Type
Driver	RF bipolar transistor	Wideband transistor	SOT323 PRF957
			SOT23 PBR951
	MMIC	Amplifier	SOT363 BGA2031/1
		Gen. purpose wideband ampl.	SOT363 BGA2771
		SOT363 BGA2776	

Function	Product	Package	Type
Mixer	RF bipolar transistor	Wideband transistor	SOT343 BFG410W
			SOT343 BFG425W
	MMIC	Linear mixer	SOT343 BFG480W
			SOT363 BGA2022

Function	Product	Package	Type
Buffer	RF bipolar transistor	Wideband transistor	SOT23 PBR951
			SOT323 PRF957
			SOT323 PRF947
			SOT416 PRF949

Function	Product	Package	Type
Power amplifier	MMIC	Gen. purpose wideband ampl.	BGA6289
			BGA6489
			BGA6589

Function	Product	Package	Type
VCO	Varicap diodes	VCO varicap diodes	SOD523 BB198
			SOD323 BB156

Product highlight: PRF957 silicon NPN UHF wideband transistor

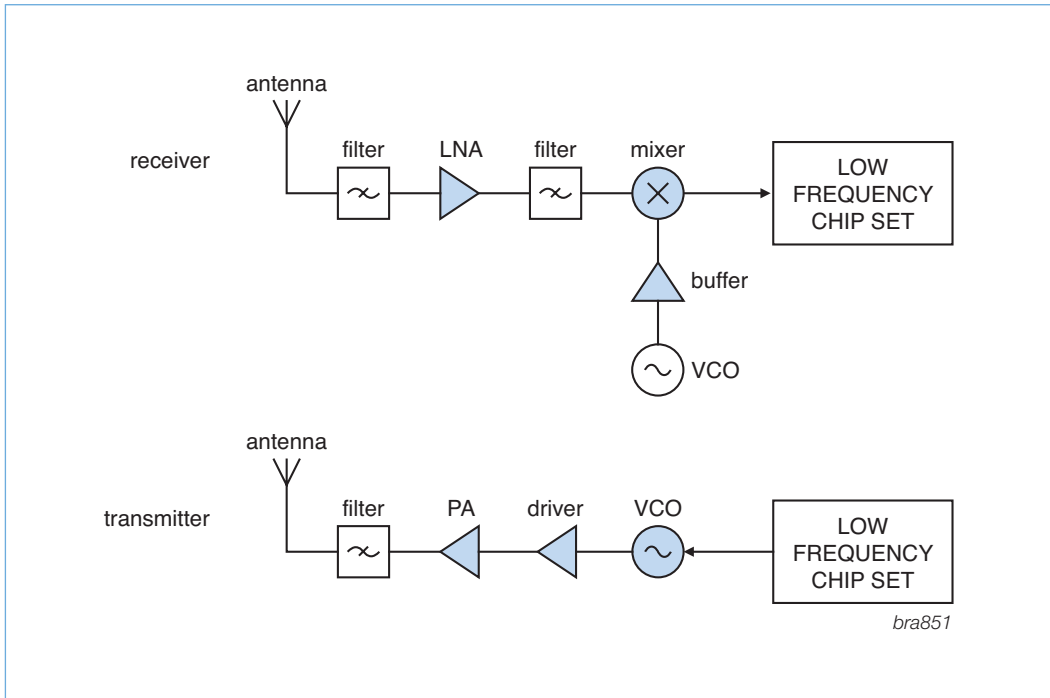
Silicon NPN UHF wideband transistor in a surface mount 3-pin SOT323 package is primarily intended for wideband applications in the RF front end. The transistor is widely built as LNA, power amplifier, driver and buffer in the UHF band application.

Features

- ▶ Small 3-pin plastic surface mounted package
- ▶ Low noise (1.3dB at 1GHz) and high power gain (15dB at 1GHz)
- ▶ Gold metallization ensures excellent reliability

1.10 RF generic front-end for applications with a dedicated antenna for reception and transmission: for e.g. tire pressure monitoring systems & keyless entry

Application diagram



Recommended products

Function	Product	Package	Type
LNA	RF bipolar transistor	Wideband transistor	SOT23 PBR951
			SOT323 PRF957
			SOT323 PRF947
	MMIC	Low noise wideband ampl.	SOT343R BGA2001
			SOT343R BGA2003

Function	Product	Package	Type
Driver	RF bipolar transistor	Wideband transistor	SOT323 PRF957
			SOT23 PBR951
		Amplifier	SOT363 BGA2031/1
	MMIC	Gen. purpose wideband ampl.	SOT363 BGA2771
			SOT363 BGA2776

Function	Product	Package	Type
VCO	Varicap diodes	VCO varicap diodes	SOD323 BB148
			SOD323 BB149A
			SOD523 BB198
			SOD323 BB156

Function	Product	Package	Type
Mixer	RF bipolar transistor	Wideband transistor	SOT343 BFG410W
			SOT343 BFG425W
	MMIC	Linear mixer	SOT343 BFG480W
		SOT363 BGA2022	

Function	Product	Package	Type
Buffer	RF bipolar transistor	Wideband transistor	SOT23 PBR951
			SOT323 PRF957
			SOT323 PRF947
			SOT416 PRF949

Function	Product	Package	Type
Power amplifier	RF bipolar transistor	Wideband transistor	SOT323 PRF957
			SOT23 PBR951
		Amplifier	SOT363 BGA2031/1
	MMIC	Gen. purpose wideband ampl.	SOT363 BGA2771
			SOT363 BGA2776

Product highlight: NXP varicap diodes for VCO

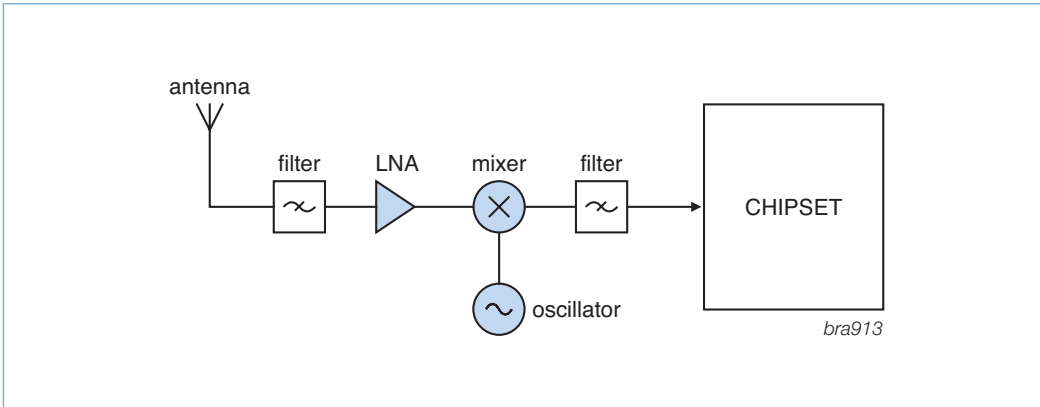
Varicap diodes are principally used as voltage varicap capacitors with their diode function a secondary option. These devices are ideal for voltage controlled oscillators (VCO) in ISM band applications.

Features

- ▶ Excellent linearity
- ▶ Excellent matching
- ▶ Very low series resistance
- ▶ High capacitance ratio

1.11 Digital Audio Broadcasting (DAB)

Application diagram



Recommended products

Function	Frequency	Product	Package	Type		
LNA	VHF band	RF bipolar transistor	Wideband transistor	SOT23	BFS17	
				SOT323	BFS17W	
		RF transistor	JFET	SOT23	BF862	
		Mosfet	5 V		SOT143	BF904
					SOT143R	BF904R
					SOT143	BF909
					SOT143	BF1201
					SOT143	BF1202
					SOT143	BF1105
					SOT143	BF1211
		9 V	SOT143	BF1212		
			SOT143	BF1100		
			SOT143	BF1109		
	S-band/ L-band	RF transistor	SiGeC transistor	SOT343F	BFU725F	
		RF bipolar transistor	Wideband transistor	SOT343	BFG425W	
			SOT343	BFG410W		
MMIC		Low noise wideband amplifier		SOT343R	BGA2001	
				SOT343R	BGA2003	
			General purpose wideband amplifier	SOT363	BGM1013	
				SOT363	BGM1011	
	SOT363	BGA2715				
	SOT363	BGA2748				

Function	Product	Package	Type	
Mixer	RF bipolar transistor	Wideband transistor	SOT343	BFG410W
			SOT343	BFG425W
			SOT343	BFG480W
	MMIC	Linear mixer	SOT363	BGA2022

Function	Product	Package	Type	
VCO	Varicap diodes	VCO varicap diodes	SOD323	BB149

Suitable frequencies for DAB identified on VHF band, L-band and S-band:

- VHF band I: 47 - 68 MHz
- VHF band III: 174 - 240 MHz
- L-band: 1452 - 1467.5 MHz
- S-band: 2310 - 2360 MHz

Product highlight: BFG410W NPN wideband transistor

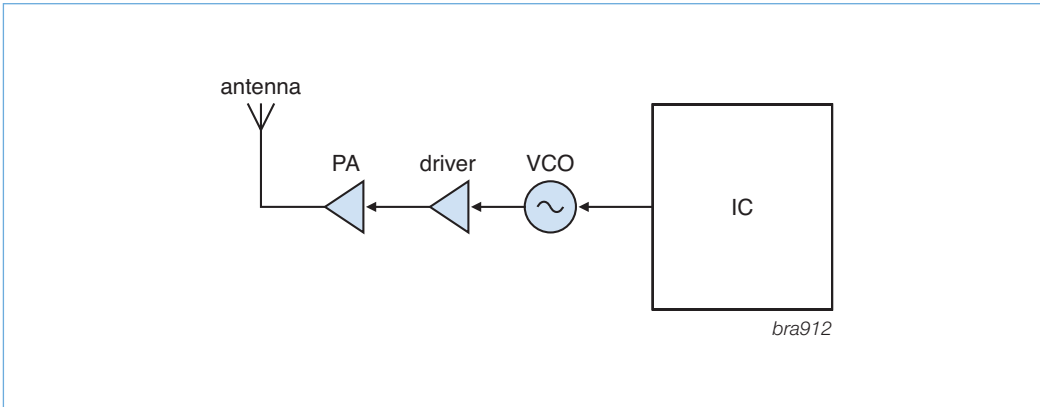
NXP NPN double polysilicon wideband transistor with buried layer is for low voltage and low noise applications in a plastic, 4-pin dual-emitter SOT343R package.

Features

- ▶ Very high power gain (18dB at 2GHz)
- ▶ Low noise figure (1.2dB at 2GHz)
- ▶ High transition frequency (22GHz)
- ▶ Emitter is thermal lead
- ▶ Low feedback capacitance (45fF)

1.12 Wireless Microphone

Application diagram



Recommended products

Function	Product	Package	Type	
PA/Driver	RF bipolar transistor	Wideband transistor	SOT23	BFT93
			SOT323	BFT93W
			SOT23	PBR951
			SOT323	PRF957
			SOT343	BFG21W
			SOT343	BFG425W
		SOT343	BFG480W	

Function	Product	Package	Type	
VCO	Varicap diodes	VCO varicap diodes	SOD523	BB145B
			SOD323	BB149

Operation frequency:

- 70M - 72 M
- 150 MHz - 270 MHz
- 470 MHz - 1000 MHz
- 2400 MHz

Product highlight: BFG480W NPN wideband transistor

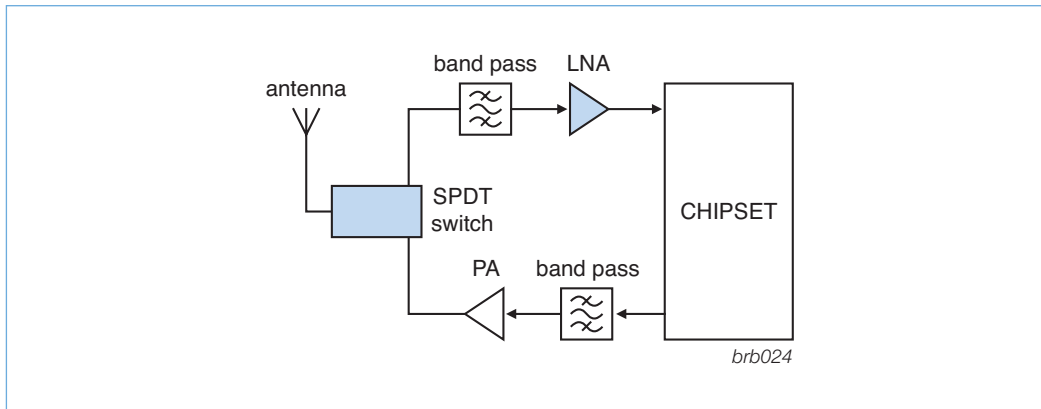
NXP NPN double polysilicon wideband transistor with buried layer is for low voltage and low noise applications in a plastic, 4-pin dual-emitter SOT343 package.

Features

- ▶ High power gain
- ▶ Low noise figure
- ▶ High efficiency
- ▶ High transition frequency
- ▶ Emitter is thermal lead
- ▶ Low feedback capacitance
- ▶ Linear and non-linear operation

1.13 Wireless USB

Application diagram



Recommended products

Function	Product		Package	Type
LNA	RF transistor	SiGeC transistor	SOT343F	BFU725F

Function	Product		Package	Type
SPDT Switch	RF diode	PIN diode	various	BAP51
			various	BAP63
			various	BAP64
			SOD882T	BAP55LX
			SOD882T	BAP142LX
			various	BAP1321

Product highlight: BFU725F SiGeC microwave NPN transistor

Meet the trend towards higher frequencies. The BFU725F provides high switching frequencies plus extreme high gain and low noise.

Features

- ▶ Very low noise (0.4 dB at 1.8 GHz / 0.67 dB at 5.8 GHz)
- ▶ High maximum stable gain (27.8 dB at 1.8 GHz / 10 dB at 18 GHz)

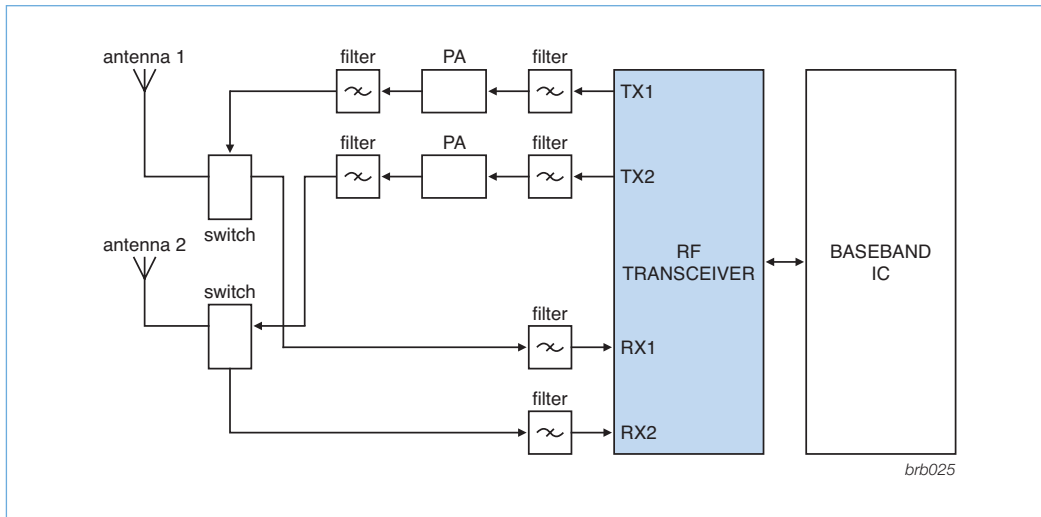
- ▶ High switching frequency (fT >100 GHz / fMAX >150 GHz)
- ▶ Plastic surface-mount SOT343F package

Benefits

- ▶ SiGeC process delivers high switching frequency from a silicon-based device
- ▶ Cost-effective alternative to GaAs devices
- ▶ RoHS compliant

1.14 RF front-end for WiMAX applications

Application diagram



Recommended products

Function	Product	Frequency	Package	Type
RF transceiver	1 Rx/1 Tx	2.3 - 2.4	SOT619	UXF23480
	2 Rx/1 Tx	2.3 - 2.7	SOT778	UXA23465
	2 Rx/2 Tx	2.3 - 2.7	SOT778	UXA23466
	1 Rx/1 Tx	2.5 - 2.7	SOT619	UXF23460
	2 Rx/1 Tx	3.3 - 3.8	SOT778	UXA23475
	2 Rx/2 Tx	3.3 - 3.8	SOT778	UXA23476
	1 Rx/1 Tx	3.3 - 3.8	SOT619	UXA23470

Product highlight: UXx234xx

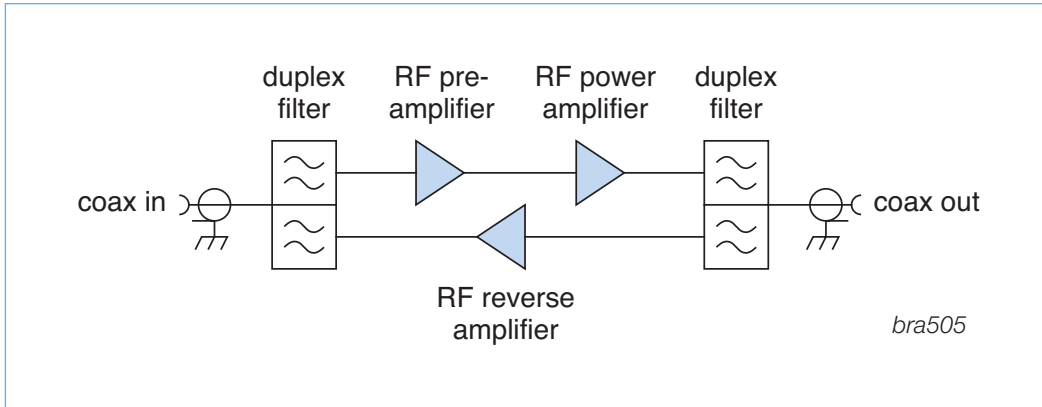
Covering frequencies from 2.3 GHz to 3.8 GHz, these fully integrated, low-power, direct conversion transceivers easily allow total WiMAX system solutions to meet TTA, FCC and ETSI requirements. With dual receiver/transmitter configurations available they can also deliver better uplink performance and improve your total end-user system. In addition, low power requirements ensure longer battery life.

Features

- ▶ Fully integrated direct up transmitter and ZIF receiver architecture
- ▶ Dual Rx and Tx for MIMO operation
- ▶ Low noise, high dynamic range receiver with high linearity
- ▶ Fully integrated VCO with integrated supply voltage regulator
- ▶ Serial bus digital interface (4 wires)

1.15 CATV electrical (line extenders)

Application diagram



Recommended products

Function	Product	Frequency	Gain (dB)	Type
RF pre-amplifier	Push-Pulls	550MHz	33.5 - 35.5	BGY588N
			33.5 - 35.5	BGY588C
			26.2 - 27.8	BGY587B
		600MHz	21 - 22	BGY687
			750MHz	33.5 - 35.2
		33.5 - 34.5		BGE788
		18 - 19		BGY785A
		870MHz	21 - 22	BGY787
			18 - 19	BGY885A
			21 - 22	BGY887
			33.5 - 34.5	BGY888
			34.5 - 36.5	CGY888C
1000MHz	18 - 19	BGY1085A		

Function	Product	Frequency	Gain (dB)	Type
RF reverse amplifier	Reverse hybrids	5-75 MHz	29.2 - 30.8	BGY68
		5-120 MHz	24.5 - 25.5	BGY66B
		5-200 MHz	23.5 - 24.5	BGY67A

All available in SOT115 package.

Function	Product	Frequency	Gain (dB)	Type
RF power amplifier	Power doublers	550MHz	18-19	BGD502
			19.5 - 20.5	BGD704
		750MHz	18.2 - 18.8	BGD712
			18.2 - 18.8	BGD712C
			20 - 20.6	BGD714
		870MHz	18 - 19	BGD802
			18.2 18.8	BGD812
			19.7 20.3	BGD814
			18.2-18.8	BGD902
			19.7 -20.3	BGD904
			21.2 - 21.8	BGD906
			19.75 - 20.25	CGD914
			19.25 - 19.75	CGD923
			20.5 - 22.5	CGD942C
			23 - 25	CGD944C
		1000MHz	20.5 - 22.5	CGD1042
			20.5 - 22.5	CGD1042H
			22.5 - 24.5	CGD1044
			22.5 - 24.5	CGD1044H

Recommended application notes

BGS67A high-dynamic-range hybrid ampl. reverse ampl. 2-way CATV systems	BGS67A
A hybrid wideband amplifier module for digital CATV networks with BGD902	BGD902

Product highlight: CGD1044H

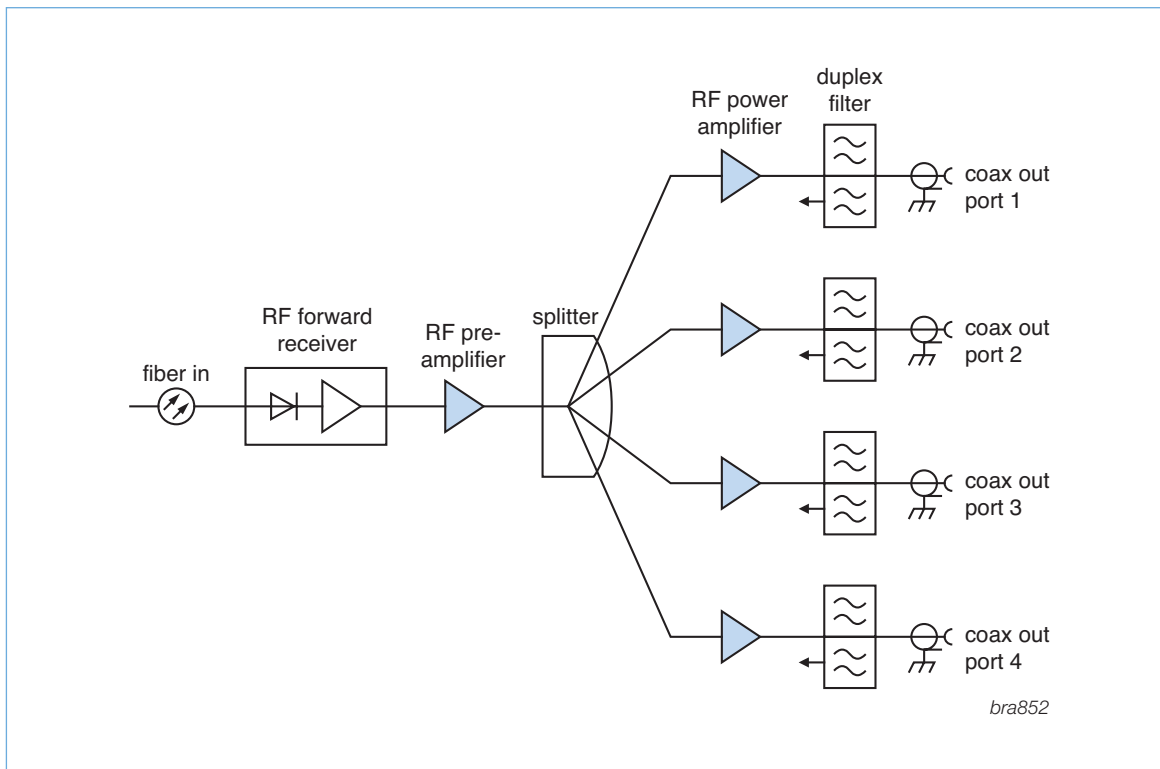
CGD1044H with high-output power is primarily designed for use in fiber deep-optical-node applications (N+0/1/2). This 1GHz solution offers an extended temperature range, high power overstress capabilities and high ESD levels resulting in a low cost of ownership. It's designed for durability and offering superior ruggedness.

Features

- ▶ High-output power
- ▶ Excellent linearity, stability, and reliability
- ▶ High power gain
- ▶ Extremely low noise
- ▶ Silicon Nitride passivity
- ▶ GaAs HFET dies for high-end applications

1.16 CATV optical (optical node with multiple out-ports)

Application diagram



Recommended products

Function	Product	Frequency	Package	Type
RF forward receiver	Forward path receiver	870MHz	SOT115	BGO807
			SOT115	BGO807C
			SOT115	BGO827

Function	Product	Frequency	Gain (dB)	Type
RF pre-amplifier	Push-Pulls	870MHz	18 - 19	BGY885A
			21 - 22	BGY887
	Power doubler	870MHz	18.2 - 18.8	BGD812

Function	Product	Frequency	Gain (dB)	Type
RF power amplifier	Power doublers	870MHz	20.5 - 22.5	CGD942C
			23 - 25	CGD944C

Recommended application notes

Using a Philips optical receiver in CATV applications	All optical receivers
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Product highlight: BGO807C

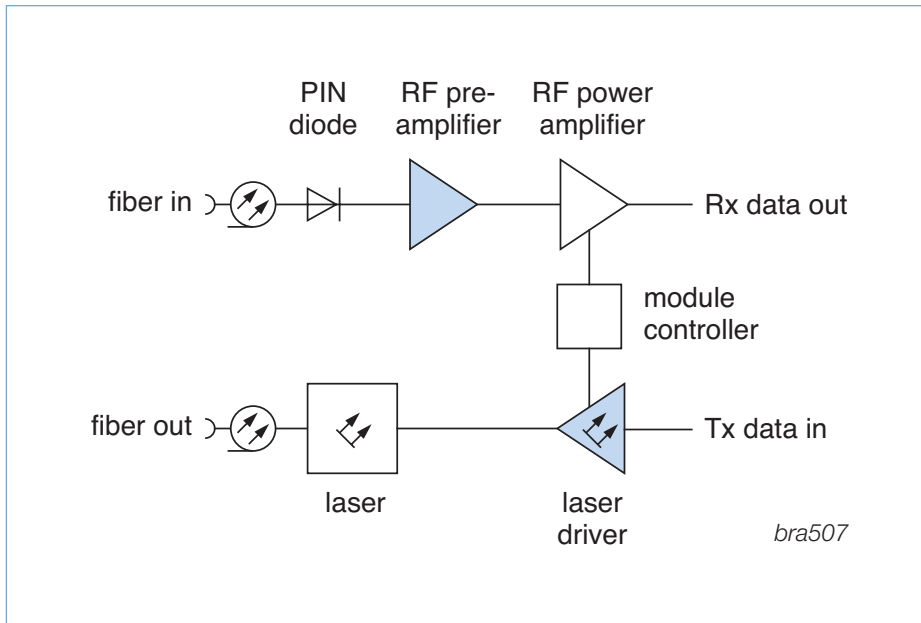
BGO807C is an integrated optical receiver module that provides high output levels and includes an integrated temperature compensated circuitry. In your optical node design, BGO807C enables a high performance/ price ratio and ruggedness. When upgrading an HFC network from analog to digital our BGO807C is the perfect fit.

Features

- ▶ Excellent linearity
- ▶ Low noise
- ▶ Excellent flatness
- ▶ Standard CATV outline
- ▶ Rugged construction
- ▶ Gold metallization ensures excellent reliability
- ▶ High optical input power range

1.17 Optical networking (SFF/SFP modules)

Application diagram



Recommended products

Function	Product	Data rate (Mb/s)	Package	Type
RF pre-amplifier	Trans-impedance amplifier	155	die only	TZA3036
		622	die only	TZA3026
		1200	die only	TZA3046
		2488	die only	TZA3013

Function	Product	Data rate (Mb/s)	Package	Type
Laser driver	Laser driver	1250	SOT560-01	TZA3047B
			SOT560-01	TZA3050

Recommended application notes

OM5811 demo boards supporting TZA47 laser drivers for 30-3200 Mb/s	TZA47
TZA30x6 – Receiver Optical Sub-Assembly*	TZA30x6

* No web link available for this application note. Please ask your Philips sales representative for assistance.

Product highlight TZA3046

TZA3046 transimpedance preamplifier brings high receiver sensitivity, wide dynamic range, and low power dissipation to Receiver Optical Sub Assemblies (ROSA). TZA3046 is optimized for Fibre Channel transmission systems and is equipped with a SFF8472-compliant output of average photo current for RSSI monitoring. A clear bonding layout and identical ports on both side of the die make assembly easy.

Features

- ▶ High receiver sensitivity, low equivalent input noise
- ▶ Exceptionally wide bandwidth
- ▶ On-chip AGC with options for external control
- ▶ Input overload up to 1.5 mA pp
- ▶ Differential outputs
- ▶ Bias voltage for PIN diode
- ▶ Single 3.3-V supply voltage (range: 2.9 to 3.6 V)



What if you could get a cost effective RF transistor up to 20 GHz?

Look at BFU725F, chapter 5.5

2. Product portfolio

NXP RF product catalog:

<http://www.nxp.com/rf>

2.1 New products

DEV = In development

CQS = Customer qualification samples

RFS = Release for supply

Type	Application / Description	Status September 2007	Planned release
NEW: RF diodes			
BB202LX	Varicap for mobile radio in cellulars in 1006 leadless package	RFS	Released
BB178LX	Varicap for TV & Satellite in 1006 leadless package	RFS	Released
BB179BLX	Varicap for TV & Satellite in 1006 leadless package	CQS	Q4 2007
BB179LX	Varicap for TV & Satellite in 1006 leadless package	RFS	Released
BB181LX	Varicap for TV & Satellite in 1006 leadless package	CQS	Q4 2007
BB182LX	Varicap for TV & Satellite in 1006 leadless package	CQS	Q4 2007
BB184LX	Low voltage varicap for TV & Satellite UHF in 1006 leadless package	CQS	Q4 2007
BB185LX	Low voltage varicap for TV & Satellite VHF in 1006 leadless package	RFS	Released
BB187LX	Low voltage varicap for TV & Satellite VHF in 1006 leadless package	CQS	Q4 2007
BAP142LX	Cellular phone, Bluetooth, Cordless phone -RF switch & FE module in 1006 leadless package	RFS	Released
BAP50LX	Cellular phone, Bluetooth, Cordless phone -RF switch & FE module in 1006 leadless package	RFS	Released
BAP51LX	Cellular phone, Bluetooth, Cordless phone -RF switch & FE module in 1006 leadless package	RFS	Released
BAP55LX	Cellular phone, Bluetooth, Cordless phone -RF switch & FE module in 1006 leadless package	RFS	Released
BAP63LX	Cellular phone, Bluetooth, Cordless phone -RF switch & FE module in 1006 leadless package	RFS	Released
BAP64LX	Cellular phone, Bluetooth, Cordless phone -RF switch & FE module in 1006 leadless package	RFS	Released
BAP65LX	Cellular phone, Bluetooth, Cordless phone -RF switch & FE module in 1006 leadless package	RFS	Released
BAP1321LX	Cellular phone, Bluetooth, Cordless phone -RF switch & FE module in 1006 leadless package	RFS	Released
NEW: RF MOS transistors			
BF1208D	Twin MOSFET with two LNAs for TV/VCR/DVD/STB/SAT with internal switching circuit	RFS	Released
BF1214	Twin MOSFET with two identical VHF-optimized LNA's	RFS	Released
NEW: RF IC, Biasing ASIC and pHEMT GaAs transistors			
BGA2714	Silicon Gain Block MMIC for Satellite LNB	RFS	Released
UAF3000TS	Biasing ASICs for Satellite LNB	RFS	Released
UAF4000TS	Biasing ASICs for Satellite LNB	RFS	Released
TFF1000HN	Fully integrated Downconverter for Satellite LNB compliant with European and Asian standards	RFS	Released
TFF1004HN	Fully integrated Downconverter for Satellite LNB compliant with European and Asian standards	RFS	Released
NEW: RF IC WiMAX			
UXA23465	RF WiMAX transceiver 2 Rx/1 Tx	RFS	Released
UXA23466	RF WiMAX transceiver 2 Rx/2 Tx	RFS	Released
UXA23475	RF WiMAX transceiver 2 Rx/1 Tx	RFS	Released
UXA23476	RF WiMAX transceiver 2 Rx/2 Tx	RFS	Released
UXF23480	RF WiMAX transceiver 1 Rx/1 Tx	RFS	Released
UXF23460	RF WiMAX transceiver 1 Rx/1 Tx	RFS	Released
UXA23470	RF WiMAX transceiver 1 Rx/1 Tx	RFS	Released
NEW: SiGeC transistors & MMICs			
BFU725F	SiGeC transistor for high frequency applications: e.g.: DECT, GPS, Wireless LAN, Satellite Radio (DAB)	RFS	Released
BFU705F	SiGeC transistor for high frequency applications: e.g.: LNB 2nd stage (12 GHz)	DEV	Q1 2008
BGU7003	MMIC for high frequency applications	DEV	Q1 2008
BFU780F	SiGeC transistor for high frequency applications with high linearity performance	DEV	Q1 2008
NEW: RF CATV modules			
CGD1042	1000 MHz, 22 dB gain Power Doubler, GaAs HFET SOT115	RFS	Released
CGD1044	1000 MHz, 25 dB gain Power Doubler, GaAs HFET SOT115	RFS	Released
CGD1042H	1000 MHz, 22 dB gain Power Doubler, GaAs HFET SOT115 High output	RFS	Released
CGD1044H	1000 MHz, 25 dB gain Power Doubler, GaAs HFET SOT115 High output	RFS	Released
CGY888C	870 MHz, 35 dB gain Push Pull, GaAs HFET SOT115	RFS	Released

2.2 RF diodes

NXP varicaps:

<http://www.nxp.com/varicaps>

NXP RF PIN diodes:

<http://www.nxp.com/pindiodes>

NXP RF Schottky diodes:

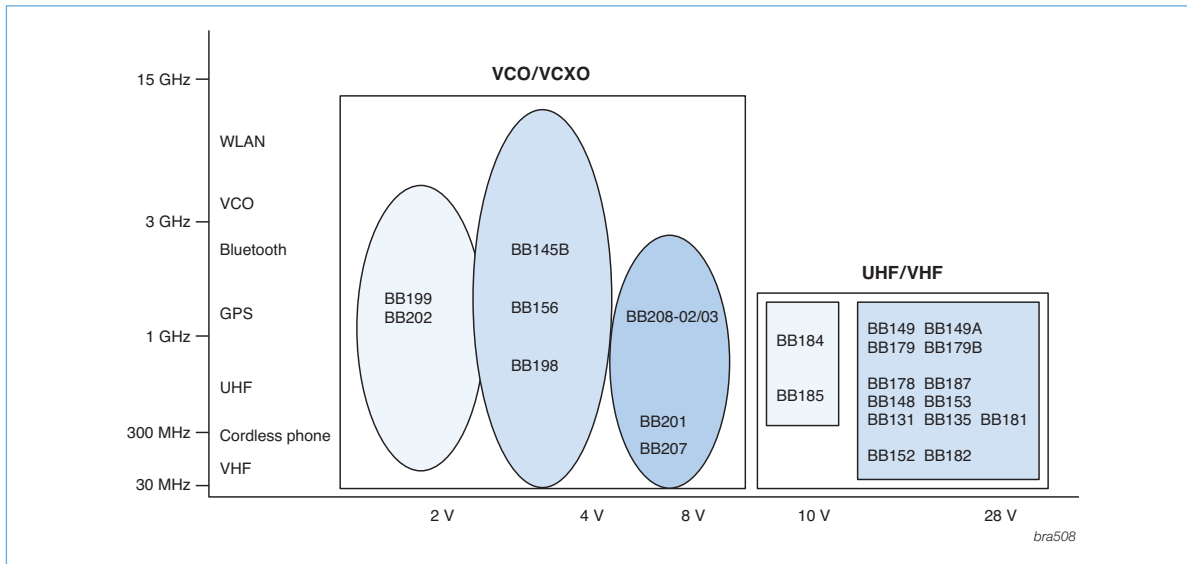
<http://www.nxp.com/rfschottkydiodes>

2.2.1 Varicap diodes

Why choose NXP semiconductors' varicap diodes:

- Reference designs for TV and radio tuning
- Direct matching process
- Small tolerances
- Short leadtimes
- Complete portfolio covering broad frequency range and variety in package (including leadless)
- Reliable volume supply

Varicap diodes line-up per frequency



Many varicap diodes are or will be available in our new UTLP leadless package, look at our varicap portfolio in this chapter. Also more information on UTLP leadless packaging in Chapter X "Packing and Packaging".

VCO varicap diodes

Type	Package	Type of connection	Cd @ Vr (pF)			Cd @ Vr (pF)			TUNING RANGE Cd over voltage range (V)			rs (Ω)
			min	max	(V)	min	max	(V)	ratio (typ.)	V1 to V2		(typ.)
BB145B	SOD523	S	6.4	7.2	1	2.55	2.95	4	2.2 min	1	4	0.6 max
BB202**	SOD523	S	28.2	33.5	0.2	7.2	11.2	2.3	2.5 min	0.2	2.3	0.35
BB202LX	SOD882T	S	28.2	33.5	0.2	7.2	11.2	2.3	2.5 min	0.2	2.3	0,35
BB156	SOD323	S	14.4	17.6	1	4.2	5.4	7.5	3.3	1	7.5	0.4
BB198	SOD523	S	25	28.5	1	4.8	6.8	4	-	-	-	0.8 max
BB199	SOD523	S	36.5	42.5	0.5	11.8	13.8	2	2.8 min	0.5	2	0.25
BB208-02*	SOD523	S	19.9	23.2	1	4.5	5.4	7.5	3.7 – 5.2	1	7.5	0.35
BB208-03*	SOD323	S	19.9	23.2	1	4.5	5.4	7.5	3.7 – 5.2	1	7.5	0.35

Bold = Highly recommended product

Bold Red = New, highly recommended product

* = Including special design for FM car radio (CREST-IC:TEF6860).

** = Including special design for mobile phone tuner ICs.

Type of connection:

S: Single

CC: Common Cathode

Radio varicap diodes: FM radio tuning

Type	Package	Type of connection	Cd @ Vr (pF)			Cd @ Vr (pF)			TUNING RANGE Cd over voltage range (V)			rs (Ω)
			min	max	(V)	min	max	(V)	ratio (typ.)	V1 to V2		(typ.)
BB201	SOT23	CC	89	102	1	25.5	29.7	7.5	3.1	1	7.5	0.25
BB202**	SOD523	S	28.2	33.5	0.2	7.2	11.2	2.3	2.5	0.2	2.3	0.35
BB202LX	SOD882T	S	28.2	33.5	0.2	7.2	11.2	2.3	2.5	0.2	2.3	0,35
BB156	SOD323	S	14.4	17.6	1	4.2	5.4	7.5	2.7	1	7.5	0.4
BB207*	SOT23	CC	76	86	1	25.5	29.7	7.5	2.6	1	7.5	0.2
BB208-02*	SOD523	S	19.9	23.2	1	4.5	5.4	7.5	3.7 – 5.2	1	7.5	0.35
BB208-03*	SOD323	S	19.9	23.2	1	4.5	5.4	7.5	3.7 – 5.2	1	7.5	0.35

Bold = Highly recommended product

Bold Red = New, highly recommended product

* = Including special design for FM car radio (CREST-IC:TEF6860).

** = Including special design for mobile phone tuner ICs.

Type of connection:

S: Single

CC: Common Cathode

TV & satellite varicap diodes - UHF tuning

Type	Package	Type of connection	Cd @ Vr (pF)			TUNING RANGE Cd over voltage range (V)			rs (Ω)	MATCHED SETS	TYPICAL APPLICATIONS			
			min	max	(V)	ratio (typ.)	V1 to V2		(typ.)	%	TV	VCO	SAT.	STB
Matched														
BB149	SOD323	S	1.90	2.25	28	9.0	1	28	0.75	2.0	X	-	-	X
BB149A	SOD323	S	1.951	2.225	28	9.0	1	28	0.75	2.0	X	-	-	X
BB179	SOD523	S	1.951	2.225	28	9.0	1	28	0.75 max	2.0	X	X	-	X
BB179LX	SOD882T	S	1.951	2.225	28	9.0	1	28	0.65	2.0	X	X	-	X
BB179B	SOD523	S	1.90	2.25	28	9.0	1	28	0.75 max	2.0	X	-	-	X
BB179BLX	SOD882T	S	1.90	2.25	28	9.0	1	28	0.65	2.0	X	-	-	X
BB184	SOD523	S	1.87	2.13	10	7	1	10	0.65	2.0	X	X	-	-
BB184LX	SOD882T	S	1.87	2.13	10	7	1	10	0.65	2.0	X	X	-	-
Unmatched														
BB135	SOD323	S	1.70	2.10	28	9.9 - 12	0.5	28	0.75	-	X	X	-	-

Red = New

Bold = Highly recommended product

Bold Red = New, highly recommended product

Type of connection:

S: Single

CC: Common Cathode

TV & satellite varicap diodes - VHF tuning

Type	Package	Type of connection	Cd @ Vr (pF)			TUNING RANGE Cd over voltage range (V)			rs (Ω)	MATCHED SETS	TYPICAL APPLICATIONS			
			min	max	(V)	ratio (typ.)	V1 to V2	(typ.)			%	TV	VCO	SAT.
Matched														
BB148	SOD323	S	2.4	2.75	28	15	1	28	0.9 max	2.0	X	-	-	X
BB152	SOD323	S	2.48	2.89	28	22	1	28	1.0	2.0	X	-	-	X
BB153	SOD323	S	2.361	2.754	28	15	1	28	0.65	2.0	X	-	-	X
BB178	SOD523	S	2.361	2.754	28	15	1	28	0.65	2.0	X	-	-	X
BB178LX	SOD882T	S	2.361	2.754	28	15	1	28	0.7	2.0	X	-	-	X
BB182	SOD523	S	2.48	2.89	28	22	1	28	1.0	2.0	X	-	-	X
BB182LX	SOD882T	S	2.48	2.89	28	22	1	28	1.0	2.0	X	-	-	X
BB185LX	SOD882T	S	2.45	2.97	10	12	1	10	0.75	2.0	X	X	-	-
BB187	SOD523	S	2.57	2.92	25	11 min.	2	25	0.75 max	2.0	X	-	-	X
BB187LX	SOD882T	S	2.57	2.92	25	11 min	2	25	0.75	2.0	X	-	-	X
Unmatched														
BB131	SOD323	S	0.7	1.055	28	14	0.5	28	3 max	-	X	-	X	X
BB181	SOD523	S	0.7	1.055	28	14	0.5	28	3 max	-	X	-	X	X
BB181LX	SOD882T	S	0.7	1.055	28	14	0.5	28	2.0	-	X	-	X	X
BBY40	SOT23		4.3	6.0	25	5.5	3	25	0.7 max	-	X	-	-	X

Red = New

Bold = Highly recommended product

Bold Red = New, highly recommended product

Type of connection:

S: Single

CC: Common Cathode

2.2.2 PIN diodes

Why choose NXP Semiconductors' PIN diodes:

- Broad portfolio
- Unrivalled performance
- Short leadtimes
- Low series inductance
- Low insertion loss
- Low capacitance

PIN diodes

Type	Package	Conf	Limits		RD (Ω) typ @			Cd (pF) type @		
			Vr(V)	If(mA)	0.5mA	1 mA	10 mA	0V	1V	20V
BAP50-02	SOD523	S	50	50	25	14	3	0.4	0.3	0.22 @ 5V
BAP50-03	SOD323	S	50	50	25	14	3	0.4	0.3	0.2 @ 5V
BAP50-04	SOT23	SS	50	50	25	14	3	0.45	0.35	0.3 @ 5V
BAP50-04W	SOT323	SS	50	50	25	14	3	0.45	0.35	0.3 @ 5V
BAP50-05	SOT23	CC	50	50	25	14	3	0.45	0.35	0.3 @ 5V
BAP50-05W	SOT323	CC	50	50	25	14	3	0.45	0.35	0.3 @ 5V
BAP50LX	SOD882T	S	50	50	25	14	3	0.45	0.35	0.3 @ 5V
BAP51LX	SOD882T	S	60	60	5.5	3.6	1.5	0.4	0.3	0.2 @ 5V
BAP51-02	SOD523	S	60	50	5.5	3.6	1.5	0.4	0.3	0.2 @ 5V
BAP51-03	SOD323	S	50	50	5.5	3.6	1.5	0.4	0.3	0.2 @ 5V
BAP51-04W	SOT323	SS	50	50	5.5	3.6	1.5	0.4	0.3	0.2 @ 5V
BAP51-05W	SOT323	CC	50	50	5.5	3.6	1.5	0.4	0.3	0.2 @ 5V
BAP51-06W	SOT323	CA	50	50	5.5	3.6	2	0.4	0.3	0.2 @ 5V
BAP55LX	SOD882T	S	50	100	3.4	2.3	1	0.27	0.23	0.18 @ 5V
BAP63-02	SOD523	S	50	100	2.5	1.95	1.17	0.36	0.32	0.25
BAP63-03	SOD323	S	50	100	2.5	1.95	1.17	0.4	0.35	0.27
BAP63-05W	SOT323	CC	50	100	2.5	1.95	1.17	0.4	0.35	0.3
BAP63LX	SOD882T	S	50	100	2.5	1.95	1.17	0.4	0.35	0.3
BAP64-02	SOD523	S	175	100	20	10	2	0.48	0.35	0.23
BAP64-03	SOD323	S	175	100	20	10	2	0.48	0.35	0.23
BAP64-04	SOT23	SS	175	100	20	10	2	0.52	0.37	0.23
BAP64-04W	SOT323	SS	100	100	20	10	2	0.52	0.37	0.23
BAP64-05	SOT23	CC	175	100	20	10	2	0.52	0.37	0.23
BAP64-05W	SOT323	CC	100	100	20	10	2	0.52	0.37	0.23
BAP64-06	SOT23	CA	175	100	20	10	2	0.52	0.37	0.23
BAP64-06W	SOT323	CA	100	100	20	10	2	0.52	0.37	0.23
BAP64LX	SOD882T	S	100	100	20	10	2	0.52	0.37	0.23
BAP65-02	SOD523	S	30	100	-	1	0.56	0.65	0.55	0.375
BAP65-03	SOD323	S	30	100	-	1	0.56	0.65	0.55	0.375
BAP65-05	SOT23	CC	30	100	-	1	0.56	0.65	0.55	0.375
BAP65-05W	SOT323	CC	30	100	-	1	0.56	0.65	0.55	0.375
BAP65LX	SOD882T	S	30	100	-	1	0.56	0.65	0.6	0.375
BAP70AM	SOT363	SS	50	100	77	40	5.4	0.57	0.4	0.2
BAP70-02	SOD523	S	50	100	77	40	5.4	0.57	0.4	0.2
BAP70-03	SOD323	S	50	100	77	40	5.4	0.57	0.4	0.2
BAP70-04W	SOT323	SS	50	100	77	40	5.4	0.57	0.4	0.2
BAP70-05	SOT23	CC	50	100	77	40	5.4	0.57	0.4	0.2
BAP1321-02	SOD523	S	60	100	3.4	2.4	1.2	0.4	0.35	0.25
BAP1321-03	SOD323	S	60	100	3.4	2.4	1.2	0.4	0.35	0.25
BAP1321-04	SOT23	SS	60	100	3.4	2.4	1.2	0.4	0.35	0.25
BAP1321LX	SOD882T	S	60	100	3.4	2.4	1.2	0.4	0.35	0.25
BAP142LX	SOD882T	S	50	100	3.3	2.4	1	0.26	0.23	0.15

Bold = Highly recommended product

Bold Red = New, highly recommended product

S = Single

SS = Series

CC = Common Cathode

CA = Common Anode

2.2.3 Band-switch diodes

Why choose NXP Semiconductors' bandswitch diodes:

- Reliable volume supplier
- Short leadtimes
- Low series Inductance
- Low Insertion loss
- Low capacitance
- High reverse Isolation

Type	Package	MAXIMUM RATINGS		CHARACTERISTICS ; maximals					
		VR(V)	IF(mA)	Rd @ IF and f			Cd @VR and f		
				Ω	(mA)	(MHz)	(pF)	(V)	(MHz)
BA277	SOD523	35	100	0.7	2	100	1.2	6	1
BA278	SOD523	35	100	0.7	2	100	1.2	6	1
BA891	SOD523	35	100	0.7	3	100	0.9	3	1
BA591	SOD323	35	100	0.7	3	100	0.9	3	1
BA792	SOD110	35	100	0.7	3	200	1.1	3	1 to 100
BAT18	SOT23	35	100	0.7	5	200	1.0	20	1

Bold = Highly recommended product

2.2.4 Schottky diodes

Why choose NXP Semiconductors' schottky diodes:

- (Very) low diode capacitance
- (Very) low forward voltage
- Single and triple-isolated diode
- (Ultra / very) small package

Applications

- Digital applications:
 - ultra high-speed switching
 - clamping circuits
- RF applications:
 - diode ring mixer
 - RF detector
 - RF voltage doubler

Low-capacitance Schottky diodes

Type	Package	VR max. (V)	IF max. (mA)	VF max. (mV)	CD max. (pF)
BAT17	SOT23	4	30	450 @ IF = 1 mA	1 @ VR = 0 V
PMBD353	SOT23	4	30	450 @ IF = 1 mA	1 @ VR = 0 V
PMBD354	SOT23	4	30	450 @ IF = 1 mA	1 @ VR = 0 V
1PS76SB17	SOD323	4	30	450 @ IF = 1 mA	1 @ VR = 0 V
1PS66SB17	SOT666	4	30	450 @ IF = 1 mA	1 @ VR = 0 V
1PS79SB17	SOD523	4	30	450 @ IF = 1 mA	1 @ VR = 0 V
1PS88SB82	SOT363	15	30	340 @ IF = 1 mA	1 @ VR = 0 V
1PS70SB82	SOT323	15	30	340 @ IF = 1 mA	1 @ VR = 0 V
1PS70SB84	SOT323	15	30	340 @ IF = 1 mA	1 @ VR = 0 V
1PS70SB85	SOT323	15	30	340 @ IF = 1 mA	1 @ VR = 0 V
1PS70SB86	SOT323	15	30	340 @ IF = 1 mA	1 @ VR = 0 V
1PS66SB82	SOT666	15	30	340 @ IF = 1 mA	1 @ VR = 0 V
1PS10SB82	SOD882	15	30	340 @ IF = 1 mA	1 @ VR = 0 V

2.3 RF Bipolar transistors

2.3.1 Wideband transistors

RF wideband transistors:

<http://www.nxp.com/rftransistors>

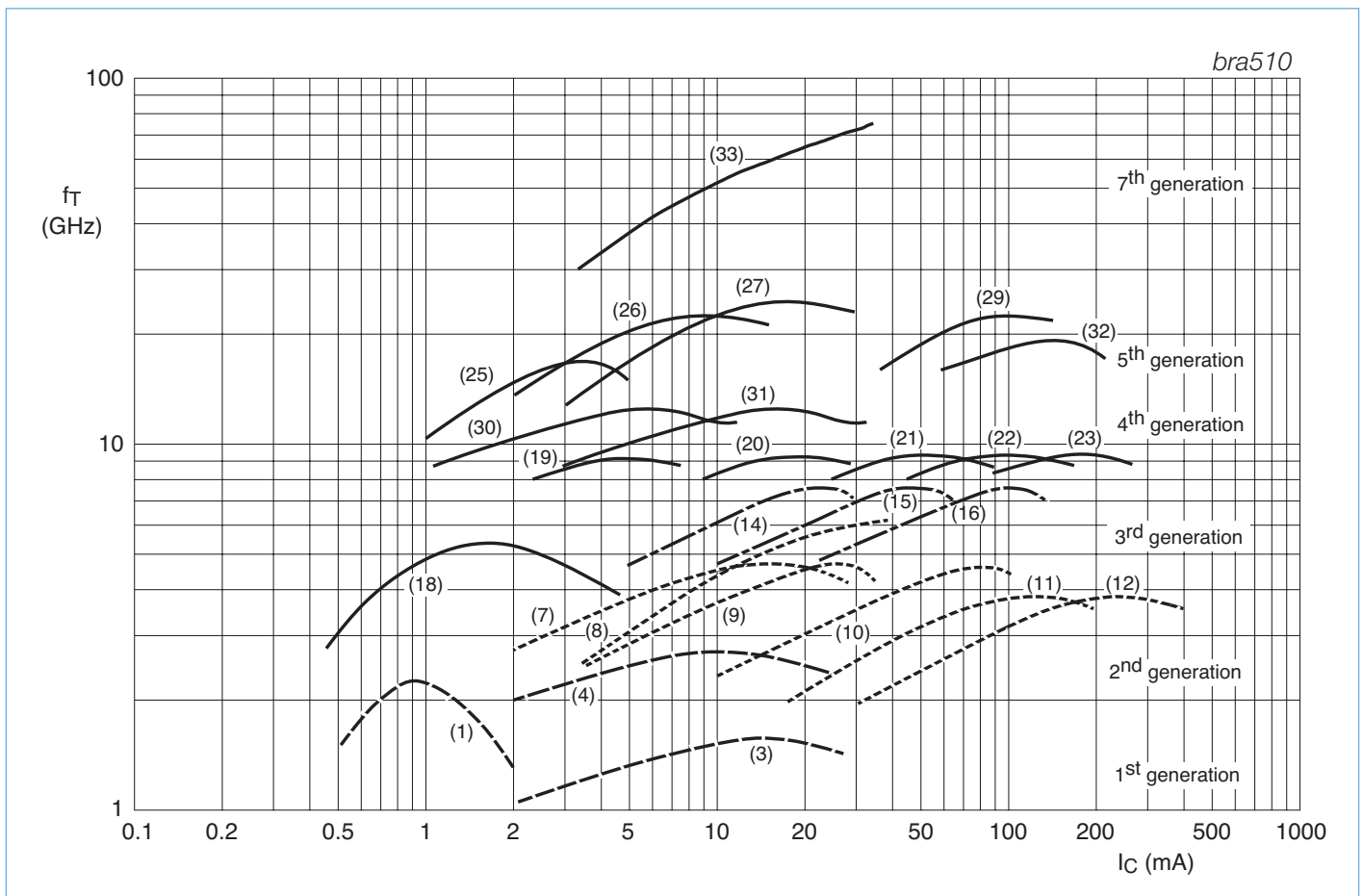
Why choose NXP Semiconductors' wideband transistors:

- Broad portfolio (1st - 7th generation)
- Short leadtimes
- Smallest packages
- Volume delivery

Wideband transistors

The f_T - I_C curve represents Transition Frequency (f_T) characteristics as a function of collector current (I_C) for the six generations of RF wideband transistors. A group of transistors having the same collector current (I_C) & similar transition frequencies (f_T) represents a curve. The curve number matches products in the table, detailing their RF characteristics.

Wideband transistors line-up per frequency



Wideband transistors (RF small signal)

Type	Curve	Package	F_r	V_{ce0}	I_c	P_{tot}	Polarity	GUM	NF	@	GUM	NF	@	V_o (mV)	P1 (1dB) (dBm)	ITO (dBm)	@ I_c & V_{ce}	
			(GHz)	(V)	(mA)	(mW)		(dB)	(dB)	(MHz)	(dB)	(dB)	(MHz)				(mA)	(V)
BFG10(X)	23	SOT143	-	8	250	250	NPN	-	-	-	7	-	1900	-	-	-	-	-
BFG10W/X	23	SOT343	-	10	250	400	NPN	-	-	-	7	-	1900	-	-	-	-	-
BLT80	-	SOT223	-	10	250	2000	NPN	>6	-	900	-	-	-	-	-	-	-	-
BLT81	-	SOT223	-	9.5	500	2000	NPN	>6.5	-	900	-	-	-	-	-	-	-	-
BLT50	-	SOT223	-	10	500	2000	NPN	10	-	470	-	-	-	-	-	-	-	-
BLT70	-	SOT223	-	8	250	2100	NPN	>6	-	900	-	-	-	-	-	-	-	-
BFS17	3	SOT23	1	15	25	300	NPN	-	4.5	500	-	-	-	-	-	-	-	-
BFS17W	3	SOT323	1.6	15	50	300	NPN	-	4.5	500	-	-	-	-	-	-	-	-
BFT25	1	SOT23	2.3	5	6.5	30	NPN	18	3.8	500	12	-	800	-	-	-	-	-
BFS17A	4	SOT23	2.8	15	25	300	NPN	13.5	2.5	800	-	-	-	150	-	-	14	10
BFG35	11	SOT223	4	18	150	1000	NPN	15	-	500	11	-	800	750	-	-	100	10
BFQ18A	11	SOT89	4	18	150	1000	NPN	-	-	-	-	-	-	-	-	-	-	-
BFG25A/X	18	SOT143	5	5	6.5	32	NPN	18	1.8	1000	-	-	-	-	-	-	-	-
BFG25AW/X	18	SOT343	5	5	6.5	500	NPN	16	2	1000	8	-	2000	-	-	-	-	-
BFG31	10	SOT223	5	15	100	1000	PNP	16	-	500	12	-	800	550	-	-	70	10
BFG90(X)	22	SOT143	5	15	200	400	NPN	13	-	900	7.5	-	2000	-	-	-	-	-
BFG92A(X)	7	SOT143	5	15	25	400	NPN	16	2	1000	11	3	2000	-	-	-	-	-
BFQ149	10	SOT89	5	15	100	1000	PNP	12	3.75	500	-	-	-	-	-	-	-	-
BFR106	10	SOT23	5	15	100	500	NPN	11.5	3.5	800	-	-	-	350	-	-	50	9
BFR92A	7	SOT23	5	15	25	300	NPN	14	2.1	1000	8	3	2000	150	-	-	14	10
BFR92AW	7	SOT323	5	15	25	300	NPN	14	2	1000	8	3	2000	-	-	-	-	-
BFR93AW	8	SOT323	5	12	35	300	NPN	13	1.5	1000	8	2.1	2000	-	-	-	-	-
BFS25A	18	SOT323	5	5	6.5	32	NPN	13	1.8	1000	-	-	-	-	-	-	-	-
BFT25A	18	SOT23	5	5	6.5	32	NPN	15	1.8	1000	-	-	-	-	-	-	-	-
BFT92	7	SOT23	5	15	25	300	PNP	18	2.5	500	-	-	-	150	-	-	14	10
BFT92W	7	SOT323	4	15	35	300	PNP	17	2.5	500	11	3	1000	-	-	-	-	-
BFT93	9	SOT23	5	12	35	300	PNP	16.5	2.4	500	-	-	-	300	-	-	30	5
BFT93W	9	SOT323	5	12	50	300	PNP	15.5	2.4	500	10	3	1000	-	-	-	-	-
BFG97	10	SOT223	5.5	15	100	1000	NPN	16	-	500	12	-	800	700	-	-	70	10
BFQ19	10	SOT89	5.5	15	100	1000	NPN	11.5	3.3	500	7.5	-	800	-	-	-	-	-
BFG93A(X)	8	SOT143	6	12	35	300	NPN	16	1.7	1000	10	2.3	2000	-	-	-	-	-
BFG94	8	SOT223	6	12	60	700	NPN	19	2.7	500	13.5	3	1000	500	21.5	34	45	10
BFR93A(R)	8	SOT23	6	12	35	300	NPN	13	1.9	1000	-	3	2000	425	-	-	30	8
BFG135	16	SOT223	7	15	150	1000	NPN	16	-	500	12	-	800	850	-	-	100	10
BFG591	22	SOT223	7	15	200	2000	NPN	13	-	900	7.5	-	2000	700	-	-	70	12
BFG591	22	SOT89	7	15	200	2000	NPN	11	-	900	5.5	-	2000	-	-	-	-	-
BFG198	15	SOT223	8	10	100	1000	NPN	18	-	500	15	-	800	700	-	-	70	8
BFG67(X)	14	SOT143	8	10	50	380	NPN	17	1.7	1000	10	2.5	2000	-	-	-	-	-
BFQ67	14	SOT23	8	10	50	300	NPN	14	1.7	1000	8	2.7	2000	-	-	-	-	-
BFQ67W	14	SOT323	8	10	50	300	NPN	13	1.3	1000	8	2.7	2000	-	-	-	-	-
PBR941	20	SOT23	8	10	50	360	NPN	15	1.4	1000	9.5	2	2000	-	-	-	-	-
PBR951	21	SOT23	8	10	100	365	NPN	14	1.3	1000	8	2	2000	-	-	-	-	-
PRF947	20	SOT323	8.5	10	50	250	NPN	16	1.5	1000	10	2.1	2000	-	-	-	-	-
PRF957	21	SOT323	8.5	10	100	270	NPN	15	1.3	1000	9.2	1.8	2000	-	-	-	-	-
BFG505(X)	19	SOT143	9	15	18	150	NPN	20	1.6	900	13	1.9	2000	-	4	10	5	6
BFG505W/X	19	SOT343	9	15	18	500	NPN	19	1.6	900	12	1.9	2000	-	1	10	5	6
BFG520(X)	20	SOT143	9	15	70	300	NPN	19	1.6	900	13	1.9	2000	275	17	26	20	6
BFG520W(X)	20	SOT343	9	15	70	500	NPN	17	1.1	900	11	1.85	2000	275	17	26	20	6
BFG540(X)	21	SOT143	9	15	120	500	NPN	18	1.3	900	11	2.1	2000	500	21	34	40	8
BFG540W(X/XR)	21	SOT343	9	15	120	500	NPN	16	1.3	900	10	2.1	2000	500	21	34	40	8
BFG541	21	SOT223	9	15	120	650	NPN	15	1.3	900	9	2.1	2000	500	21	34	40	8
BFM505	19	SOT363	9	8	18	500	NPN	17	1.1	900	10	1.9	2000	-	-	-	-	-
BFM520	20	SOT363	9	8	70	1000	NPN	15	1.2	900	9	1.9	2000	-	-	-	-	-
BFQ540	21	SOT89	9	15	120	1200	NPN	-	1.9	900	-	-	-	500	-	-	40	8
BFR505	19	SOT23	9	15	18	150	NPN	17	1.2	900	10	1.9	2000	-	4	10	5	6
BFR505T	19	SOT416	9	15	18	150	NPN	17	1.2	900	-	-	-	-	-	-	-	-
BFR520	20	SOT23	9	15	70	300	NPN	15	1.1	900	9	1.9	2000	-	17	26	20	6
BFR520T	20	SOT416	9	-	70	150	NPN	15	1.1	900	9	1.9	2000	-	17	26	20	-
BFR540	21	SOT23	9	15	120	500	NPN	14	1.3	900	7	2.1	2000	550	21	34	40	8
BFS505	19	SOT323	9	15	18	150	NPN	17	1.2	900	10	1.9	2000	-	4	10	5	6
BFS520	20	SOT323	9	15	70	300	NPN	15	1.1	900	9	1.9	2000	-	17	26	20	6
BFS540	21	SOT323	9	15	120	500	NPN	14	1.3	900	8	2.1	2000	-	21	34	40	8
PRF949	20	SOT416	9	10	50	150	NPN	16	1.5	1000	10	2.1	2000	-	-	-	-	-
BFG310W/XR	30	SOT343XR	14	6	10	60	NPN	18	1.0	1000	-	-	-	-	1.8	8.5	5	3
BFG310/XR	30	SOT143XR	14	6	10	60	NPN	18	1.0	1000	-	-	-	-	1.8	8.5	5	3
BFG325W/XR	31	SOT343XR	14	6	35	210	NPN	18.3	1.1	3000	-	-	-	-	8.7	19.4	15	3
BFG325/XR	31	SOT143XR	14	6	35	210	NPN	18.3	1.1	3000	-	-	-	-	8.7	19.4	15	3
BFG403W	25	SOT343	17	4.5	3.6	16	NPN	20	1	900	2.2	1.6	2000	-	5	6	1	1
BFG21W	29	SOT343	18	4.5	500	600	NPN	-	-	-	10	-	1900	-	-	-	-	-
BFG480W	32	SOT343	21	4.5	250	360	NPN	-	1.2	900	16	1.8	2000	-	20	28	80	2
BFG410W	26	SOT343	22	4.5	12	54	NPN	-	0.9	900	21	1.2	2000	-	5	15	10	2
BFG424F	27	SOT343F	25	4.5	30	135	NPN	-	0.8	900	23	1.2	2000	-	12	22	25	2
BFG424W	27	SOT343	25	4.5	30	135	NPN	-	0.8	900	22	1.2	2000	-	12	22	25	2
BFG425W	27	SOT343	25	4.5	30	135	NPN	-	0.8	900	20	1.2	2000	-	12	22	25	2
BFU725F	33	SOT343F	70	2.9	40	-	NPN	25	0.7	2400	17	0.7	5800	-	8	19	25	2

Bold = Highly recommended product

Bold Red = New, highly recommended product



What if you could improve the reception of your smart phone?

Look at BAW filters and duplexers, chapter 5.1

2.4 RF ICs

2.4.1 MMICs

NXP RF MMICs:

<http://www.nxp.com/mmics>

Why choose NXP Semiconductors' MMICs:

- Reduced RF component count
- Easy circuit design-in
- Reduced board size
- Short time-to-market
- Broad portfolio
- Volume delivery
- Short leadtimes

General-purpose wideband amplifiers (50 Ohm gain blocks)

Type	Package	@		Fu ⁽¹⁾ (GHz)	@ 1GHz					Gain ⁽³⁾ (dB) @				Limits		
		Vs (V)	Is (mA)		@-3dB (dB)	NF (dB)	Psat (dBm)	Gain ⁽³⁾ (dB)	P1dB (dBm)	OIP3 (dBm)	100 MHz	2.2 GHz	2.6 GHz	3.0 GHz	Vs (V)	Is (mA)
BGA2711	SOT363	5	12.6	3.6 ⁽²⁾	4.8	2.8	13.1	-0.7	8.3	13.0	14.1	13.8	12.7	6	20	200
BGA2748	SOT363	3	5.7	1.9	1.9 ⁽²⁾	-2.3	21.8	-9.2	-1.9	14.8	17.6	15.0	11.9	4	15	200
BGA2771	SOT363	3	33.3	2.4	4.5	13.2 ⁽²⁾	21.4	12.1	21.9	20.3	20.4	17.9	15.5	4	50	200
BGA2776	SOT363	5	24.4	2.8	4.9	10.5	23.2 ⁽²⁾	7.2	18.6	22.4	23.2	21.8	19.3	6	34	200
BGA2709	SOT363	5	23.5	3.6	4.0	12.5	22.7	8.3	22	22.2	23.0	22.1	21.1	6	35	200
BGA2712	SOT363	5	12.3	3.2	3.9	4.8	21.3	0.2	11	20.8	21.9	21.2	19.3	6	25	200
BGM1011	SOT363	5	25.5	-	4.7	13.8	30 ⁽²⁾	12.2	23	25.0	37.0	32.0	28.0	6	35	200
BGM1012	SOT363	3	14.6 ⁽²⁾	3.6	4.8	9.7	20.1	5.6	18	19.5	20.4	19.9	18.7	4	50	200
BGM1013	SOT363	5	27.5	2.1	4.6	14.0	35.5 ⁽²⁾	12.0	22.7	35.2	31.8	29.7	26.1	6	35	200
BGM1014	SOT363	5	21.0 ⁽²⁾	2.5	4.2	12.9	32.3	11.2	20.5	30.0	34.1	30.5	26.4	6	30	200
BGA2714	SOT363	3	4.58	2.7	2.2	-3.4	20.4	-7.9	2.1	20.8	20.8	19.4	16.8	4	10	200
BGA2715	SOT363	5	4.3 ⁽²⁾	3.3	2.6	-4.0	21.7	-8.0	2.3	13.3	23.3	22.1	20.1	6	8	200
BGA2716	SOT363	5	15.9 ⁽²⁾	3.2	5.3	11.6	22.9	8.9	22.2	22.1	22.8	22.1	20.8	6	25	200
BGA2717	SOT363	5	8.0	3.2	2.3 ⁽²⁾	1.4	23.9	-2.6	10.0	18.6	25.1	24.0	22.1	6	15	200

Bold Red = New, highly recommended product

Notes: ⁽¹⁾ Upper -3 dB point, to gain at 1 GHz. ⁽²⁾ Optimized parameter ⁽³⁾ Gain = |S₂₁|²

2-stage variable-gain linear amplifier

Type	Package	@		Frequency Range	@ 900MHz				@1900 MHz				Limits		
		Vs (V)	Is (mA)		Gain ⁽¹⁾ (dB)	DG ⁽²⁾ (dB)	P1dB (dBm)	ACPR (dBc)	Gain ⁽¹⁾ (dB)	DG ⁽²⁾ (dB)	P1dB (dBm)	ACPR (dBc)	Vs (V)	Is (mA)	Ptot (mW)
BGA2031/1	SOT363	3	51	800-2500	24	62	11	49	23	56	13	49	3.3	77	200

Notes: ⁽¹⁾ Gain = GP, power gain. ⁽²⁾ DG = Gain control range

Wideband linear mixer

Type	Package	@		RF Input	IF Output	@ 880MHz			@1900 MHz			Limits		
		Vs (V)	Is (mA)	Frequency Range	Frequency Range	NF (dB)	Gain ⁽¹⁾ (dB)	OIP3 (dBm)	NF (dB)	Gain ⁽¹⁾ (dB)	OIP3 (dBm)	Vs (V)	Is (mA)	Ptot (mW)
BGA2022	SOT363	3	6	800-2500	50-500	9	5	4	9	6	10	4	10	40

Notes: ⁽¹⁾ Gain = GP, power gain. ⁽²⁾ DG = Gain control range

Low-noise wideband amplifiers

Type	Package	@		@ 900MHz			@1800 MHz			Gain ⁽³⁾ (dB) @				Limits		
		Vs (V)	Is (mA)	NF (dB)	Gain (dB)	IIP3 (dBm)	NF (dB)	Gain (dB)	IIP3 (dBm)	100 MHz	1 GHz	2.6 GHz	3.0 GHz	Vs (V)	Is (mA)	Ptot (mW)
BGA2001	SOT343R	2.5	4	1.3	22 ⁽¹⁾	-7.4	1.3	19.5 ⁽¹⁾	-4.5	20	17.1	11.6	10.7	4.5	30	135
BGA2003	SOT343R	2.5	10 ⁽²⁾	1.8	24 ⁽¹⁾	-6.5	1.8	16 ⁽¹⁾	-4.8	26	18.6	11.1	10.1	4.5	30	135
BGA2011	SOT363	3	15	1.5	19 ⁽³⁾	10	-	-	-	24	14.8	8	6.5	4.5	30	135
BGA2012	SOT363	3	7	-	-	-	1.7	16 ⁽³⁾	10	22	18.2	11.6	10.5	4.5	15	70

Notes: ⁽¹⁾ MSG ⁽²⁾ Adjustable bias ⁽³⁾ |S₂₁|²

General-purpose, med. power ampl. (50 ohm gain blocks)

Type	Package	Ⓢ		@ 900MHz				@1800 MHz				Gain ⁽²⁾	Limits		
		V _s ⁽¹⁾	I _s	NF	Gain ⁽²⁾	OIP3	P1dB	NF	Gain ⁽²⁾	OIP3	P1dB	2.5	V _s ⁽¹⁾	I _s	P _{tot}
		(V)	(mA)	(dB)	(dB)	(dBm)	(dBm)	(dB)	(dB)	(dBm)	(dBm)	GHz	(V)	(mA)	(mW)
BGA6289	SOT89	4.1	84	3.5	15	31	17	3.7	13	28	15	12	6	120	480
BGA6489	SOT89	5.1	78	3.1	20	33	20	3.3	16	30	17	15	6	120	480
BGA6589	SOT89	4.8	81	3.0	22	33	21	3.3	17	32	20	15	6	120	480

Notes: ⁽¹⁾ Device voltage without bias resistor. ⁽²⁾ Gain = |S₂₁|²

2.4.2 Satellite LNB RF ICs

Why choose NXP Semiconductors' RF ICs:

- Lowest total cost of ownership
- Alignment free concept
- Easy circuit design-in
- Improved LO stability

Satellite LNB Downconverter ICs

	Package	Input frequency range	Conversion gain	Noise figure	Output IP3	Switched LO frequency
		(GHz)	G _c (dB)	NF (dB)	IP3(out) (dB)	(GHz)
TFF1000HN	SOT616	10.7 to 12.75	42	9	10	9.75 / 10.6
TFF1004HN	SOT616	10.7 to 12.75	32	9	10	9.75 / 10.6

Satellite LNB Biasing ICs

	Package	Supply voltage	Drain voltage	Drain current	Supply current	Polarisation detection voltage
		V _{cc} (V)	V _D (V)	I _{DO} (mA)	I _{CC} (mA)	VPOL (V)
UAF3000TS	SOT360	3.3 or 5	2	10	6	14.75
UAF4000TS	SOT403	3.3 or 5	2.2	10	6	-

2.4.3 WiMAX RF ICs

Why choose NXP Semiconductors' RF WiMAX transceivers:

- Extremely low noise figure
- Support for flexible calibration techniques ensures optimum performance and lowest power
- Field proven solution
- No external IF filter required
- Minimal external component requirement

RF WiMAX transceivers

	Frequency range (GHz)	Type	NF (dB)	Rx gain (max)	ICC (mA) RX/TX	Tx gain range (dB)	Linear output power meeting spectrum mask (dBm)	Package size HVQFN48 (mm)
UXA23465	2.3 - 2.7	2 Rx/1 Tx	2,5	87	81/78	74	+2.5 (TTA) +1 (ETSI, FCC)	6 x 6 x 0.85
UXA23466	2.3 - 2.7	2 Rx/2 Tx	2,5	87	81/140	74	+2.5 (TTA) +1 (ETSI, FCC)	6 x 6 x 0.85
UXA23475	3.3 - 3.8	2 Rx/1 Tx	3	87	83/85	74	0 (ETSI)	6 x 6 x 0.85
UXA23476	3.3 - 3.8	2 Rx/2 Tx	3	87	83/154	74	0 (ETSI)	6 x 6 x 0.85
UXF23480	2.3 - 2.4	1 Rx/1 Tx	3,2	79	129/153	74	+1	7 x 7 x 0.85
UXF23460	2.5 - 2.7	1 Rx/1 Tx	3,5	77	129/140	74	+2	7 x 7 x 0.85
UXA23470	3.3 - 3.8	2 Rx/1 Tx	3	87	50/85	74	(0) ETSI	6 x 6 x 0.85

Bold Red = New, highly recommended product

2.5 RF MOS transistors

2.5.1 JFETs

NXP RF FETs:

<http://www.nxp.com/rffets>

Why choose NXP Semiconductors' JFETs:

- Reliable volume supplier
- Short leadtimes
- Broad portfolio

N-channel junction field-effect transistors for switching

Type	Package	V _{DS} (V)	I _G (mA)	CHARACTERISTICS										
				I _{DSS} (mA)		-V _{GSoff} (V)		R _{DS(on)} (Ω)	C _{rs} (pF)		t _{on} (ns)		t _{off} (ns)	
				max	max	min	max	min	max	max	min	max	typ	max
BSR56	SOT23	40	50	50	-	4	10	25	-	5	-	-	-	25
BSR57	SOT23	40	50	20	100	2	6	40	-	5	-	-	-	50
BSR58	SOT23	40	50	8	80	0.8	4	60	-	5	-	-	-	100
PMBFJ108	SOT23	25	50	80	-	3	10	8	-	15	4	-	6	-
PMBFJ109	SOT23	25	50	40	-	2	6	12	-	15	4	-	6	-
PMBFJ110	SOT23	25	50	10	-	0.5	4	18	-	15	4	-	6	-
PMBFJ111	SOT23	40	50	20	-	3	10	30	-	typ.3	13	-	35	-
PMBFJ112	SOT23	40	50	5	-	1	5	50	-	typ.3	13	-	35	-
PMBFJ113	SOT23	40	50	2	-	0.5	3	100	-	typ.3	13	-	35	-
J108	SOT54	25	50	80	-	3	10	8	-	15	4	-	6	-
J109	SOT54	25	50	40	-	2	6	12	-	15	4	-	6	-
J110	SOT54	25	50	10	-	0.5	4	18	-	15	4	-	6	-
J111	SOT54	40	50	20	-	3	10	30	-	typ.3	13	-	35	-
J112	SOT54	40	50	5	-	1	5	50	-	typ.3	13	-	35	-
J113	SOT54	40	50	2	-	0.5	3	100	-	typ.3	13	-	35	-
PMBF4391	SOT23	40	50	50	150	4	10	30	-	3.5	-	15	-	20
PMBF4392	SOT23	40	50	25	75	2	5	60	-	3.5	-	15	-	35
PMBF4393	SOT23	40	50	5	30	0.5	3	100	-	3.5	-	15	-	50

P-channel junction field-effect transistors for switching

Type	Package	V _{DS} (V)	I _G (mA)	CHARACTERISTICS										
				I _{DSS} (mA)		-V _{GSoff} (V)		R _{DS(on)} (Ω)	C _{rs} (pF)		t _{on} (ns)		t _{off} (ns)	
				max	max	min	max	min	max	max	min	max	typ	max
PMBFJ174	SOT23	30	50	20	135	5	10	85	-	typ.4	7	-	15	-
PMBFJ175	SOT23	30	50	7	70	3	6	125	-	typ.4	15	-	30	-
PMBFJ176	SOT23	30	50	2	35	1	4	250	-	typ.4	35	-	35	-
PMBFJ177	SOT23	30	50	1.5	20	0.8	2.25	300	-	typ.4	45	-	45	-
J174	SOT54	30	50	20	135	5	10	85	-	typ.4	7	-	15	-
J175	SOT54	30	50	7	70	3	6	125	-	typ.4	15	-	30	-
J176	SOT54	30	50	2	35	1	4	250	-	typ.4	35	-	35	-
J177	SOT54	30	50	1.5	20	0.8	2.25	300	-	typ.4	45	-	45	-

N-channel junction field-effect transistors for general RF applications

Type	Package	V _{DS}	I _G	CHARACTERISTICS							
				I _{DSS}		V _{GS(off)}		Y _{fs}		C _{rs}	
				(V)	(mA)	(mA)	(V)	(mS)	(pF)	(pF)	
		max	max	min	max	min	max	min	max	min	max
DC, LF and HF amplifiers											
BF245A	SOT54	30	10	2	6.5	<8		3	6.5	Typ.=1.1	-
BF245B	SOT54	30	10	6	15	<8		3	6.5	Typ.=1.1	-
BF245C	SOT54	30	10	12	25	<8		3	6.5	Typ.=1.1	-
BF545A	SOT23	30	10	2	6.5	0.4	7.5	3	6.5	0.8	-
BF545B	SOT23	30	10	6	15	0.4	7.5	3	6.5	0.8	-
BF545C	SOT23	30	10	12	25	0.4	7.5	3	6.5	0.8	-
BF556A	SOT23	30	10	3	7	0.5	7.5	4.5	-	0.8	-
BF556B	SOT23	30	10	6	13	0.5	7.5	4.5	-	0.8	-
BF556C	SOT23	30	10	11	18	0.5	7.5	4.5	-	0.8	-
Pre-amplifiers for AM tuners in car radios											
BF861A	SOT23	25	10	2	6.5	0.2	1.0	12	20	2.1	2.7
BF861B	SOT23	25	10	6	15	0.5	1.5	16	25	2.1	2.7
BF861C	SOT23	25	10	12	25	0.8	2	20	30	2.1	2.7
BF862	SOT23	20	10	10	25	0.3	2	35	-	typ=1.9	-
RF stages FM portables, car radios, main radios & mixer stages											
BF510 ¹⁾	SOT23	20	10	0.7	3	typ. 0.8		2.5		0.4	0.5
BF511 ¹⁾	SOT23	20	10	2.5	7	typ. 1.5		4		0.4	0.5
BF512 ¹⁾	SOT23	20	10	6	12	typ. 2.2		6		0.4	0.5
BF513 ¹⁾	SOT23	20	10	10	18	typ. 3		7		0.4	0.5
Low-level general purpose amplifiers											
BFR30	SOT23	25	5	4	10	<5		1	4	1.5	-
BFR31	SOT23	25	5	1	5	<2.5		1.5	4.5	1.5	-
General-purpose amplifiers											
BFT46	SOT23	25	5	0.2	1.5	<1.2		>1		1.5	-
AM input stages UHF/VHF amplifiers											
PMBFJ308	SOT23	25	50	12	60	1	6.5	>10		1.3	2.5
PMBFJ309	SOT23	25	50	12	30	1	4	>10		1.3	2.5
PMBFJ310	SOT23	25	50	24	60	2	6.5	>10		1.3	2.5
PMBFJ620	SOT363	25	50	24	60	2	6.5	10		1.3	2.5

Bold = Highly recommended product

¹⁾ Asymmetrical

2.5.2 MOSFETs

Why choose NXP Semiconductors' MOSFETs:

- Reference designs for TV tuning
- Short leadtimes
- Broad portfolio
- Smallest packages
- 2-in-1 FETs for tuner applications
- Reliable volume supply
- Best performance MOSFETs for TV tuning

N-channel, single MOSFETs for switching

Type	Package	V _{DS} (V) max	CHARACTERISTICS													MODE		
			I _D (mA)		I _{DSS} (mA)		V _{(p)GS} (V)		R _{DS(on)} (Ω)	C _{rs} (pF)		t _{on} (ns)		t _{off} (ns)			S _{21(on)} ₂ (dB)	S _{21(off)} ₂ (dB)
			max	max	min	max	min	max	max	min	max	typ	max	typ	max		max	min
BSS83	SOT143	10	50	-	-	0.1 ²⁾	2 ¹⁾	45	typ.0.6	-	1	-	5	-	-	enh.		
Silicon RF Switches																		
BF1107	SOT23	3	10	-	100 ³⁾	-	7 ⁴⁾	20	-	-	-	-	-	-	2.5	30	depl.	
BF1108⁵⁾	SOT143B	3	10	-	100 ³⁾	-	7 ⁴⁾	20	-	-	-	-	-	3	30	depl.		
BF1108R⁵⁾	SOT143R	3	10	-	100 ³⁾	-	7 ⁴⁾	20	-	-	-	-	-	3	30	depl.		

Bold = Highly recommended product

N-channel, dual-gate MOSFETs

Type	Package	V _{DS} (V) max	I _D (mA) max	CHARACTERISTICS											VHF	UHF
				I _{BSX} (mA)		V _{(th)GS} (V)		Y _{fs} (mS)		C _{is} (pF)	C _{os} (pF)	F @ 800 MHz (dB)				
				min	max	min	max	min	max	typ	typ	typ				
With external bias																
BF908	SOT143	12	40	3	27	-	-2	36	50	3.1	1.7	1.5	X	X		
BF908R	SOT143R	12	40	3	27	-	-2	36	50	3.1	1.7	1.5	X	X		
BF908WR	SOT343R	12	40	3	27	-	-2	36	50	3.1	1.7	1.5	X	X		
BF991	SOT143	20	20	4	25	-	-2.5	10	-	2.1	1.1	1	X	-		
BF992	SOT143	20	40	-	-	-	-1.3	20	-	4	2	1.2 ⁷⁾	X	-		
BF994S	SOT143	20	30	4	20	-	-2.5	15	-	2.5	1	1 ⁷⁾	X	-		
BF996S	SOT143	20	30	4	20	-	-2.5	15	-	2.3	0.8	1.8	-	X		
BF998	SOT143	12	30	2	18	-	-2.0	21	-	2.1	1.05	1	X	X		
BF998R	SOT143R	12	30	2	18	-	-2.0	21	-	2.1	1.05	1	X	X		
BF998WR	SOT343R	12	30	2	18	-	-2.5	22	-	2.1	1.05	1	X	X		
Fully internal bias																
BF1105	SOT143	7	30	8	16	0.3	1.2 ⁶⁾	25	-	2.2 ⁹⁾	1.2 ⁸⁾	1.7	X	X		
BF1105R	SOT143R	7	30	8	16	0.3	1.2 ⁶⁾	25	-	2.2 ⁹⁾	1.2 ⁸⁾	1.7	X	X		
BF1105WR	SOT343R	7	30	8	16	0.3	1.2 ⁶⁾	25	-	2.2 ⁹⁾	1.2 ⁸⁾	1.7	X	X		
BF1109	SOT143	11	30	8	16	0.3	1.2 ⁶⁾	24	-	2.2 ⁹⁾	1.3 ⁸⁾	1.5	X	X		
BF1109R	SOT143R	11	30	8	16	0.3	1.2 ⁶⁾	24	-	2.2 ⁹⁾	1.3 ⁸⁾	1.5	X	X		
BF1109WR	SOT343R	11	30	8	16	0.3	1.2 ⁶⁾	24	-	2.2 ⁹⁾	1.3 ⁸⁾	1.5	X	X		
Partly internal bias																
BF904(A)	SOT143	7	30	8	13	0.3	1 ⁶⁾	22	30	2.2	1.3	2	X	X		
BF904(A)R	SOT143R	7	30	8	13	0.3	1 ⁶⁾	22	30	2.2	1.3	2	X	X		
BF904(A)WR	SOT343R	7	30	8	13	0.3	1 ⁶⁾	22	30	2.2	1.3	2	X	X		
BF909(A)	SOT143	7	40	12	20	0.3	1 ⁶⁾	36	50	3.6	2.3	2	X	X		
BF909(A)R	SOT143R	7	40	12	20	0.3	1 ⁶⁾	36	50	3.6	2.3	2	X	X		
BF909(A)WR	SOT343R	7	40	12	20	0.3	1 ⁶⁾	36	50	3.6	2.3	2	X	X		

¹⁾ Asymmetrical

²⁾ V_{GS(th)}

³⁾ I_D

⁴⁾ V_{SG}

⁵⁾ Depletion FET plus diode in one package

⁶⁾ V_{GS(th)}

⁷⁾ @ 200 MHz

⁸⁾ C_{OSS}

⁹⁾ C_{IG}

N-channel, dual-gate MOSFETs

Type	Package	V _{DS} (V)	I _D (mA)	CHARACTERISTICS										VHF	UHF
				I _{DSX} (mA)		V _{(th)igs} (V)		Y _{fs} (mS)		C _{is} (pF)	C _{os} (pF)	F @ 800 MHz (dB)			
				min	max	min	max	min	max	typ	typ	typ			
Partly internal bias															
BF1100	SOT143	14	30	8	13	0.3	1.2 ⁶⁾	24	33	2.2	1.4	2	X	X	
BF1100R	SOT143R	14	30	8	13	0.3	1.2 ⁶⁾	24	33	2.2	1.4	2	X	X	
BF1100WR	SOT343R	14	30	8	13	0.3	1.2 ⁶⁾	24	33	2.2	1.4	2	X	X	
BF1101	SOT143	7	30	8	16	0.3	1 ⁶⁾	25	-	2.2	1.2 ⁸⁾	1.7	X	X	
BF1101R	SOT143R	7	30	8	16	0.3	1 ⁶⁾	25	-	2.2	1.2 ⁸⁾	1.7	X	X	
BF1101WR	SOT343R	7	30	8	16	0.3	1 ⁶⁾	25	-	2.2	1.2 ⁸⁾	1.7	X	X	
BF1102(R) ¹⁰⁾	SOT363	7	40	12	20	0.3	1.2 ⁶⁾	36	-	2.8 ⁹⁾	1.6 ⁸⁾	2	X	X	
BF1201	SOT143	10	30 ¹⁾	11	19	0.3	1.2 ⁶⁾	23	35	2.6	0.9	1.9	X	X	
BF1201R	SOT143R	10	30 ¹⁾	11	19	0.3	1.2 ⁶⁾	23	35	2.6	0.9	1.9	X	X	
BF1201WR	SOT343R	10	30 ¹⁾	11	19	0.3	1.2 ⁶⁾	23	35	2.6	0.9	1.9	X	X	
BF1202	SOT143	10	30	8	16	0.3	1.2 ⁶⁾	25	40	1.7	0.85	1.1	X	X	
BF1202R	SOT143R	10	30	8	16	0.3	1.2 ⁶⁾	25	40	1.7	0.85	1.1	X	X	
BF1202WR	SOT343R	10	30	8	16	0.3	1.2 ⁶⁾	25	40	1.7	0.85	1.1	X	X	
BF1203 ¹¹⁾	SOT363	10	30	11	19	0.3	1.2 ⁶⁾	23	35	2.6	0.9	1.9	X	-	
		10	30	8	16	0.3	1.2	25	40	1.7	0.85	1.1	-	X	
BF1204 ¹⁰⁾	SOT363	10	30	8	16	0.3	1.2 ⁶⁾	25	40	1.7	0.85	1.1	X	X	
BF1205C ¹¹⁾¹²⁾¹³⁾	SOT363	6	30	14	24	0.3	1	26	41	2.2	0.9	1.4	X	-	
		6	30	9	17	0.3	1	28	43	2	0.85	1.4	-	X	
BF1205 ¹¹⁾¹²⁾¹³⁾	SOT363	10	30	8	16	0.3	1.0	26	40	1.8	0.75	1.2	X	-	
		7	30	8	16	0.3	1.0	26	40	2.0	0.85	1.4	-	X	
BF1206 ¹¹⁾	SOT363	6	30	14	23	0.3	1.0	33	48	2.4	1.1	1.6	X	-	
		6	30	9	17	0.3	1.0	29	44	1.7	0.85	1.4	-	X	
BF1206F ¹¹⁾	SOT666	6	30	3	6.5	0.3	1.0	17	32	2.4	1.1	1.1	X	-	
		6	30	3	6.5	0.3	1.0	17	32	1.7	0.85	1.0	-	X	
BF1207 ¹¹⁾¹³⁾¹⁴⁾	SOT363	6	30	13	23	0.3	1.0	25	40	2.2	0.9	1.4	X	-	
		6	30	9	19	0.3	1.0	26	41	1.8	0.8	1.4	-	X	
BF1208 ¹¹⁾¹²⁾¹³⁾	SOT666	6	30	14	24	0.3	1	26	41	2.2	0.9	1.4	X	-	
		6	30	9	17	0.3	1	28	43	2	0.85	1.4	-	X	
BF1208D ¹¹⁾¹²⁾¹³⁾	SOT666	6	30	14	24	0.3	1	26	41	2.1	0.8	1.1	X	-	
		6	30	10	20	0.3	1	25	40	2.1	0.85	1.4	-	X	
BF1210 ¹¹⁾¹²⁾	SOT363	6	30	14	24	0.3	1	26	41	2.2	0.9	1.4	X	-	
		6	30	9	17	0.3	1	28	43	2	0.85	1.4	-	X	
BF1212 ¹¹⁾¹²⁾	SOT363	6	30	14	24	0.3	1	26	41	2.2	0.9	1.4	X	-	
		6	30	9	17	1.3	1	28	48	2	0.85	1.4	-	X	
BF1211	SOT143	6	30	11	19	0.3	1.0	25	40	2.1	0.9	1.3	X	-	
BF1211R	SOT143R	6	30	11	19	0.3	1.0	25	40	2.1	0.9	1.3	X	-	
BF1211WR	SOT343	6	30	11	19	0.3	1.0	25	40	2.1	0.9	1.3	X	-	
BF1212	SOT143	6	30	8	16	0.3	1.0	28	43	1.7	0.9	1.1	-	X	
BF1212R	SOT143R	6	30	8	16	0.3	1.0	28	43	1.7	0.9	1.1	-	X	
BF1212WR	SOT343	6	30	8	16	0.3	1.0	28	43	1.7	0.9	1.1	-	X	
BF1214 ¹⁰⁾	SOT363	6	30	13	23	0.3	1.0	25	35	2.2	0.9	1.4	X	X	

Red = New

Bold = Highly recommended product

Bold Red = New, highly recommended product

1) Asymmetrical

2) V_{GS(th)}

3) I_D

4) V_{SG}

5) Depletion FET plus diode in one package

7) @200 MHz

8) C_{OSS}

9) C_{ig}

10) Two equal dual gate MOSFETs in one package

11) Two low noise gain amplifiers in one package

12) Transistor A: fully internal bias, transistor B: partly internal bias

13) Internal switching function

14) Transistor A: partly internal bias, transistor B: fully internal bias

2.6 RF Modules

NXP RF CATV-HFC modules:

<http://www.nxp.com/catv>

Why choose NXP Semiconductors' RF Modules:

- Excellent linearity, stability and reliability
- Rugged construction
- Extremely low noise
- High power gain
- Low total cost of ownership

CATV types for Chinese (C-types) and Indian market (OM-types)

New in our CATV Hybrid portfolio are two families of products.

The C types are specially designed for the Chinese market, fitting two major governmental projects. And the OM types, also called the INDI types, are designed for low-end CATV

infrastructure networks deployed in India. Both families will be extended in the following months to cover most of those two specific market segments.

C types (China)

- CATV push pulls, chapter 2.6.2 :
BGY588C and BGE788C
- CATV power doublers, chapter 2.6.3 :
BGD712C
- CATV optical receivers, chapter 2.6.4 :
BGO807C

OM types (India)

- CATV push pulls, chapter 2.6.2 :
OM7650 and OM7670

2.6.1 CATV Reverse Hybrids

Frequency range	Type number	Gain (dB)	Slope (dB)	FL	RL _{IN} /RL _{OUT}	CTB	XMOD	CSO	@ Ch	@ Vo (dBmV)	F @ fmax	Itot (mA)
5 -65 MHz	BGS67A	25 - 26	-0.1 - 0.6	± 0.2	20/20	-64	-54	-	4	50	3.5	85
5 -75 MHz	BGY68	29.2 - 30.8	-0.2 - 0.5	± 0.2	20/20	-68	-60	-	4	50	3.5	135
5 -120 MHz	BGY66B	24.5 - 25.5	-0.2 - 0.5	± 0.2	20/20	-66	-54	-	14	48	5	135
5 -200 MHz	BGY67	21.5 - 22.5	-0.2 - 0.5	± 0.2	20/20	-67	-60	-	22	50	5.5	230
	BGY67A	23.5 - 24.5	-0.2 - 0.5	± 0.2	20/20	-67	-59	-	22	50	5.5	230

2.6.2 CATV Push-Pulls

Frequency range	Type number	Gain (dB)	Slope (dB)	FL	RL _{IN} /RL _{OUT}	CTB	XMOD	CSO	@ Ch	@ Vo (dBmV)	F @ fmax	Itot (mA)
40 - 550 MHz	OM7650	33.2 - 35.5	0.2 - 2	-	10/10	-45	-	-57	77	44	8	340
	BGY588C	33.2 - 35.5	0.2 - 1.7	± 0.5	16/16	-57	-	-62	77	44	8	345
	BGY585A	17.7 - 18.7	0.5 - 2	± 0.2	20/20	-59	-62	-59	77	44	8	240
	BGY587	21.5 - 22.5	0.2 - 1.5	± 0.2	20/20	-57	-58	-54	77	44	7	240
	BGY587B	26.2 - 27.8	0.5 - 2.5	± 0.4	20/20	-57	-60	-57	77	44	6.5	340
40 - 600 MHz	BGY588N	33.5 - 35.5	0.5 - 1.5	± 0.4	20/20	-57	-59	-62	77	44	6	340
	BGY685A	17.7 - 18.7	0.5 - 2.2	± 0.2	20/20	-55	-60	-56	85	44	8.5	240
40 - 750 MHz	BGY687	21 - 22	0.8 - 2.2	± 0.2	20/20	-54	-54	-52	85	44	6.5	240
	OM7670	33.2 - 35.2	1/4	-	10/8	-43	-	-54	110	44	8	340
	BGY785A	18 - 19	0 - 2	± 0.3	20/20	-53	-56	-53	110	44	7	240
	BGE788C	33.2 - 35.2	0.3 - 2.3	± 0.6	16/16	-49	-	-52	110	44	8	325
	BGY787	21 - 22	0 - 1.5	± 0.5	20/20	-53	-52	-53	110	44	6.5	240
	BGE787B	28.5 - 29.5	0.2 - 2.2	± 0.5	20/20	-50	-54	-56	110	44	7	320
40 - 870 MHz	BGE788	33.5 - 34.5	0.5 - 2.5	± 0.5	20/20	-49	-51	-52	110	44	7	320
	BGY883	14.5 - 15.5	0 - 2	± 0.3	20/20	-61	-61	-61	49	44	8.5	235
	BGE885	16.5 - 17.5	0.2 - 1.2	± 0.5	14/14	-	-	-	129	59	8	240
	BGX885N	16.5 - 17.5	0.2 - 1.4	± 0.3	20/20	-	-	-	129	59	8	240
	BGY885A	18 - 19	0 - 2	± 0.3	20/20	-61	-61	-61	49	44	8	240
	BGY887	21 - 22	0.2 - 2	± 0.3	20/20	-55	-61	-57	129	40	6.5	235
	CGY887A	25.2 - 25.8	0.5 - 1.4	± 0.5	20/21	-62	-56	-59	129	40	5	240
	CGY887B	27.2 - 27.8	0.5 - 1.5	± 0.5	24/23	-57.5	-51	-58	132	44	5	310
	CGY888C	34.5 - 36.5	0.5 - 2.5	± 0.5	20/20	-68	-	-66	112	44	4.0	280
	BGY835C	33.5 - 34.5	0.5 - 2.5	± 0.6	21/21	-60	-59	-55	49	44	7.0	340
40 -1000 MHz	BGY887B	28.5 - 29.5	0.5 - 2.5	± 0.5	20/20	-60	-60	-60	49	44	6.5	340
	BGY888	33.5 - 34.5	0.5 - 2.5	± 0.5	20/20	-60	-59	-55	49	44	7	340
	BGY1085A	18 - 19	0 - 2	± 0.3	20/20	-53	-54	-56	150	44	7.5	240

Bold Red = New, highly recommended product

2.6.3 CATV power doublers

Frequency range	Type number	Gain (dB)	Slope (dB)	FL	RL _{IN} /RL _{OUT}	CTB	XMOD	CSO	@ Ch	@ Vo (dBmV)	F @ fmax	Itot (mA)	
40 - 550 MHz	BGD502	18 - 19	0.2 - 2.2	± 0.3	20/20	-65	-68	-62	77	44	8	435	
	BGD702	18 - 19	0.2 - 2	± 0.5	20/20	-58	-62	-58	110	44	8.5	435	
40 - 750 MHz	BGD702N	18 - 19	0.2 - 2	± 0.25	20/20	-58	-62	-58	110	44	8.5	435	
	BGD712	18.2 - 18.8	0.5 - 1.5	± 0.35	23/23	-62	-63	-63	112	44	7	410	
	BGD712C	18.2 - 18.8	0.5 - 1.5	± 0.4	17/17	-62	-	-63	112	44	7	410	
	BGD704	19.5 - 20.5	0 - 2	± 0.5	20/20	-57	-61	-56	110	44	8.5	435	
	BGD714	20 - 20.6	0.5 - 1.5	± 0.35	23/23	-61	-62	-62	112	44	7	410	
	BGD885	16.5 - 17.5	0.2 - 1.6	± 0.5	20/20	-	-	-	129	59	8	450	
40 - 870 MHz	BGD802	18 - 19	0.2 - 2	± 0.5	20/20	-54	-59	-56	129	44	9	410	
	BGD812	18.2 - 18.8	0.4 - 1.4	± 0.5	23/23	-58	-62	-60	132	44	7.5	410	
	BGD902	18.2 - 18.8	0.4 - 1.4	± 0.3	21/25	-58	-62	-58	129	44	8	435	
	BGD902L	18 - 19	0.4 - 1.4	± 0.3	21/21	-56	-60	-59	129	44	7.5	380	
	CGD923	19.25 - 19.75	0 - 1	± 0.6	20/20	-56	-57	-54	132	48	5.5	475	
	BGD804	19.5 - 20.5	0.2 - 2	± 0.5	20/20	-53	-61	-54	129	44	7.5	410	
	BGD814	19.7 - 20.3	0.4 - 1.4	± 0.5	22/25	-57.5	-62	-59	132	44	7.5	410	
	BGD904	19.7 - 20.3	0.4 - 1.4	± 0.3	21/25	-57.5	-61	-58	129	44	7.5	435	
	BGD904L	19.7 - 20.3	0.4 - 1.4	± 0.3	21/25	-55	-59	-59	129	44	7.5	380	
	CGD914	19.75 - 20.25	0.2 - 1.5	± 0.45	20/21	-59.5	-64	-50	132	44	4	375	
	BGD816L	21.2 - 21.8	0.5 - 1.5	± 0.5	22/25	-55	-58	-56	129	44	7.5	375	
	BGD906	21.2 - 21.8	0.5 - 1.5	± 0.35	22/22	-57	-60	-54	129	44	7.5	435	
	40 - 870 MHz	CGD944C	23 - 25	1 - 2	± 0.5	18/18	-66	-58	-68	132	48	5.0	450
		CGD942C	20.5 - 22.5	1 - 2	± 0.5	18/18	-66	-58	-68	132	48	5.0	450
40 - 1000 MHz	CGD1042	20.5 - 22.5	1.5 - 2.5	± 0.3	17/17	-68	-64	-68	79	56.9	5.0	450	
	CGD1044	22.5 - 24.5	1.5 - 2.5	± 0.3	17/17	-68	-64	-68	79	56.9	5.0	450	
	CGD1042H	20.5 - 22.5	0 - 1	± 0.3	14/17	-65	-65	-65	79 + 75*	59	7.0	450	
	CGD1044H	22.5 - 24.5	0 - 1	± 0.3	14/17	-65	-65	-65	79 + 75*	59	7.0	450	

Bold = Highly recommended product

Bold Red = New, highly recommended product

* = digital channels

2.6.4 CATV optical receivers

Frequency range	Type number	Rmin (V/W)	Slope (dB)	FL	S22 (dB)	d3	d2	@fm (MHz)	@Pi (mW)	F @ fmax	Conn.	Itot (mA)
Forward Path Receiver												
40 - 870	BGO807	800	0 - 2	1	11	-71	-55	854.5	1	8.5		205
	BGO807C	800	0 - 2	1	11	-71	-54	854.4	1	8.5		205
	BGO807/FC0	750	0 - 2	1	11	-71	-55	854.5	1	8.5	FC	205
	BGO807/SC0	750	0 - 2	1	11	-71	-55	854.5	1	8.5	SC	205
	BGO827	800	0 - 2	1	11	-73	-57	854.5	1	8.5		205
	BGO827/SC0	750	0 - 2	1	11	-73	-57	854.5	1	8.5	SC	205

Bold = Highly recommended product

* NOTES: This table is for reference only.

For full data please refer to the latest datasheet.

For availability please check the NXP Sales office.

Description

Frequency range: minimum and maximum frequency in MHz at which data are characterized @Ch/@Vo. The number of channels and the output voltage at which CTB, XM, CSO and d2 are characterized @fm. Measurement frequency is F. Noise Figure is in dB or Noise in pA/Sqrt(Hz). FL is Flatness Rmin is Minimum responsivity of optical receivers.

2.7 Fiber-optic transceiver ICs

NXP Optical Networking

<http://www.nxp.com/opticalnetworking>

Why choose NXP Semiconductors' Fiber Optic Transceivers:

- Reliable supplier
- Easy to design in
- Robust products

2.7.1 Laser drivers

Part number	Data-rate	Package type	Bare die	I _{mod} /I _{Bias}	Dual loop	Input	V _{cc}	Power dissipation
		Mb/s		[mA]				mW
TZA3047A	30-1250	SOT560-1	X	100-100	X	CML/PECL	3.3	420
TZA3047B	30-1250	SOT560-1	X	100-100	X	CML/PECL	3.3 ¹⁾	420
TZA3050	30-1250	SOT560-1	X	100-100	-	CML/PECL	3.3 ¹⁾	420

2.7.2 Transimpedance amplifiers

Part number	Data-rate	Package type	Bare die	In	Eq Sens	RSSI	Output	V _{cc}	Power dissipation
		Mb/s		[nA]	[dBm]				mW
TZA3036	0-155	die only	X	10	-40	Yes	50 Ohm	3.3	50
TZA3026	0-622	die only	X	67	-32	Yes	50 Ohm	3.3	60
TZA3046	0-1250	die only	X	130	-29	Yes	50 Ohm	3.3	70
TZA3013	0-2488	die only	X	450	-24	-	50 Ohm	3.3	86

Bold = highly recommended product

*) NOTES: All figures given are typical at 25 deg C

Power dissipation is given for V_{cc} = 3.3 V

Eq. sensitivity conditions: Calculated from noise figure using a lowpass bandwidth filter at 0.7x bit rate and a source with an extinction ratio of 10% and a photodiode responsivity of 0.9A/W.

3.3¹⁾ means that the output stage is capable of driving 5 V laser applications.



What if you could lower total cost of ownership for your satellite solutions?

Look at TFF1004HN for satellite LNB, chapter 5.2

3. Design-in tools

This chapter will make it easier to find and get hold of design-in information and materials, with web links or references to the NXP representative / authorized distributor.

3.1 S-Parameters

S-Parameters help you to simulate the behaviour of our devices to your specific adjustments for e.g. voltage, current.

Wideband transistors, FETs & MMICs

First, click on the type number, which takes you directly to the corresponding product information page on the NXP Semiconductors internet.

Second, scroll down on this product information page to find the S-Parameters.

Wideband transistors			
BF67	BFG480W	BFQ19	BFS520
BFG135	BFG505	BFQ67	BFS540
BFG198	BFG520	BFQ67W	BFT25
BFG21W	BFG520W	BFR106	BFT25A
BFG25A/X	BFG540	BFR505	BFT92
BFG31	BFG540W	BFR520	BFT92W
BFG35	BFG541	BFR540	BFT93
BFG310/XR	BFG590	BFR92A	BFT93W
BFG310W/XR	BFG591	BFR92AW	BRF505T
BFG325/XR	BFG93A	BFR93A	PBR941
BFG325W/XR	BFG94	BFR93AW	PBR951
BFG403W	BFG97	BFS17	PRF947
BFG410W	BFM505	BFS17A	PRF949
BFG424F	BFM520	BFS17W	PRF957
BFG424W	BFQ149	BFS25A	
BFG425W	BFQ18A	BFS505	

FETs		
BF1211	BF1212	BF511
BF1211R	BF1212R	BF513
BF1211WR	BF1212WR	BF862

MMICs		
BGA2001	BGA2712	BGA2716
BGA2003	BGM1011	BGA2717
BGA2711	BGM1012	BGA2011
BGA2748	BGM1013	BGA2012
BGA2771	BGM1014	BGA6289
BGA2776	BGM2011	BGA6489
BGA2709	BGA2715	BGA6589

3.2 Spice models

Spice models help you to create the optimal performance and to understand which external components have a certain influence on that performance.

Wideband transistors, FETs & Varicaps diodes

First, click on the type number which takes you directly to the corresponding product information page on the NXP Semiconductors internet.

Second, scroll down on this product information page to find the Spice models.

Wideband transistors			
BFG10	BFG505	BFG92A/X	BFR93AW
BFG10/X	BFG505/X	BFG93A	BFS17
BFG10W/X	BFG505W/X	BFG94	BFS17A
BFG135	BFG520	BFG97	BFS17W
BFG198	BFG520/X	BFM505	BFS25A
BFG21W	BFG520/XR	BFM520	BFS505
BFG25A/X	BFG520W	BFQ149	BFS520
BFG25AW/X	BFG520W/X	BFQ18A	BFS540
BFG31	BFG540	BFQ19	BFT25A
BFG310/XR	BFG540/X	BFQ540	BFT92
BFG310W/XR	BFG540/XR	BFQ67	BFT92W
BFG325/XR	BFG540W	BFQ67W	BFT93
BFG325W/XR	BFG540W/X	BFR106	BFT93W
BFG35	BFG540W/XR	BFR505	PBR941
BFG403W	BFG541	BFR505T	PBR951
BFG410W	BFG590	BFR520	PRF947
BFG424F	BFG590/X	BFR540	PRF949
BFG424W	BFG591	BFR92A	PRF957
BFG425W	BFG67	BFR92AW	
BFG480W	BFG67/X	BFR93A	

FETs			
BF862	BF908	BF909	BF998
BF904			

Varicap diodes			
BB145B	BB156	BB201	BB208-02
BB149	BB179	BB202	
BB149A	BB179B	BB207	

3.3 Application notes

http://www.nxp.com/products/all_appnotes/

For the application notes we refer you to chapter 1 of this manual. For each application, we have given the recommended application notes which are available on the internet (with interactive link) or via your local NXP representative or authorized distributor (look at the last chapter: Web Links and Contacts).

3.4 Demo boards



3.4.1 MMIC and SiGeC transistor demo boards

MMIC demo boards are available (although limited) via your local NXP representative or authorized distributor (look at the last chapter: Web Links and Contacts).

BFU725F	BGA2709	BGA2748	BGM1011
BGA2001	BGA2711	BGA2771	BGM1012
BGA2003	BGA2712	BGA2776	BGM1013
BGA2011	BGA2714	BGA6289	BGM1014
BGA2012	BGA2715	BGA6489	
BGA2031	BGA2716	BGA6589	

3.5 Samples of products in development

For development samples, please ask your local NXP representative or authorized distributor (see last chapter: Web Links and Contacts) to order the latest versions at the RF development team.

3.6 Samples of released products

For all released products, samples are available in the sample warehouse. Look on the home page of the NXP web site for the link to the online sample store: www.nxp.com

3.7 Datasheets

For all released products, datasheets are available on the NXP Semiconductors internet. Simply 'clicking' on a product type (in this manual chapter 1 or 2) takes you to the corresponding product information page on the NXP Semiconductors website.

3.8 Design-in support

If you need special design-in support from our design-in engineers, please ask your local NXP representative or authorized distributor (see last chapter: Web Links and Contacts), to pass on your request to the RF development team.



What if you could increase your network capacity for high-end services?

Look at 1-GHz CATV, chapter 5.4

4. Cross-references & replacements

NXP cross-references:

<http://www.nxp.com/search/index.html>

NXP end-of-life:

<http://www.nxp.com/products/eol/>

4.1 Cross-references: Manufacturer types versus NXP types

In alphabetical order of manufacturer type

Abbreviations:

BS diode	Band Switch Diode
CATV PD	CATV Power Doubler
CATV PPA	CATV Push Pull Amplifier
CATV PPA/HG	CATV Push Pull Amplifier High Gain
CATV RA	CATV Reverse Amplifier
FET	Field Effect Transistor
IS	Industry Standard
MMIC	Monolithic Microwave Integrated Circuit
Varicap	Varicap Diode
WB trs 1-4	Wideband Transistor 1-4 generation
WB trs 5-7	Wideband Transistor 5-7 generation

Manufacturer type	Manufacturer	NXP type	Product family
1SS314	Toshiba	BA591	BS diode
1SS356	Rohm	BA591	BS diode
1SS381	Toshiba	BA277	BS diode
1SS390	Rohm	BA891	BS diode
1SV172	Toshiba	BAP50-04	PIN diode
1SV214	Toshiba	BB149	Varicap
1SV214	Toshiba	BB149A	Varicap
1SV215	Toshiba	BB153	Varicap
1SV228	Toshiba	BB201	Varicap
1SV231	Toshiba	BB152	Varicap
1SV232	Toshiba	BB148	Varicap
1SV233	Sanyo	BAP70-03	PIN diode
1SV234	Sanyo	BAP64-04	PIN diode
1SV239	Toshiba	BB145B	Varicap
1SV241	Sanyo	BAP64-02	PIN diode
1SV246	Sanyo	BAP64-04W	PIN diode
1SV247	Sanyo	BAP70-02	PIN diode
1SV248	Sanyo	BAP50-02	PIN diode
1SV249	Sanyo	BAP50-04W	PIN diode
1SV250	Sanyo	BAP50-03	PIN diode
1SV251	Sanyo	BAP50-04	PIN diode
1SV252	Toshiba	BAP50-04W	PIN diode
1SV254	Toshiba	BB179	Varicap
1SV263	Sanyo	BAP50-02	PIN diode
1SV264	Sanyo	BAP50-04W	PIN diode
1SV266	Sanyo	BAP50-03	PIN diode
1SV267	Sanyo	BAP50-04	PIN diode
1SV269	Toshiba	BB148	Varicap
1SV270	Toshiba	BB156	Varicap
1SV271	Toshiba	BAP50-03	PIN diode

Manufacturer type	Manufacturer	NXP type	Product family
1SV278	Toshiba	BB179	Varicap
1SV279	Toshiba	BB179	Varicap
1SV282	Toshiba	BB178	Varicap
1SV282	Toshiba	BB178	Varicap
1SV282	Toshiba	BB178	Varicap
1SV282	Toshiba	BB187	Varicap
1SV283	Toshiba	BB187	Varicap
1SV283	Toshiba	BB178	Varicap
1SV283	Toshiba	BB178	Varicap
1SV283	Toshiba	BB187	Varicap
1SV283	Toshiba	BB187	Varicap
1SV284	Toshiba	BB156	Varicap
1SV288	Toshiba	BB152	Varicap
1SV290	Toshiba	BB182	Varicap
1SV294	Sanyo	BAP70-03	PIN diode
1SV305	Toshiba	BB202	Varicap
1SV307	Toshiba	BAP51-03	PIN diode
1SV308	Toshiba	BAP51-02	PIN diode
1T362	Sony	BB149	Varicap
1T362 A	Sony	BB149A	Varicap
1T363 A	Sony	BB153	Varicap
1T368 A	Sony	BB148	Varicap
1T369	Sony	BB152	Varicap
1T379	Sony	BB131	Varicap
1T397	Sony	BB152	Varicap
1T399	Sony	BB148	Varicap
1T402	Sony	BB179B	Varicap
1T402	Sony	BB179B	Varicap
1T403	Sony	BB178	Varicap
1T403	Sony	BB178	Varicap
1T404A	Sony	BB187	Varicap
1T405 A	Sony	BB187	Varicap

Manufacturer type	Manufacturer	NXP type	Product family
1T406	Sony	BB182	Varicap
1T408	Sony	BB187	Varicap
2N3330	IS	J176	FET
2N3331	IS	J176	FET
2N4220	IS	BF245A	FET
2N4856	IS	BSR56	FET
2N4857	IS	BSR57	FET
2N4858	IS	BSR58	FET
2N5114	IS	J174	FET
2N5115	IS	J175	FET
2N5116	IS	J175	FET
2N5432	IS	J108	FET
2N5433	IS	J108	FET
2N5434	IS	J109	FET
2N5457	IS	BF245A	FET
2N5458	IS	BF245A	FET
2N5459	IS	BF245B	FET
2N5653	IS	J112	FET
2N5654	IS	J111	FET
2SC4094	NEC	BFG520/XR	WB trs 1-4
2SC4095	NEC	BFG520/XR	WB trs 1-4
2SC4182	NEC	BFS17W	WB trs 1-4
2SC4184	NEC	BFS17W	WB trs 1-4
2SC4185	NEC	BFS17W	WB trs 1-4
2SC4186	NEC	BFR92AW	WB trs 1-4
2SC4226	NEC	PRF957	WB trs 1-4
2SC4227	NEC	BFQ67W	WB trs 1-4
2SC4228	NEC	BFS505	WB trs 1-4
2SC4247	Toshiba	BFR92AW	WB trs 1-4
2SC4248	Toshiba	BFR92AW	WB trs 1-4
2SC4315	Toshiba	BFG520/XR	WB trs 1-4
2SC4320	Toshiba	BFG520/XR	WB trs 1-4
2SC4321	Toshiba	BFQ67W	WB trs 1-4
2SC4325	Toshiba	BFS505	WB trs 1-4
2SC4394	Toshiba	PRF957	WB trs 1-4
2SC4536	NEC	BFQ19	WB trs 1-4
2SC4537	Renesas	BFR93AW	WB trs 1-4
2SC4592	Renesas	BFG520/XR	WB trs 1-4
2SC4593	Renesas	BFS520	WB trs 1-4
2SC4703	NEC	BFQ19	WB trs 1-4
2SC4784	Renesas	BFS505	WB trs 1-4
2SC4807	Renesas	BFQ18A	WB trs 1-4
2SC4842	Toshiba	BFG540W/XR	WB trs 1-4
2SC4899	Renesas	BFS505	WB trs 1-4
2SC4900	Renesas	BFG520/XR	WB trs 1-4
2SC4901	Renesas	BFS520	WB trs 1-4
2SC4988	Renesas	BFQ540	WB trs 1-4
2SC5011	NEC	BFG540W/XR	WB trs 1-4
2SC5012	NEC	BFG540W/XR	WB trs 1-4
2SC5065	Toshiba	PRF957	WB trs 1-4
2SC5085	Toshiba	PRF957	WB trs 1-4
2SC5087	Toshiba	BFG520/XR	WB trs 1-4
2SC5088	Toshiba	BFG540W/XR	WB trs 1-4
2SC5090	Toshiba	BFS520	WB trs 1-4
2SC5092	Toshiba	BFG520/XR	WB trs 1-4
2SC5095	Toshiba	BFS505	WB trs 1-4
2SC5107	Toshiba	BFS505	WB trs 1-4
2SC5463	Toshiba	BFQ67W	WB trs 1-4
2SC5593	Renesas	BFG410W	WB trs 5-7
2SC5594	Renesas	BFG425W	WB trs 5-7
2SC5623	Renesas	BFG410W	WB trs 5-7
2SC5624	Renesas	BFG425W	WB trs 5-7
2SC5631	Renesas	BFQ540	WB trs 1-4
2SJ105GR	IS	J177	FET
2SK163-K	Renesas	J113	FET
2SK163-L	Renesas	J113	FET
2SK163-M	Renesas	J113	FET
2SK163-N	Renesas	J113	FET
2SK210BL	Renesas	PMBFJ309	FET
2SK370BL	Renesas	J109	FET
2SK370GR	Renesas	J109	FET
2SK370V	Renesas	J109	FET
2SK381	Renesas	J113	FET
2SK43	Renesas	J113	FET

Manufacturer type	Manufacturer	NXP type	Product family
2SK435	Renesas	J113	FET
2SK508	Renesas	PMBFJ308	FET
3SK290	Renesas	BF998WR	FET
BA592	Infineon	BA591	BS diode
BA592	Infineon	BA591	BS diode
BA595	Infineon	BAP70-03	PIN diode
BA597	Infineon	BAP70-03	PIN diode
BA885	Infineon	BAP70-03	PIN diode
BA892	Infineon	BA891	BS diode
BA892	Infineon	BA891	BS diode
BA895	Infineon	BAP70-02	PIN diode
BAR14-1	Infineon	BAP70-03	PIN diode
BAR15-1	Infineon	BAP70-03	PIN diode
BAR16-1	Infineon	BAP70-03	PIN diode
BAR17	Infineon	BAP50-03	PIN diode
BAR60	Infineon	BAP50-03	PIN diode
BAR61	Infineon	BAP50-03	PIN diode
BAR63	Infineon	BAP63-03	PIN diode
BAR63-02L	Infineon	BAP63-02	PIN diode
BAR63-02V	Infineon	BAP63-02	PIN diode
BAR63-02W	Infineon	BAP63-02	PIN diode
BAR63-03W	Infineon	BAP63-03	PIN diode
BAR63-05	Infineon	BAP63-05W	PIN diode
BAR63-05W	Infineon	BAP63-05W	PIN diode
BAR64-02V	Infineon	BAP64-02	PIN diode
BAR64-02W	Infineon	BAP64-02	PIN diode
BAR64-03W	Infineon	BAP64-03	PIN diode
BAR64-04	Infineon	BAP64-04	PIN diode
BAR64-04W	Infineon	BAP64-04W	PIN diode
BAR64-05	Infineon	BAP64-05	PIN diode
BAR64-05W	Infineon	BAP64-05W	PIN diode
BAR64-06	Infineon	BAP64-06	PIN diode
BAR64-06W	Infineon	BAP64-06W	PIN diode
BAR65-02V	Infineon	BAP65-02	PIN diode
BAR65-02W	Infineon	BAP65-02	PIN diode
BAR65-03W	Infineon	BAP65-03	PIN diode
BAR66	Infineon	BAP1321-04	PIN diode
BAR67-02W	Infineon	BAP1321-02	PIN diode
BAR67-03W	Infineon	BAP1321-03	PIN diode
BB304C	Renesas	BF1201WR	FET
BB304M	Renesas	BF1201R	FET
BB305C	Renesas	BF1201WR	FET
BB305M	Renesas	BF1201R	FET
BB403M	Renesas	BF909R	FET
BB501C	Renesas	BF1202WR	FET
BB501M	Renesas	BF1202R	FET
BB502C	Renesas	BF1202WR	FET
BB502M	Renesas	BF1202R	FET
BB503C	Renesas	BF1202WR	FET
BB503M	Renesas	BF1202R	FET
BB535	Infineon	BB149	Varicap
BB545	Infineon	BB149A	Varicap
BB555	Infineon	BB179B	Varicap
BB555	Infineon	BB179B	Varicap
BB565	Infineon	BB179	Varicap
BB601M	Renesas	BF1202	FET
BB639	Infineon	BB148	Varicap
BB639	Infineon	BB153	Varicap
BB640	Infineon	BB152	Varicap
BB641	Infineon	BB152	Varicap
BB659	Infineon	BB178	Varicap
BB659	Infineon	BB178	Varicap
BB664	Infineon	BB187	Varicap
BB664	Infineon	BB178	Varicap
BB664	Infineon	BB178	Varicap
BB669	Infineon	BB152	Varicap
BB814	Infineon	BB201	Varicap
BB831	Infineon	BB131	Varicap
BB833	Infineon	BB131	Varicap
BB835	Infineon	BB131	Varicap
BBY58-02V	Infineon	BB202	Varicap
BBY65	Infineon	BB202	Varicap
BF1005S	Infineon	BF1105	FET
BF1009S	Infineon	BF1109	FET

Manufacturer type	Manufacturer	NXP type	Product family
BF1009SW	Infineon	BF1109WR	FET
BF2030	Infineon	BF1101	FET
BF2030R	Infineon	BF1101R	FET
BF2030W	Infineon	BF1101WR	FET
BF244A	IS	BF245A	FET
BF244B	IS	BF245B	FET
BF244C	IS	BF245C	FET
BF247A	IS	J108	FET
BF247B	IS	J108	FET
BF247C	IS	J108	FET
BF256A	IS	BF245A	FET
BF256B	IS	BF245B	FET
BF256C	IS	BF245C	FET
BF770A	Infineon	BFR93A	WB trs 1-4
BF771	Infineon	PBR951	WB trs 1-4
BF771W	Infineon	BFS540	WB trs 1-4
BF772	Infineon	BFG540	WB trs 1-4
BF775	Infineon	BFR92A	WB trs 1-4
BF775A	Infineon	BFR92A	WB trs 1-4
BF775W	Infineon	BFR92AW	WB trs 1-4
BF851A	IS	BF861A	FET
BF851B	IS	BF861B	FET
BF851C	IS	BF861C	FET
BF994S	Vishay	BF994S	FET
BF996S	Vishay	BF996S	FET
BF998	Vishay	BF998	FET
BF998	Infineon	BF998	FET
BF998R	Vishay	BF998R	FET
BF998RW	Vishay	BF998WR	FET
BF998W	Infineon	BF998WR	FET
BFG135A	Infineon	BFG135	WB trs 1-4
BFG193	Infineon	BFG198	WB trs 1-4
BFG194	Infineon	BFG31	WB trs 1-4
BFG196	Infineon	BFG541	WB trs 1-4
BFG19S	Infineon	BFG97	WB trs 1-4
BFG235	Infineon	BFG135	WB trs 1-4
BFP180	Infineon	BFG505/X	WB trs 1-4
BFP181	Infineon	BFG67/X	WB trs 1-4
BFP182	Infineon	BFG67/X	WB trs 1-4
BFP183	Infineon	BFG520/X	WB trs 1-4
BFP183R	Infineon	BFG520/XR	WB trs 1-4
BFP193	Infineon	BFG540/X	WB trs 1-4
BFP193W	Infineon	BFG540W/XR	WB trs 1-4
BFP196W	Infineon	BFG540W/XR	WB trs 1-4
BFP280	Infineon	BFG505/X	WB trs 1-4
BFP405	Infineon	BFG410W	WB trs 5-7
BFP420	Infineon	BFG425W	WB trs 5-7
BFP450	Infineon	BFG480W	WB trs 5-7
BFP81	Infineon	BFG92A/X	WB trs 1-4
BFP93A	Infineon	BFG93A/X	WB trs 1-4
BFQ193	Infineon	BFQ540	WB trs 1-4
BFQ19S	Infineon	BFQ19	WB trs 1-4
BFR106	Infineon	BFR106	WB trs 1-4
BFR180	Infineon	BFR505	WB trs 1-4
BFR180W	Infineon	BFS505	WB trs 1-4
BFR181	Infineon	BFR520	WB trs 1-4
BFR181W	Infineon	BFS520	WB trs 1-4
BFR182	Infineon	PBR941	WB trs 1-4
BFR182W	Infineon	PRF947	WB trs 1-4
BFR183	Infineon	PBR951	WB trs 1-4
BFR183W	Infineon	PRF957	WB trs 1-4
BFR193	Infineon	PBR951	WB trs 1-4
BFR193W	Infineon	PRF957	WB trs 1-4
BFR35AP	Infineon	BFR92A	WB trs 1-4
BFR92AL	Motorola	BFR92A	WB trs 1-4
BFR92P	Infineon	BFR92A	WB trs 1-4
BFR92W	Infineon	BFR92AW	WB trs 1-4
BFR93A	Infineon	BFR93A	WB trs 1-4
BFR93AL	Motorola	BFR93A	WB trs 1-4
BFR93AW	Infineon	BFR93AW	WB trs 1-4
BFS17L	Motorola	BFS17	WB trs 1-4
BFS17P	Infineon	BFS17A	WB trs 1-4
BFS17W	Infineon	BFS17W	WB trs 1-4
BFS481	Infineon	BFM505	WB trs 1-4

Manufacturer type	Manufacturer	NXP type	Product family
BFS483	Infineon	BFM520	WB trs 1-4
BFT92	Infineon	BFT92	WB trs 1-4
BFT93	Infineon	BFT93	WB trs 1-4
BIC701C	Renesas	BF1105WR	FET
BIC701M	Renesas	BF1105R	FET
BIC702C	Renesas	BF1105WR	FET
BIC702M	Renesas	BF1105R	FET
BIC801M	Renesas	BF1105	FET
BSR111	IS	PMBFJ111	FET
BSR112	IS	PMBFJ112	FET
BSR113	IS	PMBFJ113	FET
BSR174	IS	PMBFJ174	FET
BSR175	IS	PMBFJ175	FET
BSR176	IS	PMBFJ176	FET
BSR177	IS	PMBFJ177	FET
CA901	IS	BGX885N	CATV PPA
CA901A	IS	BGX885N	CATV PPA
CA922	IS	BGD885	CATV PD
CA922A	IS	BGD885	CATV PD
CMY91	Infineon	BGA2022	MMIC
D5540185	IS	BGD502	CATV PD
D7540185	IS	BGD702	CATV PD
D7540200	IS	BGD704	CATV PD
D8640185	IS	BGD802	CATV PD
D8640250GT	IS	CGD914	CATV PD
D8640250GTH	IS	CGD923	CATV PD
D8740180GT	IS	CGD923	CATV PD
D8740200GT	IS	CGD923	CATV PD
FSD273TA	Skyworks	BB148	Varicap
FSD273TA	Skyworks	BB178	Varicap
FSD273TA	Skyworks	BB178	Varicap
HBFP0405	Agilent	BFG410W	WB trs 5-7
HBFP0420	Agilent	BFG425W	WB trs 5-7
HBFP0450	Agilent	BFG480W	WB trs 5-7
HSC277	Renesas	BA277	BS diode
HSMP3800	Agilent	BAP70-03	PIN diode
HSMP3802	Agilent	BAP50-04	PIN diode
HSMP3804	Agilent	BAP50-05	PIN diode
HSMP3810	Agilent	BAP50-03	PIN diode
HSMP3814	Agilent	BAP50-05	PIN diode
HSMP381B	Agilent	BAP50-03	PIN diode
HSMP381C	Agilent	BAP50-05	PIN diode
HSMP381F	Agilent	BAP64-05W	PIN diode
HSMP3820	Agilent	BAP1321-03	PIN diode
HSMP3822	Agilent	BAP1321-04	PIN diode
HSMP3830	Agilent	BAP64-03	PIN diode
HSMP3832	Agilent	BAP64-04	PIN diode
HSMP3833	Agilent	BAP64-06	PIN diode
HSMP3834	Agilent	BAP64-05	PIN diode
HSMP3860	Agilent	BAP50-03	PIN diode
HSMP3862	Agilent	BAP50-04	PIN diode
HSMP3864	Agilent	BAP50-05	PIN diode
HSMP3866	Agilent	BAP50-02	PIN diode
HSMP386E	Agilent	BAP50-04W	PIN diode
HSMP386L	Agilent	BAP50-05W	PIN diode
HSMP3880	Agilent	BAP51-03	PIN diode
HSMP3890	Agilent	BAP51-03	PIN diode
HSMP3892	Agilent	BAP64-04	PIN diode
HSMP3894	Agilent	BAP64-05	PIN diode
HSMP3895	Agilent	BAP51-02	PIN diode
HSMP389B	Agilent	BAP51-02	PIN diode
HSMP389C	Agilent	BAP64-04	PIN diode
HSMP389F	Agilent	BAP51-05W	PIN diode
HVB14S	Renesas	BAP50-04W	PIN diode
HVC131	Renesas	BAP65-02	PIN diode
HVC132	Renesas	BAP51-02	PIN diode
HVC200A	Renesas	BB178	Varicap
HVC200A	Renesas	BB187	Varicap
HVC202A	Renesas	BB179	Varicap
HVC202B	Renesas	BB179B	Varicap
HVC300A	Renesas	BB182	Varicap
HVC300B	Renesas	BB182	Varicap
HVC306A	Renesas	BB187	Varicap
HVC306B	Renesas	BB187	Varicap

Manufacturer type	Manufacturer	NXP type	Product family
HVC355B	Renesas	BB145B	Varicap
HVC359	Renesas	BB202	Varicap
HVC363A	Renesas	BB178	Varicap
HVC363A	Renesas	BB178	Varicap
HVC376B	Renesas	BB198	Varicap
HVC376B	Renesas	BB202	Varicap
HVD132	Renesas	BAP51-02	PIN diode
HVU131	Renesas	BAP65-03	PIN diode
HVU132	Renesas	BAP51-03	PIN diode
HVU202(A)	Renesas	BB149	Varicap
HVU202(A)	Renesas	BB149A	Varicap
HVU300A	Renesas	BB152	Varicap
HVU307	Renesas	BB148	Varicap
HVU315	Renesas	BB148	Varicap
HVU316	Renesas	BB131	Varicap
HVU363A	Renesas	BB148	Varicap
HVU363A	Renesas	BB153	Varicap
HVU363B	Renesas	BB148	Varicap
INA-51063	Agilent	BGA2001	MMIC
J270	IS	J177	FET
J308	IS	J108	FET
J309	IS	J109	FET
J310	IS	J110	FET
JDP2S01E	Toshiba	BAP65-02	PIN diode
JDP2S01U	Toshiba	BAP65-03	PIN diode
JDP2S02T	Toshiba	BAP63-02	PIN diode
JDP2S04E	Toshiba	BAP50-02	PIN diode
KV1835E	Toko	BB199	Varicap
MA2S077	IS	BA277	BS diode
MA2S357	Matsushita	BB187	Varicap
MA2S357	Matsushita	BB178	Varicap
MA2S357	Matsushita	BB178	Varicap
MA2S372	Matsushita	BB179	Varicap
MA2S374	Matsushita	BB182	Varicap
MA2SV01	Renesas	BB202	Varicap
MA357	Matsushita	BB153	Varicap
MA366	Matsushita	BB148	Varicap
MA368	Matsushita	BB131	Varicap
MA372	Matsushita	BB149	Varicap
MA372	Matsushita	BB149A	Varicap
MA4CP101A	Matsushita	BAP65-03	PIN diode
MA4P274-1141	Matsushita	BAP51-03	PIN diode
MA4P275-1141	Matsushita	BAP65-03	PIN diode
MA4P275CK-287	Matsushita	BAP65-05	PIN diode
MA4P277-1141	Matsushita	BAP70-03	PIN diode
MA4P278-287	Matsushita	BAP70-03	PIN diode
MA4P789-1141	Matsushita	BAP1321-03	PIN diode
MA4P789ST-287	Matsushita	BAP1321-04	PIN diode
MC7712	IS	BGY785A	CATV PPA
MC7716	IS	BGY787	CATV PPA
MC7722	IS	BGY785A	CATV PPA
MC7726	IS	BGY787	CATV PPA
MC7833	IS	CGY887A	CATV PPA/HG
MC7852	IS	BGY885A	CATV PPA
MC7862	IS	CGD923	CATV PD
MC7866	IS	BGD816L	CATV PD
MHW1224	Motorola/Freescale	BGY67	CATV RA
MHW1244	Motorola/Freescale	BGY67A	CATV RA
MHW1253LA	Motorola/Freescale	BGY67A	CATV RA
MHW1254L	Motorola/Freescale	BGY68	CATV RA
MHW1254LA	Motorola/Freescale	BGY68	CATV RA
MHW1304L	Motorola/Freescale	BGY68	CATV RA
MHW1304LA	Motorola/Freescale	BGY68	CATV RA
MHW1304LAN	Motorola/Freescale	BGY68	CATV RA
MHW1346	Motorola/Freescale	BGY67A	CATV RA
MHW1353LA	Motorola/Freescale	BGY67A	CATV RA
MHW1354LA	Motorola/Freescale	BGY68	CATV RA
MHW5182A	Motorola/Freescale	BGY585A	CATV PPA
MHW5185B	Motorola/Freescale	BGD502	CATV PD
MHW5222A	Motorola/Freescale	BGY587	CATV PPA
MHW5272A	Motorola/Freescale	BGY587B	CATV PPA/HG
MHW5342A	Motorola/Freescale	BGY588N	CATV PPA/HG
MHW5342T	Motorola/Freescale	BGY588N	CATV PPA/HG
MHW6182	Motorola/Freescale	BGY585A	CATV PPA

Manufacturer type	Manufacturer	NXP type	Product family
MHW6182-6	Motorola/Freescale	BGY685A	CATV PPA
MHW6182T	Motorola/Freescale	BGY585A	CATV PPA
MHW6185B	Motorola/Freescale	BGD502	CATV PD
MHW6185T	Motorola/Freescale	BGD502	CATV PD
MHW6205	Motorola/Freescale	BGD704	CATV PD
MHW6222	Motorola/Freescale	BGY587	CATV PPA
MHW6222B	Motorola/Freescale	BGY687	CATV PPA
MHW6222T	Motorola/Freescale	BGY587	CATV PPA
MHW6272	Motorola/Freescale	BGY587B	CATV PPA
MHW6272T	Motorola/Freescale	BGY587B	CATV PPA
MHW6342	Motorola/Freescale	BGY588N	CATV PPA
MHW6342T	Motorola/Freescale	BGY588N	CATV PPA
MHW7182B	Motorola/Freescale	BGY785A	CATV PPA
MHW7182C	Motorola/Freescale	BGY785A	CATV PPA
MHW7185C	Motorola/Freescale	BGY785A	CATV PPA
MHW7185C	Motorola/Freescale	BGD712	CATV PD
MHW7185CL	Motorola/Freescale	BGD712	CATV PD
MHW7205C	Motorola/Freescale	BGD714	CATV PD
MHW7205CL	Motorola/Freescale	BGD714	CATV PD
MHW7205CLN	Motorola/Freescale	BGD714	CATV PD
MHW7222	Motorola/Freescale	BGY787	CATV PPA
MHW7222A	Motorola/Freescale	BGY787	CATV PPA
MHW7222B	Motorola/Freescale	BGY787	CATV PPA
MHW7222B	Motorola/Freescale	BGY787	CATV PPA
MHW7242A	Motorola/Freescale	BGE787B	CATV PPA/HG
MHW7272A	Motorola/Freescale	BGE787B	CATV PPA/HG
MHW7292	Motorola/Freescale	BGE787B	CATV PPA/HG
MHW7292A	Motorola/Freescale	BGE787B	CATV PPA/HG
MHW7292AN	Motorola/Freescale	BGE787B	CATV PPA/HG
MHW7342	Motorola/Freescale	BGE788	CATV PPA/HG
MHW8142	Motorola/Freescale	BGY883	CATV PPA
MHW8182B	Motorola/Freescale	BGY885A	CATV PPA
MHW8182C	Motorola/Freescale	BGY885A	CATV PPA
MHW8185	Motorola/Freescale	BGD902	CATV PD
MHW8185L	Motorola/Freescale	BGD902L	CATV PD
MHW8188A	Motorola/Freescale	BGD906	CATV PD
MHW8205	Motorola/Freescale	BGD904	CATV PD
MHW8205L	Motorola/Freescale	BGD904L	CATV PD
MHW8207A	Motorola/Freescale	BGD906	CATV PD
MHW8227A	Motorola/Freescale	CGD942C	CATV PD
MHW8242A	Motorola/Freescale	CGY887A	CATV PPA
MHW8247A	Motorola/Freescale	CGD944C	CATV PPA
MHW8272A	Motorola/Freescale	CGY887B	CATV PPA
MHW8292	Motorola/Freescale	BGY887B	CATV PPA
MHW8342	Motorola/Freescale	BGY888	CATV PPA
MHW9146	Motorola/Freescale	BGY883	CATV PPA
MHW9186	Motorola/Freescale	BGY885A	CATV PPA
MHW9186A	Motorola/Freescale	BGY885A	CATV PPA
MHW9182B	Motorola/Freescale	BGY1085A	CATV PPA
MHW9182C	Motorola/Freescale	BGY1085A	CATV PPA
MHW9187	Motorola/Freescale	CGD923	CATV PD
MHW9188	Motorola/Freescale	CGD923	CATV PD
MHW9188A	Motorola/Freescale	BGD904	CATV PD
MHW9189	Motorola/Freescale	BGD904	CATV PD
MHW9189A	Motorola/Freescale	BGD904	CATV PD
MHW9207A	Motorola/Freescale	BGD906	CATV PD
MHW9227A	Motorola/Freescale	BGD906	CATV PD
MHW9236	Motorola/Freescale	CGY887A	CATV PPA/HG
MHW9242A	Motorola/Freescale	CGD1042	CATV PD
MHW9247	Motorola/Freescale	CGD944C	CATV PD
MHW9247A	Motorola/Freescale	CGD944C	CATV PD
MHW9276	Motorola/Freescale	CGY887B	CATV PPA/HG
MHWJ5272A	Motorola/Freescale	BGY587B	CATV PPA
MHWJ7185A	Motorola/Freescale	BGD712	CATV PD
MHWJ7205A	Motorola/Freescale	BGD714	CATV PD
MHWJ7292	Motorola/Freescale	BGE787B	CATV PPA/HG
MHWJ9182	Motorola/Freescale	BGY1085A	CATV PPA
MMG2001NT1	Motorola/Freescale	BGD816L	CATV PD
MMG2001T1	Motorola/Freescale	BGD816L	CATV PD
MMBF4391	Motorola	PMBF4391	FET
MMBF4392	Motorola	PMBF4392	FET
MMBF4393	Motorola	PMBF4393	FET
MMBF4860	Motorola	PMBFJ112	FET
MMBF5484	Motorola	BFR31	FET

Manufacturer type	Manufacturer	NXP type	Product family
MMBFJ113	Motorola	PMBFJ113	FET
MMBFJ174	Motorola	PMBFJ174	FET
MMBFJ175	Motorola	PMBFJ175	FET
MMBFJ176	Motorola	PMBFJ176	FET
MMBFJ177	Motorola	PMBFJ177	FET
MMBFJ308	Motorola	PMBFJ308	FET
MMBFJ309	Motorola	PMBFJ309	FET
MMBFJ310	Motorola	PMBFJ310	FET
MMBFU310	Motorola	PMBFJ310	FET
MMBR5031L	Motorola	BFS17	WB trs 1-4
MMBR5179L	Motorola	BFS17A	WB trs 1-4
MMBR571L	Motorola	PBR951	WB trs 1-4
MMBR901L	Motorola	BFR92A	WB trs 1-4
MMBR911L	Motorola	BFR93A	WB trs 1-4
MMBR920L	Motorola	BFR93A	WB trs 1-4
MMBR931L	Motorola	BFT25A	WB trs 1-4
MMBR941BL	Motorola	PBR941	WB trs 1-4
MMBR941L	Motorola	PBR941	WB trs 1-4
MMBR951AL	Motorola	PBR951	WB trs 1-4
MMBR951L	Motorola	PBR951	WB trs 1-4
MMBV105GLT1	ON Semicond.	BB156	Varicap
MMBV109LT1	ON Semicond.	BB148	Varicap
MPF102	IS	BF245A	FET
MPF970	IS	J174	FET
MPF971	IS	J176	FET
MRF577	Motorola	PRF957	WB trs 1-4
MRF5811L	Motorola	BFG93A/X	WB trs 1-4
MRF917	Motorola	BFQ67W	WB trs 1-4
MRF927	Motorola	BFS25A	WB trs 1-4
MRF9411L	Motorola	BFG520/X	WB trs 1-4
MRF947	Motorola	BFS520	WB trs 1-4
MRF947A	Motorola	PRF947	WB trs 1-4
MRF9511L	Motorola	BFG540/X	WB trs 1-4
MRF957	Motorola	PRF957	WB trs 1-4
MT4S34U	Toshiba	BFG410W	WB trs 5-7
PRF947B	Motorola	PRF947	WB trs 1-4
PZFJ108	IS	J108	FET
PZFJ109	IS	J109	FET
PZFJ110	IS	J110	FET
R0605250L	IS	BGY66B	CATV RA
R0605300L	IS	BGY68	CATV RA
R2005240	IS	BGY67A	CATV RA
RN142G	Rohm	BAP1321-03	PIN diode
RN142S	Rohm	BAP1321-02	PIN diode
RN731V	Rohm	BAP50-03	PIN diode
RN739D	Rohm	BAP50-04	PIN diode
RN739F	Rohm	BAP50-04W	PIN diode
S505T	Vishay	BF1101	FET
S505TR	Vishay	BF1101R	FET
S505TRW	Vishay	BF1101WR	FET
S5540220	IS	BGY587	CATV PPA
S595T	Vishay	BF1105	FET
S595TR	Vishay	BF1105R	FET
S595TRW	Vishay	BF1105WR	FET
S7540185	IS	BGY785A	CATV PPA
S7540215	IS	BGY787	CATV PPA
S8740190	IS	BGD812	CATV PD
S8740220	IS	BGD814	CATV PD
S8740230	IS	BGD816L	CATV PD
S949T	Vishay	BF1109	FET
S949TR	Vishay	BF1109R	FET
S949TRW	Vishay	BF1109WR	FET
S974T	Vishay	BF1109	FET
S974TR	Vishay	BF1109R	FET
S974TRW	Vishay	BF1109WR	FET
SMP1302-004	Skyworks	BAP50-05	PIN diode
SMP1302-005	Skyworks	BAP50-04	PIN diode
SMP1302-011	Skyworks	BAP50-03	PIN diode
SMP1302-074	Skyworks	BAP50-05W	PIN diode
SMP1302-075	Skyworks	BAP50-04W	PIN diode
SMP1302-079	Skyworks	BAP50-02	PIN diode
SMP1304-001	Skyworks	BAP70-03	PIN diode
SMP1304-011	Skyworks	BAP70-03	PIN diode
SMP1307-001	Skyworks	BAP70-03	PIN diode

Manufacturer type	Manufacturer	NXP type	Product family
SMP1307-011	Skyworks	BAP70-03	PIN diode
SMP1320-004	Skyworks	BAP65-05	PIN diode
SMP1320-011	Skyworks	BAP65-03	PIN diode
SMP1320-074	Skyworks	BAP65-05W	PIN diode
SMP1321-001	Skyworks	BAP1321-03	PIN diode
SMP1321-005	Skyworks	BAP1321-04	PIN diode
SMP1321-011	Skyworks	BAP1321-03	PIN diode
SMP1321-075	Skyworks	BAP1321-04	PIN diode
SMP1321-079	Skyworks	BAP1321-02	PIN diode
SMP1322-004	Skyworks	BAP65-05	PIN diode
SMP1322-011	Skyworks	BAP65-03	PIN diode
SMP1322-074	Skyworks	BAP65-05W	PIN diode
SMP1322-079	Skyworks	BAP65-02	PIN diode
SMP1340-011	Skyworks	BAP63-03	PIN diode
SMP1340-079	Skyworks	BAP63-02	PIN diode
SMP1352-011	Skyworks	BAP64-03	PIN diode
SMP1352-079	Skyworks	BAP64-02	PIN diode
SMV1235-004	Skyworks	BB181	Varicap
SMV1236-004	Skyworks	BB156	Varicap
SST111	IS	PMBFJ111	FET
SST112	IS	PMBFJ112	FET
SST113	IS	PMBFJ113	FET
SST174	IS	PMBFJ174	FET
SST175	IS	PMBFJ175	FET
SST176	IS	PMBFJ176	FET
SST177	IS	PMBFJ177	FET
SST201	IS	BFT46	FET
SST202	IS	BFR31	FET
SST203	IS	BFR30	FET
SST308	IS	PMBFJ308	FET
SST309	IS	PMBFJ309	FET
SST310	IS	PMBFJ310	FET
SST4391	IS	PMBF4391	FET
SST4392	IS	PMBF4392	FET
SST4393	IS	PMBF4393	FET
SST4856	IS	BSR56	FET
SST4857	IS	BSR57	FET
SST4859	IS	BSR56	FET
SST4860	IS	BSR57	FET
SST4861	IS	BSR58	FET
SVC201SPA	Sanyo	BB187	Varicap
TMPF4091	IS	PMBF4391	FET
TMPF4092	IS	PMBF4392	FET
TMPF4093	IS	PMBF4393	FET
TMPF4391	IS	PMBF4391	FET
TMPF4392	IS	PMBF4392	FET
TMPF4393	IS	PMBF4393	FET
TMPFB246A	IS	BSR56	FET
TMPFB246B	IS	BSR57	FET
TMPFB246C	IS	BSR58	FET
TMPFJ111	IS	PMBFJ111	FET
TMPFJ112	IS	PMBFJ112	FET
TMPFJ113	IS	PMBFJ113	FET
TMPFJ174	IS	PMBFJ174	FET
TMPFJ175	IS	PMBFJ175	FET
TMPFJ176	IS	PMBFJ176	FET
TMPFJ177	IS	PMBFJ177	FET
TSDF54040	Vishay	BF1102	FET
uPC2709	NEC	BGA2709	MMIC
uPC2711	NEC	BGA2711	MMIC
uPC2712	NEC	BGA2712	MMIC
uPC2745	NEC	BGA2001	MMIC
uPC2746	NEC	BGA2001	MMIC
uPC2748	NEC	BGA2748	MMIC
uPC2771	NEC	BGA2771	MMIC
uPC8112	NEC	BGA2022	MMIC

4.2 Cross-references: NXP discontinued types versus NXP replacement types

In alphabetical order of manufacturer type

Abbreviations:

BS diode	Band Switch Diode
CATV	Community Antenna Television System
FET	Field Effect Transistor
Varicap	Varicap Diode
WB trs	Wideband Transistor
OM	Optical Module

NXP discontinued type	Product family	NXP replacement type	NXP discontinued type	Product family	NXP replacement type
BA277-01	BS diode	BA277	BFR93	WB trs	BFR92A
BAP142L	PIN diode	BAP142LX	BFR93AT	WB trs	BFR93AW
BAP51-01	PIN diode	BAP51LX	BFR93R	WB trs	BFR93A
BAP51L	PIN diode	BAP51LX	BFU510	WB trs	BFU725F
BAP55L	PIN diode	BAP55LX	BFU540	WB trs	BFU725F
BB145	Varicap	BB145B	BGA2031	WB trs	BGA2031/1
BB145B-01	Varicap	BB145B	BGD102/02	CATV	BGD502
BB151	varicap	BB135	BGD102/04	CATV	BGD502
BB157	varicap	BB187	BGD104	CATV	BGD704
BB178L	Varicap	BB178LX	BGD104/04	CATV	BGD704
BB179BL	Varicap	BB179BLX	BGD502/01	CATV	BGD502
BB179L	Varicap	BB179LX	BGD502/01	CATV	BGD502
BB181L	Varicap	BB181LX	BGD502/01	CATV	BGD502
BB182B	Varicap	BB182	BGD502/01	CATV	BGD502
BB182B	Varicap	BB182	BGD502/03	CATV	BGD502
BB182L	Varicap	BB182LX	BGD502/03	CATV	BGD502
BB187L	Varicap	BB187LX	BGD502/05	CATV	BGD502
BB190	Varicap	BB149	BGD502/07	CATV	BGD502
BB202L	Varicap	BB202LX	BGD502/6M	CATV	BGD702
BB804	Varicap	BB207	BGD502/C7	CATV	BGD502
BBY42	Varicap	BBY40	BGD502/R	CATV	BGD502
BF1203	FET	BF1203	BGD504	CATV	BGD704
BF689K	WB trs	BFS17	BGD504/01	CATV	BGD704
BF763	WB trs	BFS17	BGD504/02	CATV	BGD704
BF851A	FET	BF861A	BGD504/09	CATV	BGD704
BF851A	FET	BF861A	BGD602	CATV	BGD702
BF851B	FET	BF851B	BGD602/02	CATV	BGD702
BF851B	FET	BF851B	BGD602/07	CATV	BGD702
BF851C	FET	BF861C	BGD602/09	CATV	BGD702
BF851C	FET	BF861C	BGD602/14	CATV	BGD702
BF992/01	FET	BF992	BGD602D	CATV	BGD712
BFC505	WB trs	BFM505	BGD702D	CATV	BGD712
BFC520	WB trs	BFM520	BGD702D/08	CATV	BGD712
BFET505	WB trs	BFM505	BGD704/01	CATV	BGD704
BFET520	WB trs	BFM520	BGD704/07S	CATV	BGD704
BFG17A	WB trs	BFS17A	BGD704/S9	CATV	BGD704
BFG197	WB trs	BFG198	BGD704N	CATV	BGD714
BFG197/X	WB trs	BFG198	BGD802/09	CATV	BGD802
BFG25AW/XR	WB trs	BFG25AW/X	BGD802N	CATV	BGD812
BFG410W/CA	WB trs	BFG410W	BGD802N	CATV	BGD812
BFG425W/CA	WB trs	BGF425W	BGD802N/07	CATV	BGD812
BFG425W/CA	WB trs	BGF425W	BGD802N/07	CATV	BGD812
BFG505/XR	WB trs	BFG505/X	BGD804N	CATV	BGD814
BFG505W/XR	WB trs	BFG505W/X	BGD804N	CATV	BGD814
BFG520W/XR	WB trs	BFG520W/X	BGD804N/02	CATV	BGD814
BFG590/XR	WB trs	BFG590/X	BGD804N/02	CATV	BGD814
BFG590W	WB trs	BFG590W/X	BGD902/07	CATV	BGD902
BFG590W/XR	WB trs	BFG590W/X	BGD904/02	CATV	BGD904
BFG67/XR	WB trs	BFG67	BGD904/07	CATV	BGD904
BFG92A	WB trs	BFG92A/X	BGD906/02	CATV	BGD906
BFG92A/XR	WB trs	BFG92A/X	BGE847BO	CATV	BGO827
BFG93A/XR	WB trs	BFG93A/X	BGE847BO	CATV	BGO827
BFQ34/01	WB trs	BFG35	BGE847BO	CATV	BGO827
BFR92	WB trs	BFR92A	BGE847BO/FC	CATV	BGO827/SC0
BFR92AR	WB trs	BFR92A	BGE847BO/FC0	CATV	BGO827/SC0
BFR92AT	WB trs	BFR92AW	BGE847BO/FC0	CATV	BGO827/SC0

NXP discontinued type	Product family	NXP replacement type
BGE847BO/FC1	CATV	BGO827/SC0
BGE847BO/SC	CATV	BGO827/SC0
BGE847BO/SC0	CATV	BGO827/SC0
BGE847BO/SC0	CATV	BGO827/SC0
BGE887BO	CATV	BGO827
BGE887BO/FC	CATV	BGO827/SC0
BGE887BO/FC1	CATV	BGO827/SC0
BGE887BO/SC	CATV	BGO827/SC0
BGO847/01	CATV	BGO847
BGO847/01	CATV	BGO847
BGO847/FC0	CATV	BGO827/SC0
BGO847/FC0	CATV	BGO827/SC0
BGO847/FC01	CATV	BGO827/SC0
BGO847/FC01	CATV	BGO827/SC0
BGO847/SC0	CATV	BGO827/SC0
BGQ34/01	WB	BFG35
BGU2003	WB trs	BGA2003
BGX885/02	CATV	BGX885N
BGY1085A/07	CATV	BGY1085A
BGY584A	CATV	BGY585A
BGY585A/01	CATV	BGY585A
BGY586	CATV	BGY587
BGY586/05	CATV	BGY587
BGY587/01	CATV	BGY587
BGY587/01	CATV	BGY587
BGY587/02	CATV	BGY587
BGY587/02	CATV	BGY587
BGY587/07	CATV	BGY587
BGY587/09	CATV	BGY587
BGY587B/01	CATV	BGY587B
BGY587B/02	CATV	BGY587B
BGY587B/09	CATV	BGY587B
BGY588	CATV	BGY588N
BGY588/04	CATV	BGY588N
BGY66B/04	CATV	BGY66B
BGY67/04	CATV	BGY67
BGY67/09	CATV	BGY67
BGY67/14	CATV	BGY67
BGY67/19	CATV	BGY67
BGY67A/04	CATV	BGY67A
BGY67A/14	CATV	BGY67A
BGY68/01	CATV	BGY68
BGY685A/07	CATV	BGY685A
BGY685AD	CATV	BGY785A
BGY685AD	CATV	BGY785A
BGY685AL	CATV	BGY785A
BGY687/07	CATV	BGY687
BGY687/14	CATV	BGY687
BGY687B	CATV	BGE787B
BGY687B/02	CATV	BGE787B
BGY785A/07	CATV	BGY785A
BGY785A/09	CATV	BGY785A
BGY785AD	CATV	BGY785A
BGY785AD/06	CATV	BGY785A
BGY785AD/8M	CATV	BGY885A
BGY785AD/8M	CATV	BGY885A

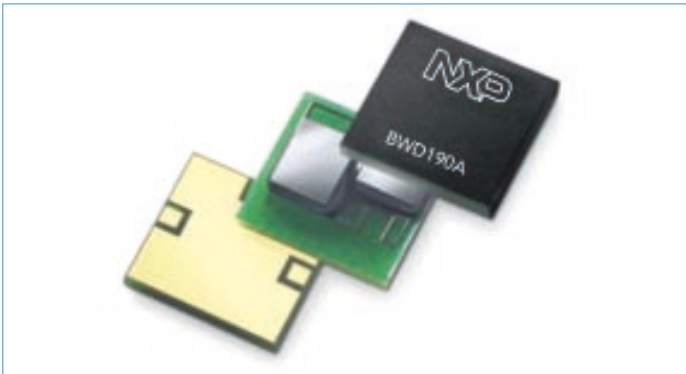
NXP discontinued type	Product family	NXP replacement type
BGY787/02	CATV	BGY787
BGY787/07	CATV	BGY787
BGY787/09	CATV	BGY787
BGY847BO	CATV	BGO827
BGY847BO/SC	CATV	BGO827/SC0
BGY84A	CATV	BGY585A
BGY84A/04	CATV	BGY585A
BGY84A/05	CATV	BGY585A
BGY85	CATV	BGY585A
BGY85A	CATV	BGY585A
BGY85A/04	CATV	BGY585A
BGY85A/05	CATV	BGY585A
BGY85H/01	CATV	BGY585A
BGY86	CATV	BGY587
BGY86/05	CATV	BGY587
BGY87	CATV	BGY587
BGY87/J1	CATV	BGY587
BGY87B	CATV	BGY587B
BGY88	CATV	BGY588N
BGY88/04	CATV	BGY588N
BGY88/04	CATV	BGY588N
BGY88/07	CATV	BGY588N
BGY887/02	CATV	BGY887
BGY887BO	CATV	BGO827
BGY887BO/FC	CATV	BGO827/FC0
BGY887BO/SC	CATV	BGO827/SC0
ON4520/09	CATV	BGY687
ON4520/2	CATV	BGY687
ON4594/M5	CATV	BGY585A
ON4749	CATV	BGY588N
ON4749	CATV	BGY588N
ON4831-2	CATV	BGY885A
ON4869	CATV	BGY587
ON4876	CATV	BGY1085A
ON4890	CATV	BGD712
ON4890	CATV	BGD712
ON4990	CATV	BGD885
OQ2545	OM	TZA3011
OQ2545B	OM	TZA3011
PMBT3640/AT	WB trs	BFS17
PN4392	FET	PMBF4392
PN4393	FET	PMBF4393
SA5223	OM	TZA3036
TZA3001	OM	TZA3047
TZA3001	OM	TZA3047
TZA3023	OM	TZA3026
TZA3031	OM	TZA3047
TZA3031	OM	TZA3047
TZA3033	OM	TZA3036
TZA3041	OM	TZA3047
TZA3042B	OM	TZA3047
TZA3043	OM	TZA3046
TZA3043B	OM	TZA3046
XSA5223	OM	TZA3036
XSA5223	OM	TZA3036

5. Focus applications & products

5.1 High performance miniature BAW filters and duplexers

Bulk Acoustic Wave (BAW) filters and duplexers for Front-End Modules and Cellular Phones

Bulk Acoustic Wave filters provide high performance, ultra small size solutions for next generation integrated cellular phones. Together with NXP Waferlevel Package this allows for seamless integration of BAW filters into RF front-end modules.



The NXP series of high-performance Bulk Acoustic Wave (BAW) filters and duplexers is optimized for (W-)CDMA/GSM cellular phones. Available in NXP-patented Wafer Level Chip Scale Packaging (WL-CSP), they provide superior performance in an ultra-small size.

Compared to Surface Acoustic Wave (SAW) filters, BAW typically offers superior power handling, enhanced ESD robustness, smaller size, reduced in-band insertion loss and increased steepness of the filter skirts in lower and upper transition bands. BAW filters also offer less center frequency drift versus temperature change and are more suitable for applications at frequencies ranging from 1 to 20 GHz.

Features

- High performance BAW filters and duplexers
 - Low insertion loss
 - High stopband rejections/isolations
 - Low temperature drift
 - Superior power handling
 - Enhanced ESD robustness
- Ultra-small, NXP-Waferlevel Package
 - Ultra-small footprint (as small as 1.5mm²)
 - Very low profile (height < 450 µm after solder reflow)

Benefits

- Optimized for:
 - UMTS interstage filter (band II)
 - UMTS Duplexer (band I, II, III, VII)
 - Satellite radio, Bluetooth
- Easy package-less chip scale integration into RF front-end module
- In house EM simulation to support FEM design in
- Reduced PCB implementation size
- Ideal for high frequency applications
- Superior performance in very small size

High-performance BAW filters & Duplexers

Designed for easy integration into front-end modules, they deliver low insertion loss and high selectivity. NXP BAW filters and duplexers support receive (Rx) and transmit (Tx) applications in (W-)CDMA and other wireless applications higher than 1.5 GHz :

- US PCS (1900 MHz)
 - BWT190(A) high-rejection Tx interstage filter
 - BWD190(A) duplexer
- UMTS (2100MHz)
 - BWD210(A) BAW duplexer
- Satellite filter (2300 MHz)
 - BWR230(A) antenna filter

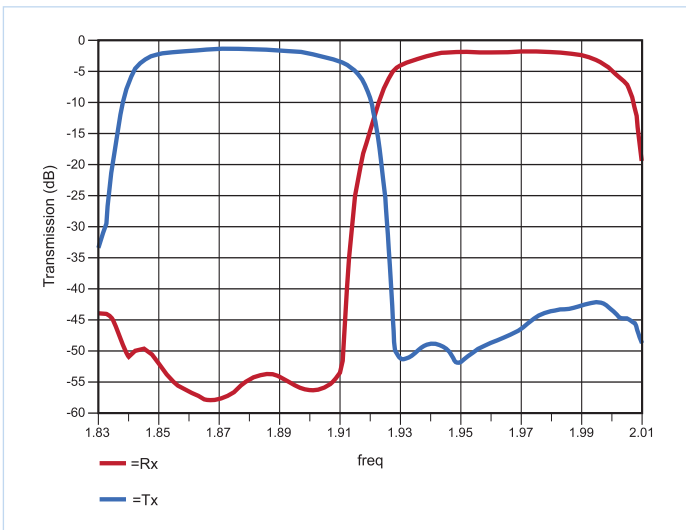
NXP Semiconductors BAW devices

Type	Description	Freq. (MHz)	Size chip scale (mm ²)	Molded
BWT190(A)	PCS Tx interstage filter	1900	1.4 x 0.7	2.0 x 1.6
BWD190(A)	PCS duplexer	1900	Tx: 1.3 x 0.9 Rx: 1.4 x 0.9	3 x 2.5
BWD210(A)	UMTS duplexer	2100	Tx: 1.3 x 0.9 Rx: 1.4 x 0.9	3 x 2.5
BWR230(A)	Satellite filter	2300	n.a.	1.6 x 1.0

Electrical characteristics of the BWD190A, T_j = 25°C, Z₀ = 50Ω

Parameter	Band	Frequency (MHz)	Min (dB)	Max (dB)
Insertion Loss	Tx	1850 – 1910	-	2.8
	Rx	1930 – 1990	-	3.0
Ripple	Tx		-	0.5
Rejection			-	-
Tx to Antenna	Rx		41	-
Rx to Antenna	Tx		50	-
Return Loss	Tx		12	-
	Rx		12	-
	Antenna		12	-
Isolation (Tx – Rx)	Tx		53	-
	Rx		45	-

Passband characteristics of duplexer BWD190A



5.2 Total solution for satellite LNB

Create a Ku-band DVB-S LNB for less, with higher reliability

NXP fully integrated down converter (PLL synthesizer/mixer/amplifier) TFF1004HN for satellite LNB

The TFF1004HN is an integrated downconverter for use in Low Noise Block (LNB) converters in a 10.7 GHz to 12.75 GHz Ku band satellite receiver system. This alignment-free concept replaces current solutions that require components such as GaAs mixer and DRO. As part of our LNB chipset, it enables a Ku-band satellite receiver that lowers total cost of ownership and guarantees the stability of the local oscillator.



Features

- 4 Pre-amplifier, mixer, buffer amplifier, and PLL synthesizer in one IC
- State-of-the-art SiGe BiCMOS process
- Alignment-free concept
- LO frequency with XTAL control
- Low phase noise
- Switched LO frequency: 9.75 and 10.6 GHz
- Low spurious
- HVQFN24 package (4 x 4 x 0.85 mm)
- Part of complete LNB chipset:
 - NXP UAF3000TS for supply and band/polarization switching
 - NXP BFU725F for 2nd LNA stage
- Demo board available

Application

- 4 Ku-band DVB-S receiver

Designed for use in the Low Noise Block (LNB) of a Ku-band satellite receiver for Asian and European standards, the NXP

TFF1004HN is a highly integrated IC that includes an LNA, a mixer, a down-converter, a PLL, a crystal oscillator, and an IF buffer.

It is manufactured in NXP's breakthrough SiGe BiCMOS process for microwave applications, which is more cost-effective than GaAs processes and more reliable than discrete implementations.

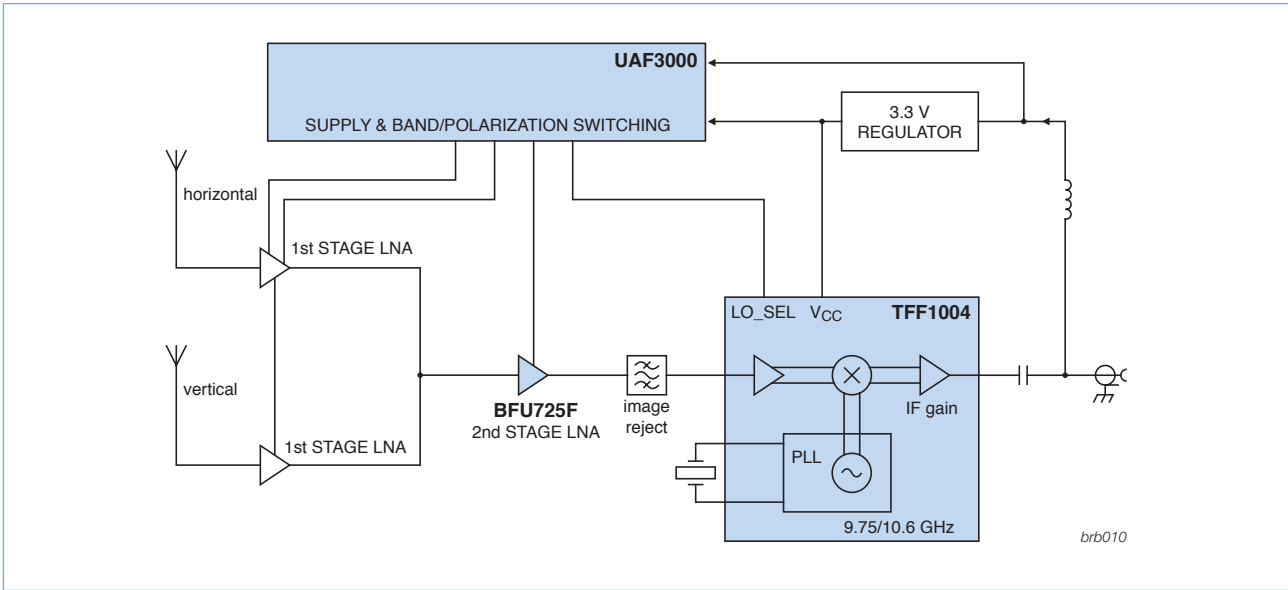
To comply with Asian and European DVB-S standards, the TFF1004HN supports RF input frequencies between 10.7 and 12.75 GHz, and uses a selectable LO that operates at 9.75 or 10.6 GHz.

It is housed in a small HVQFN24 package that measures only 4 x 4 x 0.85 mm, and is designed to work as part of a complete chipset that provides a total LNB solution.

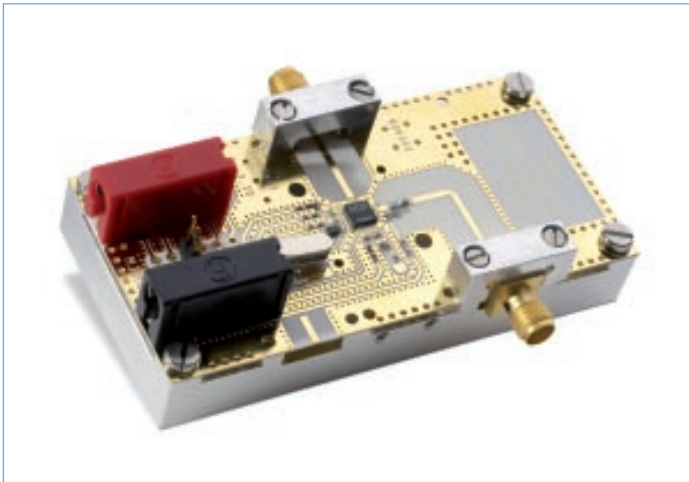
Complete LNB chipset

The chipset consists of the TFF1004HN, the UAF3000TS, and the BFU725F. The UAF3000TS is a FET bias controller with a polarization switch and tone detection. It provides biasing for up to three LNA devices. An integrated bandgap reference ensures the accuracy of voltage and tone detection, also over temperature. For horizontal and vertical switching, there is an integrated supply-voltage detector, and for switching between high and low bands, there is a 22-kHz tone detector. The supply voltage range, 3.3 V or 5 V, is detected automatically.

The BFU725F is an NPN microwave transistor for high-speed, low-noise applications. In the LNB chipset, it is used for the second LNA stage. It is manufactured in a 110-GHz fT-SiGeC technology, so it delivers an excellent noise figure (1.0 dB at 12 GHz), and a high maximum stable gain (13 dB at 12 GHz).



LNB application with TFF1004HN, UAF3000TS, and BFU725F



TFF1004HN demo board

	Input frequency range (GHz)	Conversion gain Gc (dB)	Noise figure NF (dB)	Output IP3 IP3(out) (dB)	Switched LO frequency (GHz)
TFF1004HN	10.7 to 12.75	32	9	10	9.75 / 10.6
	Typ. collector current IC(max) (mA)	Transition frequency fT (GHz)	Noise figure NF (dB) @ 12 GHz	Max. stable power gain MSG/GP(max) (dB) @ 12 GHz	Collector-emitter breakdown voltage BVCEO (V)
BFU725F	8	68	1.0	13	3.2
	Supply voltage VCC (V)	Drain voltage VD (V)	Drain current IDO (mA)	Supply current ICC (mA)	Polarization detection voltage VPOL (V)
UAF3000TS	3.3 or 5	2	10	6	14.75

5.3 NXP CATV C-family for the Chinese SARFT standard

Connecting people, protecting your network

Specially designed for the Chinese Hybrid Fiber Coax (HFC) infrastructure, NXP CATV C-family offers you a total solution for cable TV networks. It is both flexible enough for connecting rural communities as part of China's 'Connecting every village' program and powerful enough for upgrading major cities from analog to high-end digital services. All C-type devices are compliant with the Chinese State Administration for Radio, Film and Television (SARFT) standard, and cover most HFC applications in the 550 - 870 MHz range.



Products

- BGY588C, BGE788C and CGY888C push-pull amplifiers
- BGD712C, CGD944C and CGD942C power doublers
- BGO807C optical receiver

Features

- Excellent linearity, stability and reliability
- High power gain
- Extremely low noise
- Silicon Nitride passivity
- GaAs HFET dies for high end devices

Benefits

- Compliant with Chinese SARFT HFC networks standard
- Transparent cap allows confirmation of product authenticity
- Rugged construction

Further extending our high quality CATV portfolio, this new family lets you address an even wider range of HFC applications. Dedicated solutions for the implementation of CATV systems in China, our C-type devices deliver the performance you need for modern TV infrastructures.

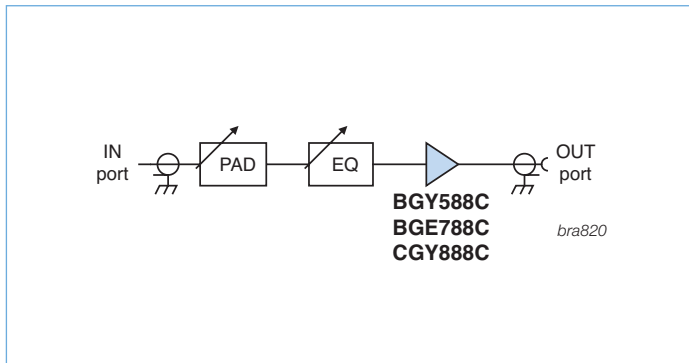
The BGY588C, BGE788C and BGD712C devices cover the frequency range from 550 MHz to 750 MHz. Extending the C-family portfolio into the high-end segment, the CGD944C, CGD942C, CGY888C and BGO807C operate between 40 MHz and 870 MHz and have been specifically tested under Chinese raster conditions. Manufactured using our GaAs HFET die process, the CGD942C, and CGD944C are high-gain, high-performance 870 MHz power doublers. They are capable of satisfying the demanding requirements of top-end applications including high-power optical nodes.

Our GaAs HFET MMIC dies are providing 'by design' the best ESD protection levels with no needs for external TVS components normally used with GaAs pHEMT devices.

All CATV C-type devices feature a see-through cap that makes it easy to distinguish them from counterfeit products.

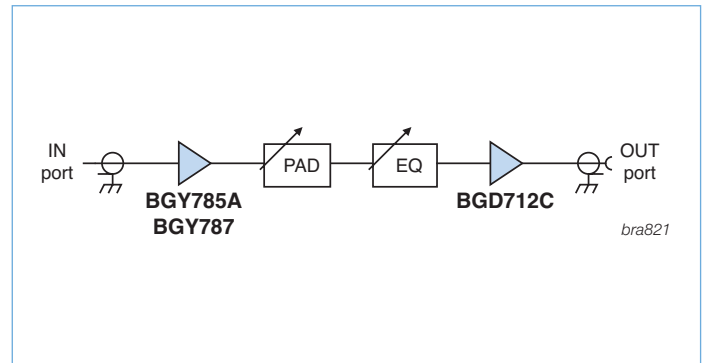
BGY588C and BGE788C

The last stage of an HFC network structure is called a terminating amplifier or 'user amplifier' as it is close to the subscribers. Each terminating amplifier requires a single module such as BGY588C for 550 MHz, BGE788C for 750 MHz and CGY888C for 860 MHz systems. These modules are fitting perfectly in the Chinese 'Connecting to Every Village' projects.



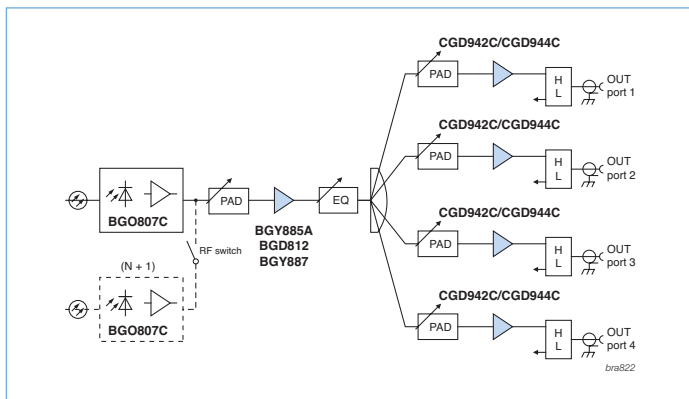
BGD712C

The BGD712C is a 750 MHz, 18 dB power doubler module. It has been designed for 750 MHz optical nodes including ordinary or optical receivers and distribution amplifiers. It can also be used in line extender amplifiers together with a 750 MHz push-pull module, such as BGY785A or BGY787. As such it can be used widely in Chinese 'Connecting to Every Village' projects.



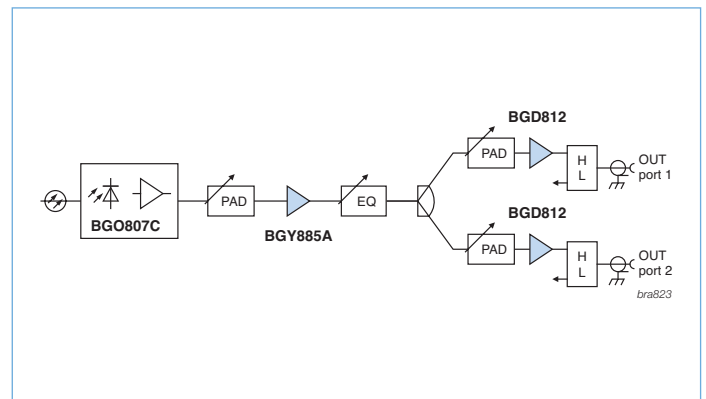
CGD944C and CGD942C

Our full GaAs power doublers modules, CGD942C and CGD944C offer high output power and better CTB and CSO than other modules. Designed for high-end HFC networks containing optical nodes with multiple out-ports, these modules enable each port to directly cover at least 125 subscribers. These two devices are ideal when used in upgrading HFC networks to 860 MHz.



BGO807C

BGO807C is an integrated optical receiver module that provides high output levels and includes an integrated temperature compensated circuitry. In your optical node design, BGO807C enables a high performance/ price ratio and ruggedness. When upgrading an HFC network from analog to digital our BGO807C is the perfect fit.



C-family application information

NXP C-family by application							
Application	BGY588C	BGE788C	CGY888C	BGD712C	BGO807C	CGD944C	CGD942C
Optical node				•	•	•	•
Optical receiver				•	•	•	•
Distribution amplifier			•	•	•	•	•
Line extender amplifier			•	•	•	•	
Terminating amplifier	•	•	•				

Push-pull amplifiers

Parameters		BGY588C	BGE788C	CGY888C
Power gain (dB)	typ.	34,5	34,2	35,5
Slope cable equivalent (dB)	range	0.2 - 1.7	0.3 - 2.3	1.5 typ.
Composite triple beat (dB)	max.	-57	-49	-66
Composite 2nd order distortion (dB)	max.	-62	-52	-64
Noise (@ fmax) (dB)	max.	8	8	3 typ.
Total current consumption (mA)	typ.	325	305	280
Frequency range (MHz)	range	40 - 550	40 - 750	40 - 870

Power doublers

Parameters		BGD712C	CGD944C	CGD942C
Power gain (dB)	typ.	18,5	25	23
Slope cable equivalent (dB)	range	0.5 - 1.5	1 - 2	1 - 2
Composite triple beat (dB)	max.	-62	-66	-66
Composite 2nd order distortion (dB)	max.	-63	-67	-67
Noise (@ fmax) (dB)	max.	7	5	5
Total current consumption (mA)	typ.	395	450	450
Frequency range (MHz)	range	40 - 750	40 - 870	40 - 870

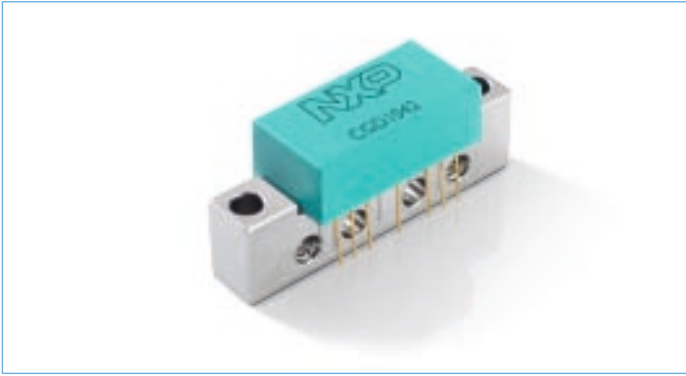
Optical receiver

Parameters		BGO807C
Responsivity (Rmin)	min.	800
Slope cable equivalent (dB)	range	0 - 2
Composite triple beat (dB)	max.	-71
Composite 2nd order distortion (dB)	max.	-55
Noise (@ fmax) (dB)	max.	8,5
Total current consumption (mA)	typ.	190
Frequency range (MHz)	range	40 - 870
Connector		- / SCO / FCO

5.4 Upgrade to a sustainable 1-GHz CATV network

NXP high-gain power doublers CGD104x for 1-GHz CATV applications

These high-performance GaAs devices for 1-GHz CATV applications make it easy for cable operators to extend their services to include HDTV, VoIP, and digital simulcasting.



Designed for 1-GHz “sustainable networks”, these high-performance GaAs devices enable extended bandwidth and higher data rates. They deliver increased network capacity and make way for high-end services like HDTV, VoIP, and digital simulcasting.

The power doublers CGD1042 and CGD1044 are ideal for use in line extenders and trunk amplifiers. Their high-output counterparts, the CGD1042H and CGD1044H, are designed for use in fiber deep-optical-node applications (N+0/1/2), delivering the highest output power on the market today.

Products

- Power doublers: CGD1042, CGD1044
- High-output power doublers: CGD1042H, CGD1044H

Features

- Excellent linearity, stability, and reliability
- High power gain
- Extremely low noise
- Silicon Nitride passivity
- GaAs HFET dies for high-end applications
- Rugged construction

Benefits

- Simple upgrade to 1-GHz capable networks
- Optimized heat management
- Excellent temperature resistance
- Low total cost of ownership
- High ESD levels
- High power-stress capability
- Highly automated assembly

Applications

- Hybrid Fiber Coax (HFC) applications
- Line extenders
- Trunk amplifiers
- Fiber deep-optical-node (N+0/1/2)

The GaAs HFET die process delivers high gain and high performance, along with lower current and better CTB and CSO ratings.

These 1-GHz solutions are designed for durability and offer superior ruggedness, an extended temperature range, high-power overstress capabilities, and high ESD levels. The result is low cost of ownership.

The GaAs die is inserted in a unique HVQFN package that is then mounted on thermal vias that manage heat transfer to the heat sink. Temperature-control circuitry keeps the module’s high performance stable over a wide range of temperature changes.

Assembly is fully automated and requires almost no human intervention and therefore repeatability remains very high.

Upcoming push-pull products

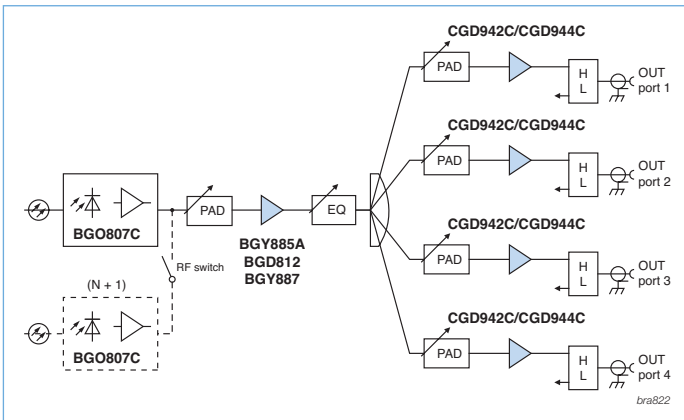
New push-pulls, currently under development, will combine with the power doublers to service almost all modern HFC applications. The push-pull CGY1041 will deliver a gain of 21 dB, the CGY1043 a gain of 23 dB and the CGY1047 a gain of 27dB.

Quick reference data

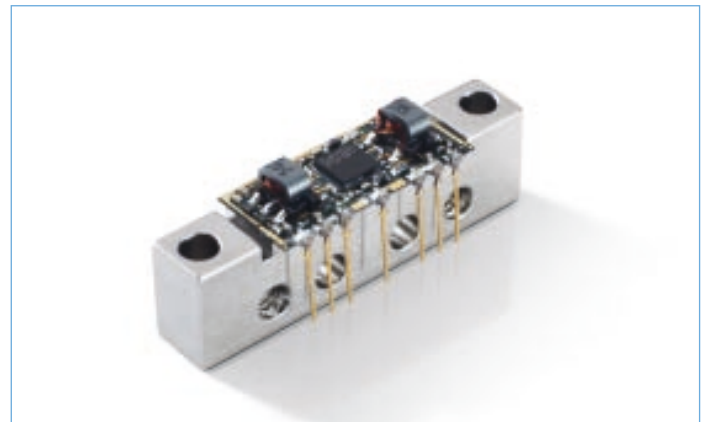
Parameters		CGD1042	CGD1044	CGD1042H	CGD1044H
Power gain (dB)	typ.	23	25	23	25
Slope cable equivalent (dB)	typ.	2	2	1,5	1
Composite triple beat (dB)	typ.	-70(1)	-70(1)	-75(2)	-75(2)
Composite 2nd order distortion (dB)	typ.	-75(1)	-75(1)	-76(2)	-76(2)
Noise (@ fmax) (dB)	max.	5	5	6	6
Total current consumption (mA)	typ.	450	450	450	450
Frequency range (MHz)	range	40 - 1000	40 - 1000	40 - 1000	40 - 1000

⁽¹⁾ 79 analog channels, 13.9 dB extrapolated tilt up to 1 GHz, $V_{out} = 56.9$ dBmV @ 1GHz

⁽²⁾ 79 analog channels + 75 digital channels (-6 dB offset, 18 dB extrapolated tilt up to 1 GHz, $V_{out} = 59$ dBmV @ 1GHz)



An optical node with multiple out-ports using the CGD1042(H) and CGD1044(H)



Power doubler shown without cap

5.5 A perfect match up to 20 GHz

SiGeC microwave NPN transistor BFU725F

Meet the trend towards higher frequencies. With NXP Semiconductors' latest SiGeC microwave NPN transistor BFU725F, you get high switching frequencies plus extremely high gain and low noise. All this in an easy-to-use SOT343F package. It's the ideal solution for applications up to 20 GHz.



Features

- Very low noise (0.4 dB at 1.8 GHz / 0.67 dB at 5.8 GHz)
- High maximum stable gain (27.8 dB at 1.8 GHz / 10 dB at 18 GHz)
- High switching frequency ($f_T > 100$ GHz / $f_{MAX} > 150$ GHz)
- Plastic surface-mount SOT343F package

Benefits

- SiGeC process delivers high switching frequency from a silicon-based device
- Cost-effective alternative to GaAs devices
- RoHS compliant

Applications

- GPS systems
- DECT phones
- Low noise amplifier (LNA) for microwave communications systems
- 2nd stage LNA and mixer in direct broadcast satellite (DBS) low-noise blocks (LNBS)
- Satellite radio
- WLAN and CDMA applications
- Low-noise microwave applications

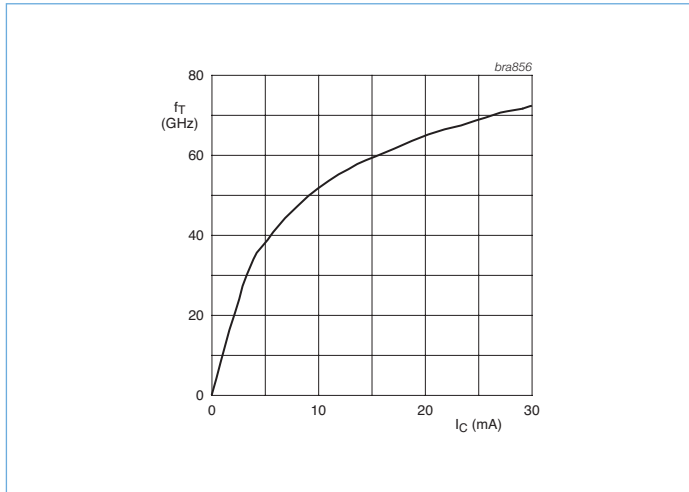
The NPN microwave transistor BFU725F delivers an unbeatable blend of high switching frequency, high gain and very low noise. Thanks to its ultra-low noise figure, it's perfect for your sensitive RF receivers particularly those for high-performance cell phones. Alternatively, with its high cut-off frequency, it's your ideal solution for microwave applications in the 10 GHz to 30 GHz range, such as satellite TV receivers and automotive collision avoidance radar.

The BFU725F get its outstanding performance from our innovative silicon-germanium-carbon (SiGeC) BiCMOS process. QUBiC4X was designed specifically to meet the needs of real-life, high-frequency applications and delivers an unrivalled fusion of high power gain and excellent dynamic range. It combines the performance of gallium-arsenide (GaAs) technologies with the reliability of a silicon-based process. In addition, with the BFU725F, you don't need a biasing IC or negative biasing voltage. So it's a much more cost-effective solution than GaAs pHEMT devices.

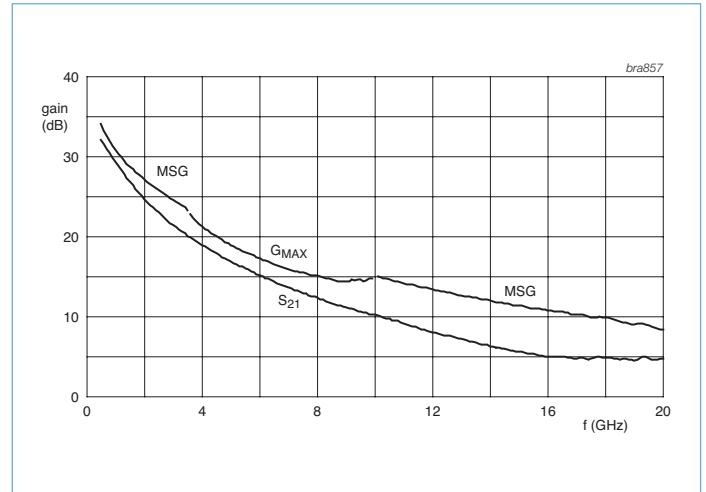
Quick reference data

Parameter	Symbol	Conditions	Value
Collector-emitter breakdown voltage	BV_{CE0}	$I_C = 1 \text{ mA}; I_B = 0$	3.2 V
Maximum collector current	$I_{C(max)}$		40 mA
Transition frequency	f_T	$V_{CE} = 2 \text{ V}; I_C = 25 \text{ mA}; f = 2 \text{ GHz}$	68 GHz
Noise figure	NF	$V_{CE} = 2 \text{ V}; I_C = 5 \text{ mA}; f = 1.8 \text{ GHz}; \Gamma_s = \Gamma_{opt}$	0.4 dB
		$V_{CE} = 2 \text{ V}; I_C = 5 \text{ mA}; f = 2.4 \text{ GHz}; \Gamma_s = \Gamma_{opt}$	0.45 dB
		$V_{CE} = 2 \text{ V}; I_C = 5 \text{ mA}; f = 5.8 \text{ GHz}; \Gamma_s = \Gamma_{opt}$	0.7 dB
		$V_{CE} = 2 \text{ V}; I_C = 5 \text{ mA}; f = 12 \text{ GHz}; \Gamma_s = \Gamma_{opt}$	1.0 dB
Maximum stable power gain	MSG / $G_{P(max)}$	$V_{CE} = 2 \text{ V}; I_C = 25 \text{ mA}; f = 1.8 \text{ GHz}$	26.6 dB
		$V_{CE} = 2 \text{ V}; I_C = 25 \text{ mA}; f = 2.4 \text{ GHz}$	25.5 dB
		$V_{CE} = 2 \text{ V}; I_C = 25 \text{ mA}; f = 5.8 \text{ GHz}$	17 dB
		$V_{CE} = 2 \text{ V}; I_C = 25 \text{ mA}; f = 12 \text{ GHz}$	13 dB

¹ Calculated from noise figure using a lowpass bandwidth filter at 0.7x bit rate and a source with an extinction ratio of 10% and a photodiode responsivity of 0.9A/W.



Transition frequency as a function of collector current (typical values)



Gain as a function of frequency (typical values)

5.6 Best-in-class LNB performance

MMIC wideband amplifier BGA2714

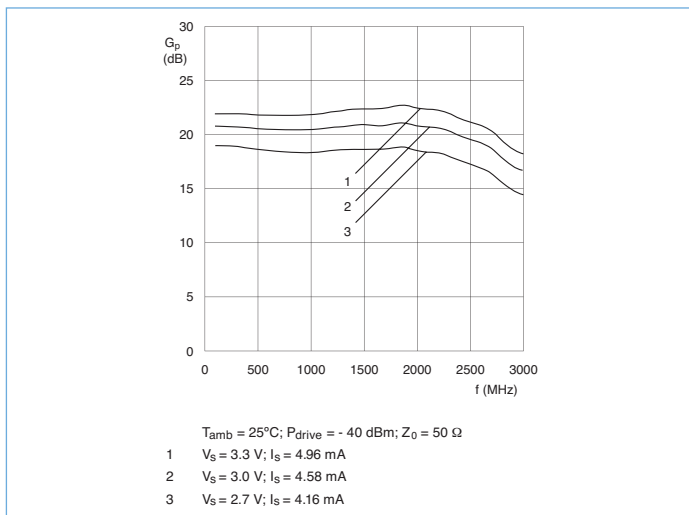
Improve the performance of your LNB design with our MMIC wideband amplifier BGA2714. It delivers best-in-class performance at very low current, is small and needs very few external components. In short, it's the ideal 1st stage IF amplifier for LNBs and other low-noise wideband applications.



A demoboard is available to help further simplify your design-in process

Features

- Extremely flat gain curve (21 dB \pm 1 dB up to 2.5 GHz)
- Wide frequency range (up to 2.7 GHz @ 3 dB gain bandwidth)
- Internally matched to 50 Ω
- Very low current (4.6 mA @ 3 V)
- Low supply voltage (3 V)
- Good linearity (2.1 dBm @ 1 GHz)
- Low noise (2.2 dB @ 1 GHz)
- Excellent reverse isolation (> 50 dB up to 2 GHz)



Power gain as function of frequency; typical values

- Unconditionally stable
- Very few external components required
- Compact SOT363 package

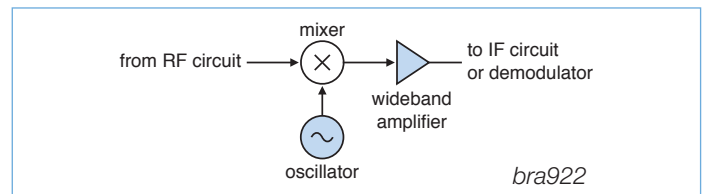
Applications

- LNB IF amplifier
- General-purpose low-noise wideband amplifier for frequencies up to 2.7 GHz

Our MMIC wideband amplifier BGA2714 is designed to meet the specific needs of LNB designs. It operates from a conveniently low supply voltage with a low supply current.

In addition, it delivers industry-leading performance with a wide frequency range, high and flat power gain and low noise. Supplied in a compact, industry-standard SOT363 package, it simplifies system integration.

MMICs like NXP Semiconductors' BGA2714 are smart RF solutions that automatically compensate for temperature and process variations. They integrate transistors, resistors and capacitors into a single device, reducing component count and simplify design. In fact, with the BGA2714 you need just two coupling capacitors and an RF decoupling capacitor.



Application as IF amplifier

Quick reference data

Symbol	Parameter	Condition	Typical value
V_s	supply voltage		3 V
I_s	supply current		4.58 mA
G_p	power gain	1 GHz	20.4 dB
NF	noise figure	1 GHz	2.2 dB
$PL_{(sat)}$	saturated load power	1 GHz	-3.4 dBm

5.7 Mobile applications break free with WiMAX MIMO

WiMAX 802.16e MIMO transceivers UXA234xx

High broadband mobile applications are quickly becoming a reality thanks to the benefits of smart antennae technologies, such as WiMAX 802.16e multiple input/multiple output (MIMO). By offering a complete family of compatible receiver/transmitters, including full dual Rx/Tx solutions, NXP helps you give consumers a richer mobile lifestyle with robust high-speed internet access and video streaming from their mobile equipment.



Features

- Fully integrated direct up transmitter and ZIF receiver architecture
- Dual Rx and Tx for MIMO operation
- Low noise, high dynamic range receiver with high linearity
- Fully integrated VCO with integrated supply voltage regulator
- Serial bus digital interface (4 wires)
- Supply voltage 2.7 V to 2.9 V
- Support for channel bandwidths from 3.5 MHz to 20 MHz

Benefits

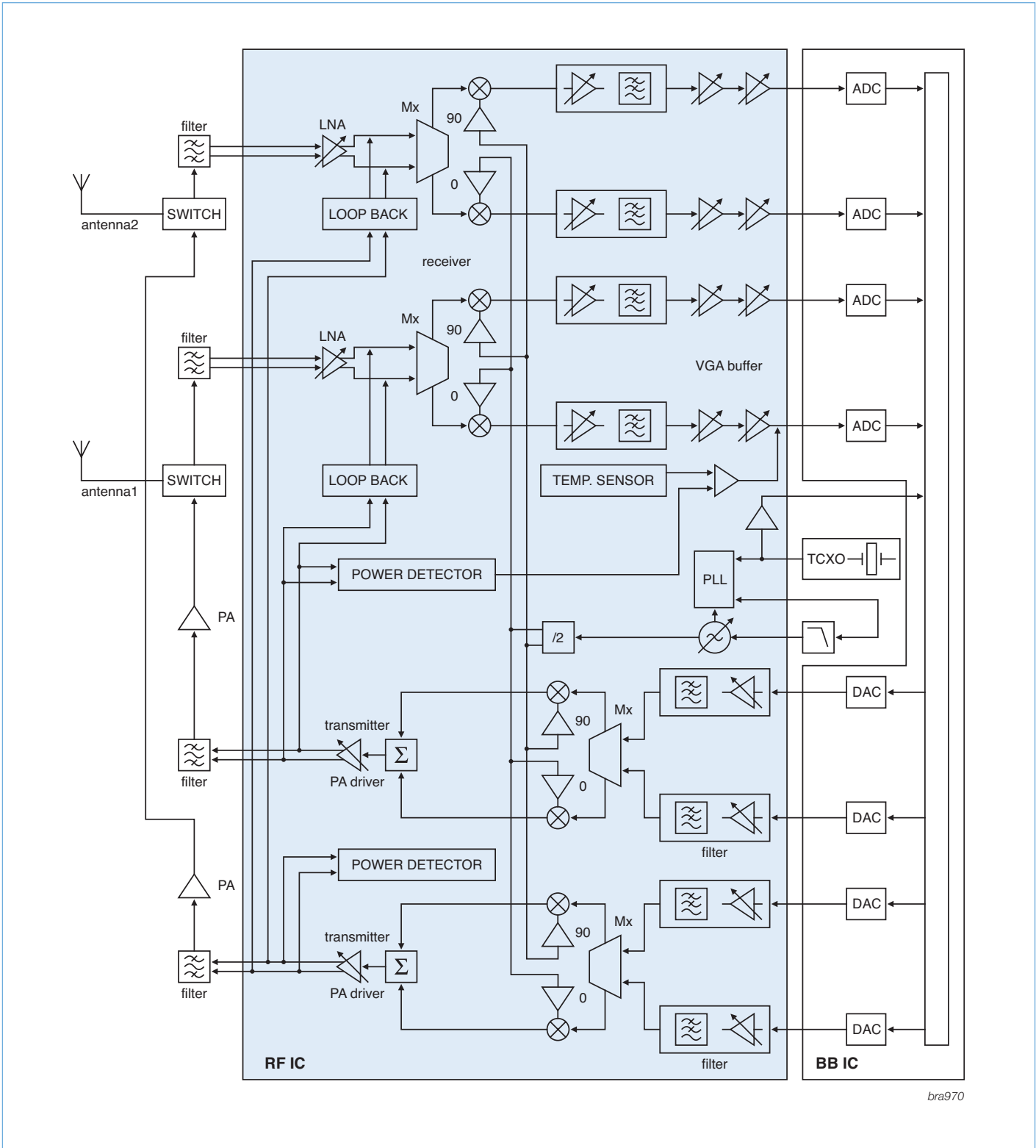
- Extremely low noise figure
- Support for flexible calibration techniques ensures optimum performance and lowest power
- Field proven solution
- No external IF filter required
- Minimal external component requirement

Applications

- Smart phones
- Laptop PCs
- PDAs
- Games consoles
- PCI and PCIe cards

Our next generation UXA234xx WiMAX products enable high broadband mobile applications, by allowing you to add robust high-speed internet access and video streaming to mobile equipment. Developed in close cooperation with end customers and baseband companies, NXP Semiconductors' proven WiMAX solutions deliver best-in-class performance. They provide flexible interfacing to a variety of baseband devices and offer seamless handover from basestation to basestation.

Covering frequencies from 2.3 GHz to 3.8 GHz, these fully integrated, low-power, direct conversion transceivers easily allow total WiMAX system solutions to meet TTA, FCC and ETSI requirements. With dual receiver/transmitter configurations available they can also deliver better uplink performance and improve your total end-user system. In addition, low power requirements ensure longer battery life. Highly integrated, the UXA234xx family requires the minimum of extra external parts, significantly reducing overall component count. Their small 6 mm x 6 mm footprint gives further space and cost savings, while being housed in a low-profile (0.85 mm) package ensures they meet the needs of mobile manufacturers.



bra970

Typical application diagram using the UXA23476

	Frequency range (GHz)	Type	NF (dB)	Rx gain (max) (dB)	I _{cc} (mA) RX/TX	Tx gain range (dB)	Linear output power meeting spectrum mask (dBm)	Package size HVQFN48 (mm)
UXA23465	2.3 - 2.7	2 Rx/1 Tx	2.5	87	81/100	74	+2.5 (TTA) +1 (ETSI, FCC)	6 x 6 x 0.85
UXA23466	2.3 - 2.7	2 Rx/2 Tx	2.5	87	81/182	74	+2.5 (TTA) +1 (ETSI, FCC)	6 x 6 x 0.85
UXA23475	3.3 - 3.8	2 Rx/1 Tx	3.0	87	81/100	74	0 (ETSI)	6 x 6 x 0.85
UXA23476	3.3 - 3.8	2 Rx/2 Tx	3.0	87	81/182	74	0 (ETSI)	6 x 6 x 0.85
UXF23480	2.3 - 2.4	1 Rx/1 Tx	3.2	79	129/153	74	+1	7 x 7 x 0.85
UXF23460	2.5 - 2.7	1 Rx/1 Tx	3.5	77	129/140	74	+1	7 x 7 x 0.85
UXF23470	3.3 - 3.8	2 Rx/1 Tx	3	87	50/85	74	(0) ETSI	6 x 6 x 0.85

5.8 Boost RF performance and reduce system size

RF PIN diodes in leadless SOD882T

Deliver the maximum performance and functionality in the smallest space with our new RF PIN diodes in SOT882T. These unique products enhance the RF performance of your system while reducing its form factor and cutting your time to market.



Features

- Low series inductance
- Low capacitance
- Leadless, package with very small footprint (1.0 mm x 0.6 mm)
- Low profile (0.4 mm)
- Low insertion loss

Benefits

- Unrivalled performance
- Faster time to market
- Smaller end products
- Easier assembly

Applications

- Cellular and cordless phones
- Low noise blocks
- Multi-switch boxes
- Set-top boxes
- CATV infrastructure

- Base stations
- eMetering
- Bluetooth and wireless LAN
- Car Radio

Our RF PIN diodes are ideal for a wide range of mobile communications and RF applications. Their low loss and low distortion levels improve battery life and quality in mobile phones and cordless phones. Moreover, their extremely low forward resistance, diode capacitance and series inductance simplify design-in.

We offer an extensive portfolio of RF PIN diodes. So you're sure to find the right solution for your needs. The latest additions to this portfolio are housed in the ultra-small, leadless SOD882T package, making them particularly suitable for wireless devices.

As part of our ultra-thin leadless package (UTLP) platform, the SOD882T package uses a patent-pending etch process that produces extremely high silicon to footprint ratio and a profile as low as 0.4 mm. In addition, the package has no leads and so delivers very low parasitics for maximum RF performance. This unique combination of properties results in devices that maximize the performance and functionality of your system while reducing its size and weight. They also simplify board assembly to help cut your time to market.

Product overview

Type	Limits		Typ. RD (Ω) @			Typ. Cd (pF) @		
	Vr (V)	If (mA)	0.5 mA	1 mA	10 mA	0 V	1 V	20 V
BAP50LX	50	50	25	14	3	0.45	0.35	0.3 (@ 5 V)
BAP51LX	60	60	5.5	3.6	1.5	0.4	0.3	0.2 (@ 5 V)
BAP55LX	50	100	3.4	2.3	1	0.27	0.23	0.18 (@ 5 V)
BAP63LX	50	100	2.5	1.95	1.17	0.4	0.35	0.3
BAP64LX	100	100	20	10	2	0.52	0.37	0.23
BAP65LX	30	100		1	0.56	0.65	0.6	0.375
BAP1321LX	60	100	3.4	2.4	1.2	0.4	0.35	0.25
BAP142LX	50	100	3.3	2.4	1	0.26	0.23	0.15

Functions of pin diodes

	Telecom		Consumer and automotive					Industrial			Connectivity	
	Cellular	Cordless	Low-noise block	Multi switch box	Walkie-talkie	Set top box	Car radio	CATV	Base station	eMetering	Bluetooth	WLAN
Switching	•	•	•	•	•				•	•	•	
Attenuating						•	•	•				•



What if you could build the world's best portable WiMAX device, now!

Look at WiMAX, chapter 5.7

6. Packing and packaging information

6.1 Ultra thin leadless package platform



NXP ultra-thin leadless package (UTLP) platform for faster time-to-market, smaller form factor.

Features

- Low height (0.4 mm)
- Small footprint
- Very flexible platform
- High silicon-to-footprint ratio
- Increased performance
- Footprint compatible with JETA standard SC-101
- Very efficient packing (15k/7" reel)
- RoHs-compliant, green plastic.

Benefits

- Improved electrical, thermal and moisture resistance
- Reduced noise
- Easier board assembly
- More functionality in a smaller space
- Excellent RF performance.

The NXP ultra-thin leadless package (UTLP) uses a patent-pending etch process, enabling a lead frame with independent top and bottom layouts, giving maximum product creation flexibility. A very high silicon-to-footprint ratio, combined with a low profile of 0.4 mm makes the device perfectly suited for space constrained portable applications, like mobile communications, PDA's and handheld devices, increasing performance with same footprint.

The unique design improves the package's electrical and thermal performance, and at the same time increases the moisture resistance. The chosen technology enables the reduction of added package material to a minimum, to come as close to a bare die as possible, without the bare die drawbacks in assembly. The resulting very low parasitics give a much better performance than leaded packages or even QFN type, enabling a design-in range, which includes high-frequency applications operating at up to 24 GHz.

The product creation flexibility also supports packaging techniques like multiple dies, multiple leads with isolated die pads, re-routing and even fine pitch flip chip, which enhances RF performance even further. This enables more functionality in a smaller space. The result is a package, which increases customer's design flexibility, reduces time to market and improves performance in a broad range of (mobile) applications.

The package makes board assembly easier. The footprint is compatible with JETA standard SC-101 and because of the built-in standoff; both metal defined and solder resist defined PCB layouts can be used. To lessen the impact on the environment the package is already dark green and packed with as many as 15k units on a 7" reel.

Ordering information

Type number	Description	Package
BAP50LX	Silicon PIN diode	SOD882T
BAP51LX	Silicon PIN diode	SOD882T
BAP63LX	Silicon PIN diode	SOD882T
BAP64LX	Silicon PIN diode	SOD882T
BAP65LX	Silicon PIN diode	SOD882T
BAP1321LX	Silicon PIN diode	SOD882T
BB202LX	Low-voltage variable FM capacitance diode	SOD882T
BB178LX	VHF-high variable capacitance diode	SOD882T
BB179LX	UHF variable capacitance diode	SOD882T
BB182LX	VHF-low variable capacitance diode	SOD882T
BAP55LX	Silicon PIN diode	SOD882T
BAP142LX	Silicon PIN diode	SOD882T

6.2 Packing quantities per package with relevant ordering code

Package	Packing quantity	Product 12NC ending	Packing method
SOD110	3,000	115	8 mm tape and reel
	11,000	135	8 mm tape and reel
SOD323/SC-76	3,000	115	8 mm tape and reel
	10,000	135	8 mm tape and reel
SOD523/SC-79	3,000	115	8 mm tape and reel
	10,000	135	8 mm tape and reel
	8,000	315	2 mm pitch tape and reel
	20,000	335	2 mm pitch tape and reel
SOD882T	15,000	315	8 mm tape and reel
SOT23	3,000	215	8 mm tape and reel
	10,000	235	8 mm tape and reel
SOT54	5,000	112	bulk, delta pinning
	5,000	412	bulk, straight leads
	10,000	116	tape and reel, wide pitch
	10,000	126	tape ammpack, wide pitch
SOT89/SC-62	1,000	115	12 mm tape and reel
	4,000	135	12 mm tape and reel
SOT115	100	112	4 tray/box
SOT143(N/R)	3,000	215	8 mm tape and reel
	10,000	235	8 mm tape and reel
SOT223/SC-73	1,000	115	12 mm tape and reel
	4,000	135	12 mm tape and reel
SOT323/SC-70	3,000	115	8 mm tape and reel
	10,000	135	8 mm tape and reel
SOT343(N/R)	3,000	115	8 mm tape and reel
	10,000	135	8 mm tape and reel
SOT360	2,500	118	16 mm tape and reel
SOT363/SC-88	3,000	115	8 mm tape and reel
	10,000	135	8 mm tape and reel
SOT403	2,500	118	12 mm tape and reel
SOT416/SC-75	3,000	115	8 mm tape and reel
SOT560	490	551	tray
	2,450	557	multiple trays
SOT567	200	112	4tray/box
	500	118	32 mm tape and reel
SOT616	6,000	118	12 mm tape and reel
SOT619	260	551	tray
	4,000	518	multiple trays
SOT638	90	551	tray
	450	557	multiple trays
SOT666	4,000	115	8 mm tape and reel
SOT724	2,500	118	16 mm tape and reel
SOT778	490	551	tray
	4,000	518	multiple trays

6.3 Marking codes list

In case a '%' is given in the marking code, it means this type can be assembled at different assembly sites.

Instead of a '%', you will find:

p = made in Hong-Kong

t = made in Malaysia

W = made in China

Marking code	Type	Package	Marking code	Type	Package	Marking code	Type	Package
1	BA277	SOD523	A1	BB208-02	SOD523	K7	BAP1321-02	SOD523
2	BB182	SOD523	A1	BGA2001	SOT343	K8	BAP70-02	SOD523
7	BA891	SOD523	A2	BAT18	SOT23	K9	BB199	SOD523
8	BB178	SOD523	A2	BB184	SOD523	L1	BB202LX	SOD882T
9	BB179	SOD523	A2	BB208-03	SOD323	L2	BAP51LX	SOD882T
%13	BB207	SOT23	A2%	BGA2022	SOT363	L2	BB202	SOD523
%3A	BGA6289	SOT89	A3	BAP64-03	SOD323	L2%	BF1203	SOT363
%4A	BGA6489	SOT89	A3	BB198	SOD523	L3	BB178LX	SOD882T
%5A	BGA6589	SOT89	A3	BGA2003	SOT343	L3%	BF1204	SOT363
%6G	PMBF4393	SOT23	A3%	BGA2031/1	SOT363	L4	BB179LX	SOD882T
%6J	PMBF4391	SOT23	A5	BAP51-03	SOD323	L4%	BF1205	SOT363
%6K	PMBF4392	SOT23	A5%	BGA2011	SOT363	L5	BB179BLX	SOD882T
%6S	PMBFJ176	SOT23	A6%	BGA2012	SOT363	L6	BB181LX	SOD882T
%6W	PMBFJ175	SOT23	A7%	BFG310W/XR	SOT343	L6%	BF1206	SOT363
%6X	PMBFJ174	SOT23	A8	BAP50-03	SOD323	L7	BB182LX	SOD882T
%6Y	PMBFJ177	SOT23	A8%	BFG325W/XR	SOT343	L8	BA792	SOD110
%AB	BF1210	SOT363	A8%	PMBFJ620	SOT363	L8	BB187LX	SOD882T
10%	BAT18	SOT23	A9	BAP70-03	SOD323	L9%	BF1208	SOT363
1B%	BGA2717	SOT363	B6-	BGA2715	SOT363	LA	BB185LX	SOD882T
1C%	BAP50-05	SOT23	B6%	BFU725F	SOT343F	LA	BF1201WR	SOT343
1N%	BAP70-04W	SOT323	B7%	BGA2716	SOT363	LA%	BF1201	SOT143
1W-	BAP51-05W	SOT323	BC%	BFQ591	SOT89	LB%	BF1201R	SOT143
20%	BF545A	SOT23	BFG135	BFG135	SOT223	LD%	BF1202	SOT143
21%	BF545B	SOT23	BFG198	BFG198	SOT223	LE	BF1202WR	SOT343
22%	BF545C	SOT23	BFG31	BFG31	SOT223	LE%	BF1202R	SOT143
24%	BF556A	SOT23	BFG35	BFG35	SOT223	LF%	BF1211	SOT143
25%	BF556B	SOT23	BFG541	BFG541	SOT223	LG%	BF1212	SOT143
26%	BF556C	SOT23	BFG591	BFG591	SOT223	LH%	BF1211R	SOT143
28%	BF861A	SOT23	BFG94	BFG94	SOT223	LK%	BF1212R	SOT143
29%	BF861B	SOT23	BFG97	BFG97	SOT223	M08	PMBFJ308	SOT23
2A%	BF862	SOT23	BLT50	BLT50	SOT223	M09	PMBFJ309	SOT23
2L	BF1208	SOT666	BLT70	BLT70	SOT223	M1%	BFR30	SOT23
2N	BF1206F	SOT666	BLT80	BLT80	SOT223	M10	PMBFJ310	SOT23
2R	BF1207F	SOT666	BLT81	BLT81	SOT223	M2%	BF1207	SOT363
30%	BF861C	SOT23	C1%	BGM1011	SOT363	M2%	BFR31	SOT23
31%	BFR505	SOT23	C2%	BGM1012	SOT363	M26	BF908	SOT143
32%	BFR520	SOT23	C4%	BGM1013	SOT363	M27	BF908R	SOT143
33%	BFR540	SOT23	C5%	BGM1014	SOT363	M28	BF909	SOT143
34%	BFT25A	SOT23	D2	BAP63-03	SOD323	M29	BF909R	SOT143
38%	PMBFJ108	SOT23	D3	BAP65-03	SOD323	M3%	BFT46	SOT23
39%	PMBFJ109	SOT23	D4%	BFR30/B	SOT23	M33	BF861A	SOT23
40%	PMBFJ110	SOT23	E1%	BFS17	SOT23	M33	BF909A	SOT143
41%	PMBFJ111	SOT23	E1%	BFS17/FD	SOT23	M34	BF861B	SOT23
42%	PMBFJ112	SOT23	E1%	BFS17W	SOT323	M34	BF909AR	SOT143
47%	PMBFJ113	SOT23	E2%	BFS17A	SOT23	M35	BF861C	SOT23
48%	PMBFJ308	SOT23	E2%	BGA2712	SOT363	M41	BF904A	SOT143
49%	PMBFJ309	SOT23	E3%	BGA2709	SOT363	M42	BF904AR	SOT143
4A	BF1208D	SOT666	FB	BFQ19	SOT89	M6%	BF1205C	SOT363
4K%	BAP64-04	SOT23	FF	BFQ18A	SOT89	M65	BF545A	SOT23
4L%	BAP50-04	SOT23	FG	BFQ149	SOT89	M66	BF545B	SOT23
4W%	BAP64-04W	SOT323	G2	BA278	SOD523	M67	BF545C	SOT23
50%	PMBFJ310	SOT23	G2%	BGA2711	SOT363	M74	BSS83	SOT143
5K%	BAP64-05	SOT23	G3%	BGA2748	SOT363	M84	BF556A	SOT23
5W%	BAP64-05W	SOT323	G4%	BGA2771	SOT363	M85	BF556B	SOT23
6F%	BAP1321-04	SOT23	G5%	BGA2776	SOT363	M86	BF556C	SOT23
6K%	BAP64-06	SOT23	K1	BAP51-02	SOD523	M91	BF991	SOT143
6W%	BAP50-04W	SOT323	K2	BAP51-05W	SOD523	M92	BF992	SOT143
7K%	BAP65-05	SOT23	K4	BAP50-02	SOD523	MB	BF998WR	SOT343
8K%	BAP70-05	SOT23	K5	BAP63-02	SOD523	MC	BF904WR	SOT343
A1	BA591	SOD323	K6	BAP65-02	SOD523	MD	BF908WR	SOT343

Marking code	Type	Package
ME	BF909WR	SOT343
MF	BF1100WR	SOT343
MG	BF909AWR	SOT343
MG%	BF994S	SOT143
MH	BF904AWR	SOT343
MH%	BF996S	SOT143
MK	BF1211WR	SOT343
ML	BF1212WR	SOT343
MO%	BF998	SOT143
MO%	BF998R	SOT143
MO4	BF904	SOT143
MO6	BF904R	SOT143
N	BB181	SOD523
N0	BFR505T	SOT416
N0%	BFM505	SOT363
N0%	BFS505	SOT323
N1	BFG505W/X	SOT343
N2	BFR520T	SOT416
N2%	BFM520	SOT363
N2%	BFS520	SOT323
N28	BFR520	SOT23
N29	BFR540	SOT23
N3	BFG520W	SOT343
N30	BFR505	SOT23
N33	BFG505	SOT143
N36	BFG520	SOT143
N37	BFG540	SOT143
N38	BFG590	SOT143
N39	BFG505/X	SOT143
N4	BFG520W/X	SOT343
N4	BFQ540	SOT89
N4%	BFS540	SOT323
N42	BFG520/X	SOT143
N43	BFG540/X	SOT143
N44	BFG590/X	SOT143
N48	BFG520/XR	SOT143
N49	BFG540/XR	SOT143
N6%	BFS25A	SOT323
N7	BFG540W/X	SOT343
N71	BFG10/X	SOT143

Marking code	Type	Package
N8	BFG540W/XR	SOT343
N9	BFG540W	SOT343
N9%	BAP70AM	SOT363
NA	BF1105WR	SOT343
NA%	BF1105R	SOT143
NB	BF1109WR	SOT343
NB%	BF1109R	SOT143
NC	BF1101WR	SOT343
NC%	BF1101R	SOT143
ND	BFG424W	SOT343
ND%	BF1101	SOT143
NE	BFG424F	SOT343
NE%	BF1105	SOT143
NF%	BF1109	SOT143
NG%	BF1108	SOT143
NH%	BF1108R	SOT143
P08	PMBFJ108	SOT23
P09	PMBFJ109	SOT23
P1	BB131	SOD323
P1	BFG21W	SOT343
P10	PMBFJ110	SOT23
P11	PMBFJ111	SOT23
P12	PMBFJ112	SOT23
P13	PMBFJ113	SOT23
P2%	BFR92A	SOT23
P2%	BFR92AW	SOT323
P3	BFG403W	SOT343
P4	BFG410W	SOT343
P5	BB135	SOD323
P5	BFG425W	SOT343
P6	BFG480W	SOT343
P7	BB147	SOD323
P8	BB148	SOD323
P9	BB149	SOD323
PB	BB152	SOD323
PC	BB153	SOD323
PE	BB155	SOD323
PF	BB156	SOD323
PL	BB149A	SOD323
R2%	BFR93A	SOT23

Marking code	Type	Package
R2%	BFR93AW	SOT323
R5	BFR93AR	SOT23
R7%	BFR106	SOT23
R8%	BFG93A	SOT143
S	BAP64-02	SOD523
S1%	BFG310/XR	SOT143
S2%	BBY40	SOT23
S2%	BFG325/XR	SOT143
S3%	BF1107	SOT23
S6%	BF510	SOT23
S7%	BF511	SOT23
S8%	BF512	SOT23
S9%	BF513	SOT23
SB%	BF1214	SOT363
SC%	BB201	SOT23
T5	BFG10W/X	SOT343
V1	BFG25AW/X	SOT343
V1%	BFT25	SOT23
V10	BFT25A	SOT23
V11	BFG25A/X	SOT143
V12	BFG67/X	SOT143
V14	BFG92A/X	SOT143
V15	BFG93A/X	SOT143
V2%	BFQ67	SOT23
V2%	BFQ67W	SOT323
V3%	BFG67	SOT143
V4%	BAP64-06W	SOT323
V6%	BAP65-05W	SOT323
V8	BAP1321-03	SOD323
W1	BF1102	SOT363
W1%	BFT92	SOT23
W1%	BFT92W	SOT323
W2%	BF1102R	SOT363
W4%	BAP50-05W	SOT323
W6%	BAP51-04W	SOT323
W7%	BAP51-06W	SOT323
W9%	BAP63-05W	SOT323
X	BB187	SOD523
X1%	BFT93	SOT23
X1%	BFT93W	SOT323

7. Contacts and web links

How to contact your authorized distributor or local NXP representative

Authorized distributors

Asia Pacific:

http://www.nxp.com/profile/sales/asia_pacific_dist

Europe / Africa / Middle East:

http://www.nxp.com/profile/sales/europe_dist

North America:

http://www.nxp.com/profile/sales/northamerica_dist

South America:

http://www.nxp.com/profile/sales/southamerica_dist

Local NXP Offices

Asia Pacific:

http://www.nxp.com/profile/sales/asia_pacific

Europe / Africa / Middle East:

<http://www.nxp.com/profile/sales/europe>

North America:

<http://www.nxp.com/profile/sales/northamerica>

South America:

<http://www.nxp.com/profile/sales/southamerica>

Web links

NXP Semiconductors:

<http://www.nxp.com>

NXP RF Manual web page:

<http://www.nxp.com/rfmanual>

NXP varicaps:

<http://www.nxp.com/varicaps>

NXP RF PIN diodes:

<http://www.nxp.com/pindiodes>

NXP RF Schottky diodes:

<http://www.nxp.com/rfschottkydiodes>

NXP RF MMICs:

<http://www.nxp.com/mmics>

NXP RF wideband transistors:

<http://www.nxp.com/rftransistors>

NXP RF FETs:

<http://www.nxp.com/rffets>

NXP RF CATV electrical & optical:

<http://www.nxp.com/catv>

NXP optical networking:

<http://www.nxp.com/opticalnetworking>

NXP RF applications:

<http://www.nxp.com/rf>

NXP application notes:

http://www.nxp.com/all_appnotes

NXP cross-references:

<http://www.nxp.com/products/xref>

NXP green packaging:

http://www.nxp.com/green_roadmap

NXP end-of-life:

<http://www.nxp.com/products/eol>

NXP Quality Handbook:

<http://www.standardics.nxp.com/quality/handbook>

NXP literature:

<http://www.nxp.com/products/discretes/documentation>

NXP packaging:

<http://www.nxp.com/package>

NXP sales offices and distributors:

<http://www.nxp.com/profile/sales>



www.nxp.com

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